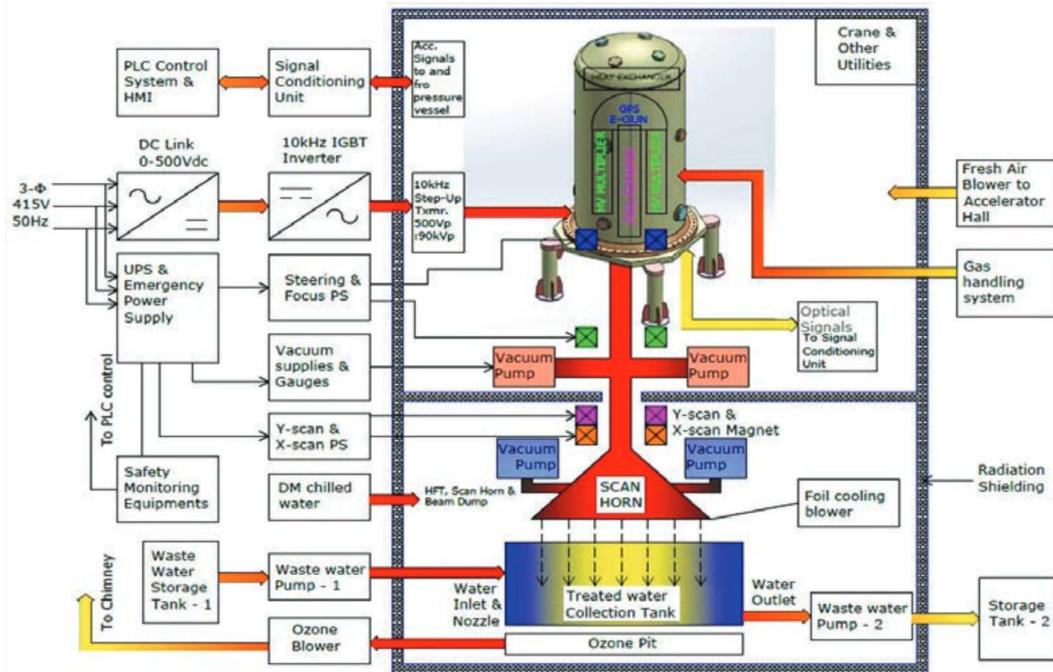


BHABHA ATOMIC RESEARCH CENTRE

ACCELERATOR AND PULSE POWER DIVISION



*SIMULATION, ANALYSIS & TESTING OF HV MULTIPLIER CIRCUIT
FOR DC ELECTRON BEAM ACCELERATOR*

SUBMITTED BY: DEBRAJ BHATTACHARJEE

BRANCH- ELECTRICAL ENGINEERING (2021-2025)

ENROLLMENT NO.-21UEE014

NATIONAL INSTITUTE OF TECHNOLOGY, AGARTALA

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Yours Faithfully,
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(21UEE014,EE,NIT AGARTALA)

Date:

Place: Electron Beam Centre

BHABHA ATOMIC RESEARCH CENTRE

ACCELERATOR AND PULSE POWER DIVISION



CERTIFICATE

*This is to certify that Mr. Debraj Bhattacharjee, a student of Electrical Engineering at National Institute of Technology, Agartala has successfully completed his summer training at Bhabha Atomic Research Centre , APPD from 12th May 2024 to 5th July 2024. He has successfully completed his project work on **Simulation, Analysis & Testing of HV Multiplier Circuit for DC Electron Beam Accelerator** . During the training he took keen interest in the assigned work. We wish him all success in his academic endeavors and life.*

Date:

Mentor

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Introduction to 1MeV 100KW DC Electron Accelerator

The Electron Beam Centre (EBC) Beam technology development group (BTG, BARC) has designed and developed a dc accelerator in the energy range of 1-3MeV and beam current range of 0-100mA. One unit of DC electron accelerator in the energy range of 1MeV-3MeV, 30KW has been constructed and demonstrated for flue gas treatment, dye waste water treatment etc. Presently this accelerator is dismantled and a new high power accelerator in the energy range of 0.8Mev, 100KW has been developed and installed at the existing pressure vessel of 3 MeV DC accelerator for demonstration. This machine can be considered as the workhorse for industrial radiation processing applications like modification of bulk polymers, cross linking of cables, degradation of scrap Teflon and cellulose materials, diamond colouring. EB treated hydro gel, small scale industrial flue gas treatment.

The 1.0MeV machine works on the principle of accelerating electron in a graded dc high voltage column developed by a Symmetrical Cockcroft Walton Voltage Multiplier.

The dc accelerating potential of 1.0MV is generated by a voltage multiplier scheme, based on capacitor-rectifier cascade circuit. The multiplier is driven by a high frequency power source fed from 3- φ 415V, 50Hz mains. Power required for the electron gun located at the 1.0MV potential is derived from the multiplier column. The derived power is converted in to supplies of different ratings to energize the electron gun and the control circuits. Entire high voltage system consisting of voltage multiplier, accelerating column, electron gun and electron gun supplies are enclosed in a vessel filled with 95% N₂-5% SF₆ gas at 6kg/cm² pressure to obtain the required electrical insulation.

Introduction to Voltage Multiplier Circuits

Cascaded voltage Doubler circuits for higher voltages are cumbersome and require too many supply and isolating transformers. It is possible to generate very high D.C. voltages from single supply transformers by extending the simple voltage doubler circuits. This is simple and compact. Here we discuss about Cockcroft-Walton Voltage Multiplier.

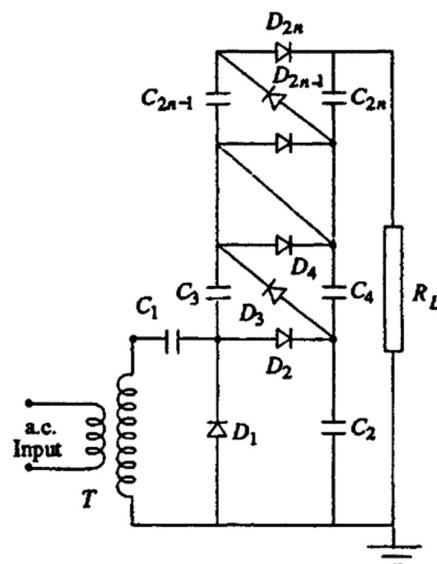


Figure-1: Cockcroft-Walton Voltage Multiplier Circuit

Voltage multiplier circuit using the Cockcroft-Walton principle is shown in Figure. The First Stage Consist of D_1 , D_2 , C_1 , C_2 , and transformer \mathbf{T} . During the Positive Cycle, C_1 is Charged through D_1 to a voltage of $+V_{max}$. During the Negative Cycle, C_2 is Charged through D_2 to a voltage of $+2V_{max}$ as C_1 is already charged to $+V_{max}$ and thus C_1 and \mathbf{T} provides the $+2V_{max}$ voltage to C_2 . Similarly, C_3 is charged to voltage of $+2V_{max}$ through D_3 and then C_4 is charged to voltage of $+4V_{max}$ with respect to ground and similarly C_{2n} to $+2nV_{max}$ with respect to ground .But Voltage across any individual Capacitor or Diode is only $2V_{max}$. The Diodes D_1 , D_3 , ... D_{2n-1} shown in Figure operate and conduct during the positive half cycles while the Diodes D_2 , D_4 ... D_{2n} conduct during the negative half cycles. Typical current and voltage waveforms of such a circuit are shown in the below figure.

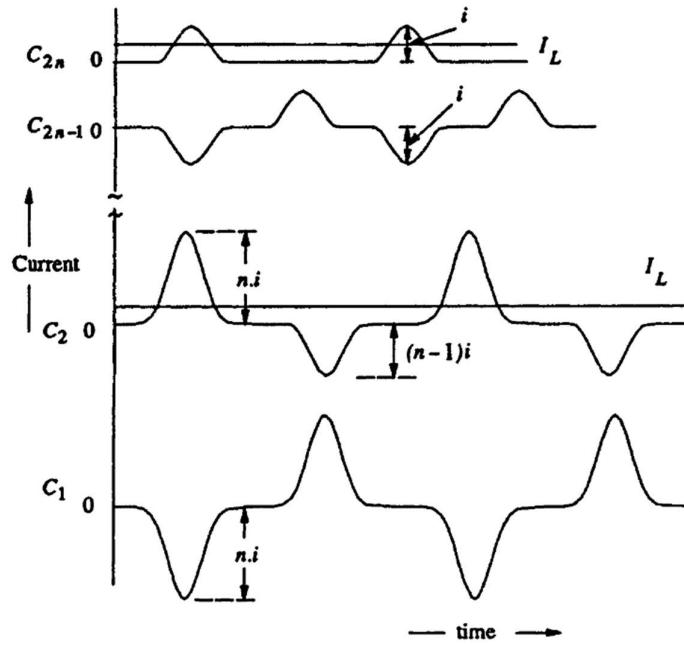


Figure-2: Schematic Current Waveform across the first and the last capacitor of the cascaded Voltage multiplier Circuit.

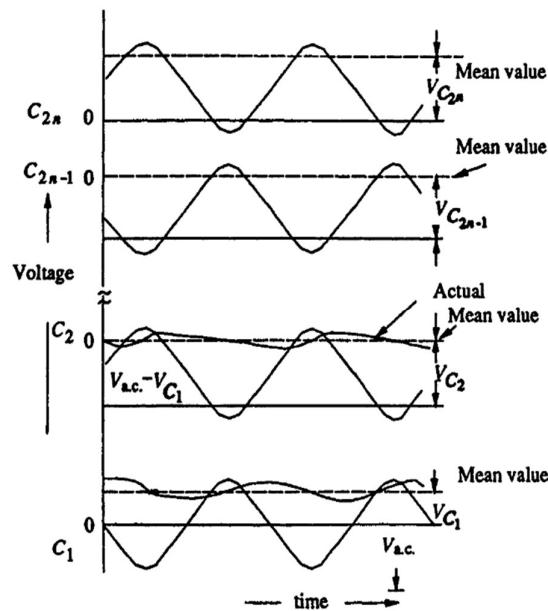


Figure-3: Schematic Voltage Waveform across the first and the last capacitor of the cascaded Voltage multiplier Circuit.

High Voltage Multiplier rated for 1MV, 100mA

Introduction

The electron beam is accelerated upto 1MeV energy using an Ultra High Voltage DC Power Source. This supplies the power needed for acceleration of electron beam and also develops the required Electric-field in the accelerating tubes for acceleration of electron beam.

The 1MV Voltage multiplier of 15 stages, Symmetrical Cockcroft-Walton scheme has been selected due to its simple design, easier fabrication & testing, high energy efficiency as well as rugged & reliable operation. The Voltage multiplier is located inside a pressure vessel filled with 95% N₂-5% SF₆ gas at 6kg/cm² pressure.

Technical Specifications

The salient specifications of the High Voltage Generator are as follows:

1. Operating Voltage	0.80MV - 1.00 MV
3. Load current	0-100 mA
4. Voltage drop (Regulation)	280 kV (max.)
5. Ripple (p-p)	10 kV (max.)
6. Multiplier Scheme	Symmetrical Cockcroft-Walton
7. Operating gas medium	95% N ₂ -5% SF ₆ gas at 6kg/cm ² pressure

Design Considerations for Cascaded Voltage Multipliers

A simple cascade voltage multiplier circuit was discovered by Cockcroft and Walton, hence, known as Cockcroft-Walton multiplier after them. A comparison of various forms of voltage multipliers i.e conventional, symmetric and parallel coupled multiplier is given below through the formula of Output Voltage.

Conventional Cockcroft-Walton Multiplier :

$$V_L = 2NV_i - \frac{I}{fC} \left(\frac{2N^3}{3} + \frac{N^2}{2} - \frac{N}{4} \right) \pm \frac{N(N+1)I}{2f}$$

Symmetrical Cockcroft-Walton Multiplier:

$$V_L = 2NV_i - \frac{I}{fC} \left(\frac{N^3}{6} + \frac{N^2}{4} + \frac{N}{3} \right) \pm \frac{NI}{2fC}$$

Parallel Cockcroft-Walton Multiplier:

$$V_L = \frac{NV_i}{k} - \frac{NI}{KfC_{SE}} \pm \frac{I}{2fC_{SE}}$$

The main feature of all these voltage multipliers is that, input is high frequency AC voltage and output is high voltage DC. The first three circuits (i.e. conventional, balanced & symmetrical) utilize discrete capacitors and operate at moderate frequencies usually in 1-10 kHz range.

The parallel circuit was mastered by Radiation Dynamics Inc. and marketed as 'Dynamitron' type generator. This generator operates at 30-300 kHz input and utilizes geometrical (i.e. stray) capacitances formed between metal components (i.e. corona guards, RF Electrodes and rectifiers) for development of High Voltage.

Selection Criteria for type of Generator

In general, Cockcroft-Walton circuits are used when relatively lower output voltage is required. A Conventional Circuit is used for relatively lower voltage and current, whereas, symmetrical Circuit is used when lower voltage but higher output current is desired. Parallel circuit utilizes geometric capacitances, which are of very low value (in pF), hence stored energy is low, even at much higher voltages. Therefore, parallel circuit is used for higher voltage usually in 2- 6 MV range.

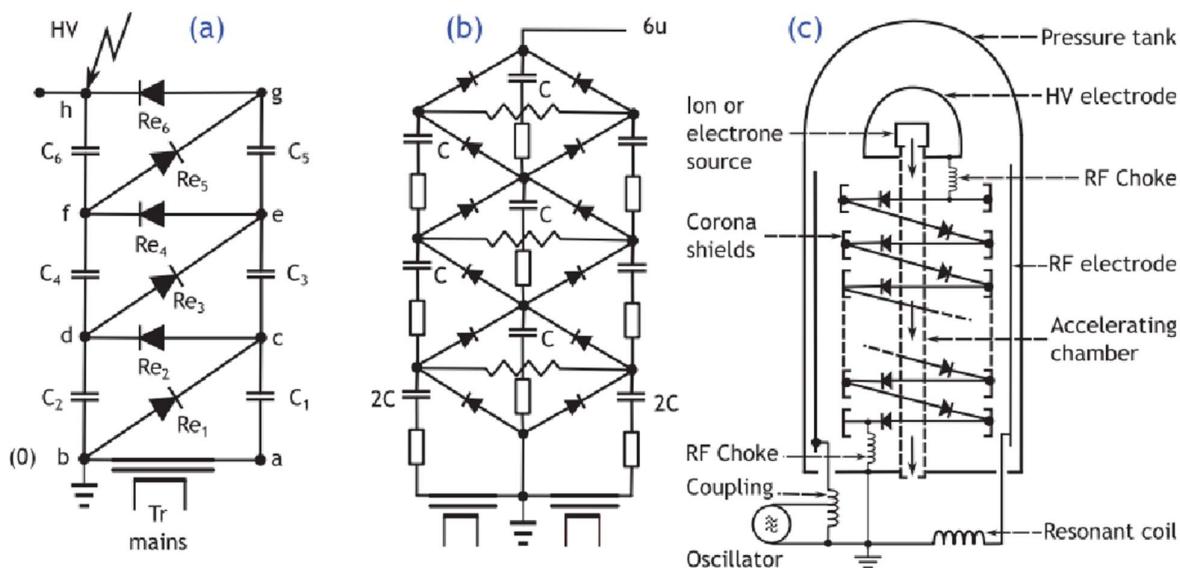
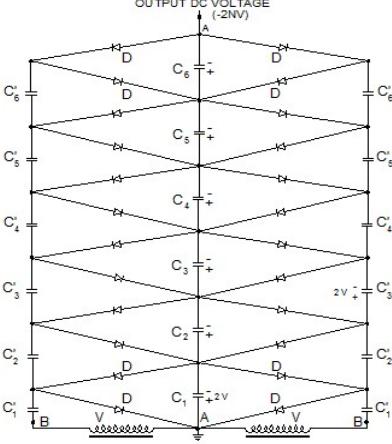
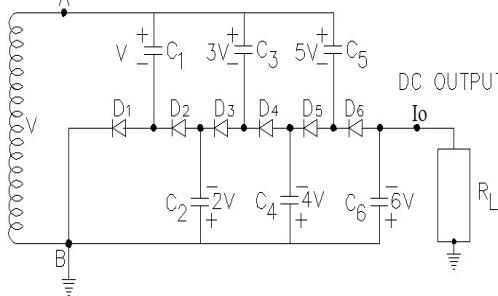


Figure : Electrical Scheme of the three types of voltage multiplier circuits: (a) conventional CW circuit, (b) symmetrical CW circuit, and (c) parallel (dynamitron) circuit.

Detail Comparison of Symmetric and Parallel CW

No.	Parameter	Cockcroft Walton Symmetrical Scheme	Parallel Coupled Multiplier
1	Output Voltage	$V_L = 2NV_i - \frac{I}{fC} \left(\frac{N^3}{6} + \frac{N^2}{4} + \frac{N}{3} \right) \pm \frac{NI}{2fC}$ <p>Input Voltage, $V_i = 40\text{kV}_P$; $N = 15$; $C = 20\text{nF}$; $I = 100\text{mA}$</p>	$V_L = \frac{NV_i}{k} - \frac{NI}{k f C_{SE}} \pm \frac{I}{2 f C_{SE}}$ <p>Input Voltage, $V_i = 150\text{kV}_P$; $N = 25$; $C_{SE} = 16\text{pF}$; $I = 100\text{mA}$</p>
2	Scheme	 <p>Fig.: SYMMETRICAL COCKCROFT WALTON CIRCUIT</p>	 <p>Fig. : SIMPLIFIED ELECTRICAL SCHAMATIC OF PARALLEL FED VOLTAGE MULTIPLIER</p>
3	Frequency	10kHz	100kHz
4	Components	HV ceramic capacitors (40DKD33 x 54 Nos. per stage) & HV diodes (HVRW-4 with PIV-4kV, 1A, $T_{rr} = 150\text{ns}$)	HV Distributed gas capacitor made of corona rings and RF electrode & HV diodes (UXFOB, 8kV, 0.5A with $T_{rr} = 50\text{ns}$)
5	Principle	Series Capacitance charging	Parallel capacitance charging
6	Regulation	28%	30%
7	Ripple	$\pm 2.6\%$	$\pm 2\%$
8	Input Source	40kV-0-40kVp, 10kHz, 104kW A) Solid state inverter with $\eta=95\%$ OR B) Triode based oscillator with $\eta=70\%$	75kV-0-75kVp, 100kHz, 103kW Triode based oscillator with $\eta=70\%$
9	Bulk Insulation	SF ₆ /N ₂ gas at 6kg/cm ² pressure	SF ₆ /N ₂ gas at 6kg/cm ² pressure
10	Stored Energy	2.7kJ	100-200J

Capacitor and diode rating & Connections

We currently have commercially available 3.3 nF capacitors rated at 40kV. However, for our Symmetrical Cockcroft Walton Generator aiming to achieve 1 MeV and 100 mA with 15 stages, we require 19.8nF per stage capacitance with a working voltage of 90kV (rating 120kV). To meet this requirement, we connect three 3.3 nF capacitors in series, resulting in a total voltage rating of 120 kV. We repeat this arrangement 18 times in parallel to achieve the desired capacitance of 19.8 nF at the required voltage.

Two critical properties of diodes play a crucial role in selecting the appropriate diode for use in a Symmetrical Cockcroft Walton Generator:

1. *Peak Inverse Voltage (PIV):*

- PIV, also known as reverse breakdown voltage, represents the maximum reverse voltage that a diode or PN-junction can withstand in a non-conducting state (reverse bias) before breakdown occurs.
- Ensuring that the diode's PIV rating exceeds the maximum reverse voltage encountered is essential for safe operation during reverse bias conditions.

2. *Reverse Recovery Time (T_{rr}):*

- refers to the duration it takes for a diode to transition from its conducting state (ON) to its blocking state (OFF) when switching from forward bias to reverse bias.
- During this time, stored charge within the diode is discharged, allowing it to effectively block reverse current.
- Proper management of T_{rr} ensures smooth transitions and prevents voltage spikes.

We currently have HVRW-4 HV Diodes with a peak inverse voltage (PIV) rating of 4 kV, a current capacity of 1 A, and a reverse recovery time (T_{rr}) of 150 ns. However, our requirement is for HV Diodes with a PIV of 90 kV. To achieve this, we connect the HVRW-4 diodes in series to ensure smooth operation. Specifically, we connect 36 diodes in series within each stage.

Calculation of SCW multiplier Output Voltage at loaded condition

$$V_i = 45kV - 0 - 45kV$$

$$N = 15$$

$$f = 10kHz$$

$$C = 20nF$$

$$I = 100mA$$

$$V_L = 2NV_i - \frac{I}{fC} \left(\frac{N^3}{6} + \frac{N^2}{4} + \frac{N}{3} \right) \pm \frac{NI}{2fC}$$

$$V_L = (2 \times 15 \times 45) - \left(\frac{0.1}{10^4 \times 20 \times 10^{-9}} \right) (623.75) \pm \frac{15 \times 0.1}{2 \times 10^4 \times 20 \times 10^{-9}}$$

$$V_L = (1350kV) - (311.875kV) \pm (3.75kV)$$

$$V_L = (1350kV) - (311.875kV) \pm (3.75kV)$$

$$V_L = (1.038MV) \pm (3.75kV)$$

$$\text{No Load Voltage} = 1.350MV$$

$$\text{Load Voltage} = 1.038MV$$

$$\text{Regulation} = 311.875kV$$

$$\text{Ripple} = 3.75kV$$

$$\% \text{ Voltage Regulation} = 23.10\%$$

$$\% \text{ Ripple} = 0.277\%$$

Applications of Cockcroft-Walton Circuits

1. High-Voltage Power Supplies:

- The symmetrical Cockcroft-Walton circuit is commonly employed to generate high DC voltages efficiently.
- It is used in X-ray machines, electron microscopes, and other medical and scientific equipment that require high-voltage power supplies.

2. Particle Accelerators:

- Particle accelerators, such as cyclotrons and linear accelerators, accelerate charged particles (e.g., protons, electrons) to high energies.
- Its simplicity and scalability make it suitable for use in particle accelerators.

3. Nuclear Physics Experiments:

- In nuclear physics research, experiments often require high voltages to accelerate particles or create electric fields.
- The Cockcroft-Walton circuit can supply the needed voltages for ionization chambers, detectors, and other equipment.

4. Electrostatic Precipitators:

- Electrostatic precipitators are used to remove particulate matter (dust, smoke, etc.) from industrial exhaust gases.
- The high-voltage output of the Cockcroft-Walton circuit charges the plates in these precipitators, attracting and collecting particles.

5. Photomultiplier Tubes (PMTs):

- PMTs are sensitive light detectors used in applications like scintillation detectors, fluorescence measurements, and night vision devices.
- The Cockcroft-Walton circuit provides the necessary high voltage to accelerate photoelectrons within PMTs.

6. Ion Implantation in Semiconductor Manufacturing:

- Ion implantation is a key process in semiconductor manufacturing.
- The Cockcroft-Walton circuit can generate the high voltages needed to accelerate ions into the semiconductor substrate.

Simulation of 15 stage symmetrical Cockcroft Walton

We have simulated the SCWM circuit in LTSpice and use ideal diodes and capacitors, replacing the transformer with two independent voltage sources. Additionally, we assume default values for the diode's Peak Inverse Voltage (PIV) and Reverse Recovery Time (T_{rr}), which are infinite and 0 seconds, respectively. The simulation duration is 200 milliseconds to ensure steady state condition is achieved. Data recording begins at 199 milliseconds to minimise LT Spice raw file size, with a time step of 10 nanoseconds to get smooth waveform. Smaller the time step, more will be simulation run time.

SCWM have two AC column and one DC Column.

At No Load:

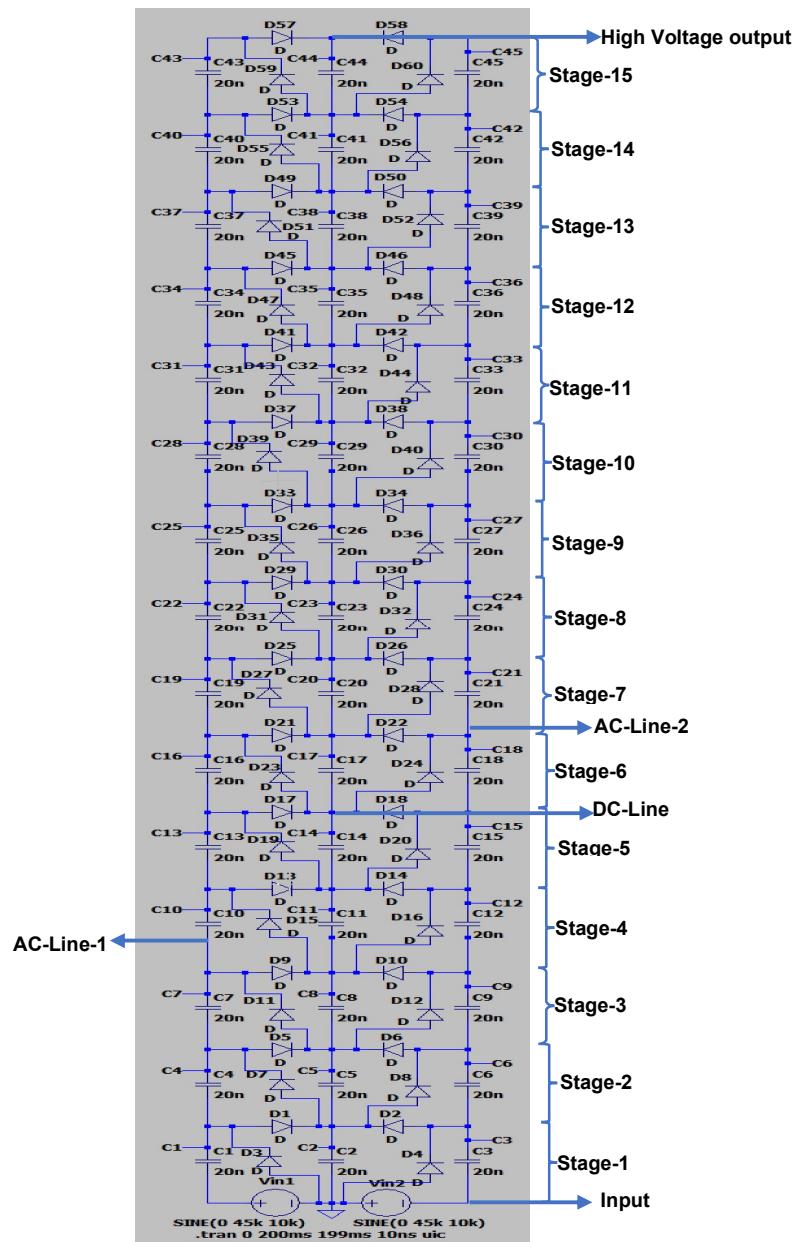


Figure- 5: Simulation at No Load Condition

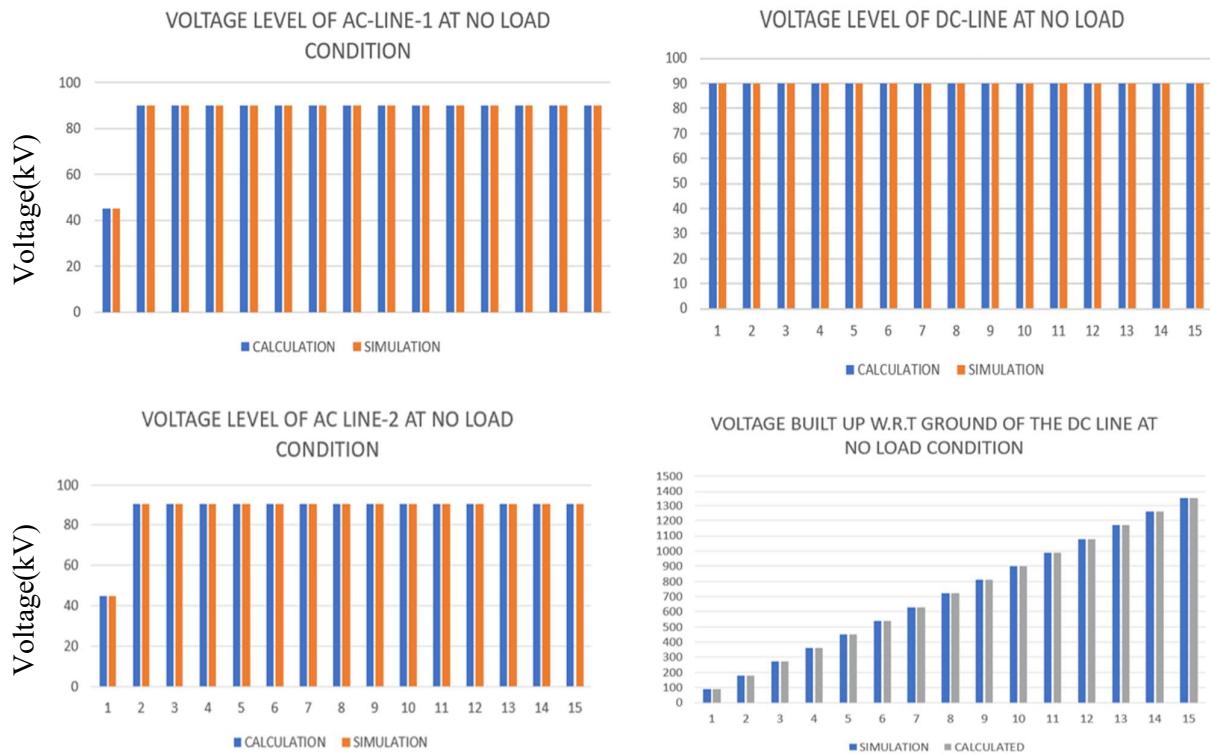
Voltage Level(At No load):

STAGE	AC-1(kV)	DC(kV)	AC-2(kV)	Voltage Built up w.r.t Ground(kV)
1	44.99	89.99	44.99	89.99
2	89.99	89.99	89.99	179.99
3	89.99	89.99	89.99	269.99
4	89.99	89.99	89.99	359.99
5	89.99	89.99	89.99	449.99
6	89.99	89.99	89.99	539.99
7	89.99	89.99	89.99	629.98
8	89.99	89.99	89.99	719.98
9	89.99	89.99	89.99	809.98
10	89.99	89.99	89.99	899.97
11	89.99	89.99	89.99	989.97
12	89.99	89.99	89.99	1079.99
13	89.99	89.99	89.99	1169.995
14	89.99	89.99	89.99	1259.94
15	89.99	89.99	89.99	1349.93

Input Voltage Level:

INPUT VOLTAGE	
Vin (kV)(1)	Vin (kV)(2)
44.99	44.99

GRAPHICAL REPRASENTATION OF VOLTAGE LEVEL AT NO LOAD



Waveform of Voltage at Different stages and input Voltage

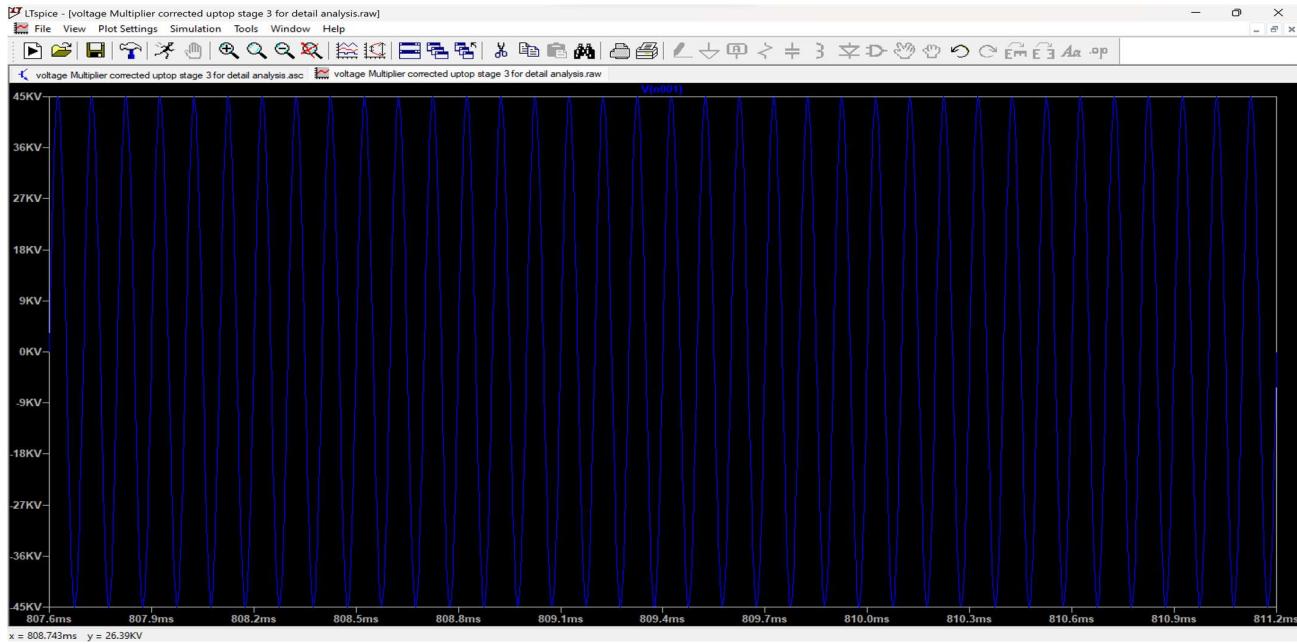


Figure-6: Input Voltage at ACLine-1(45kV)

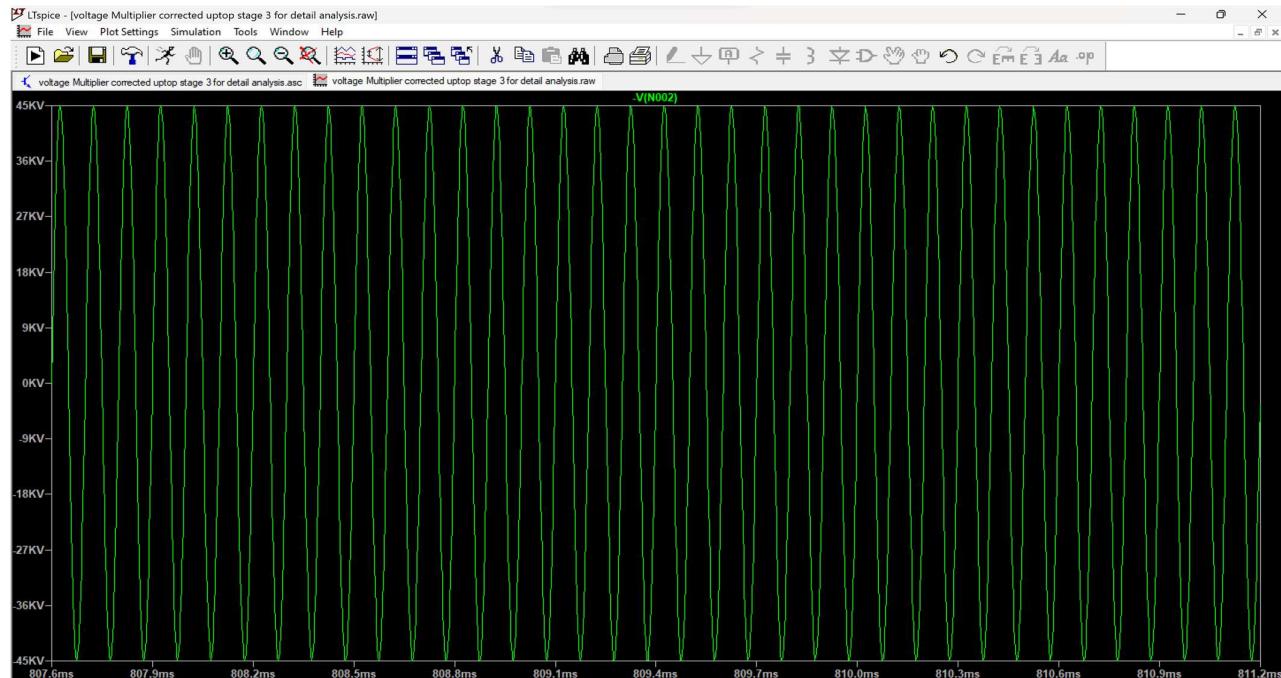


Figure-7: Input Voltage at ACLine-2(45kV)

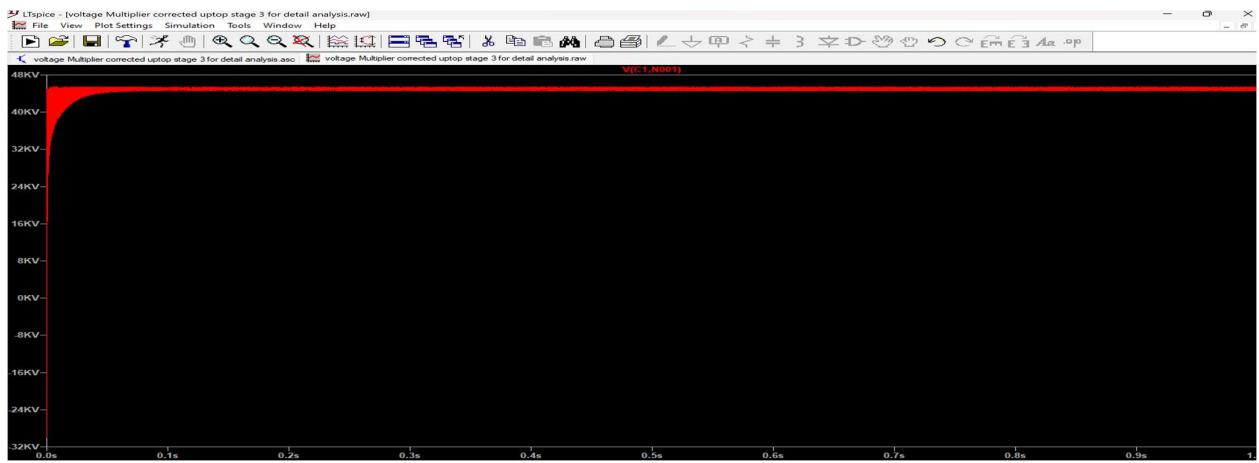


Figure-8: Voltage across Stage-1 Capacitor of ACLine-1

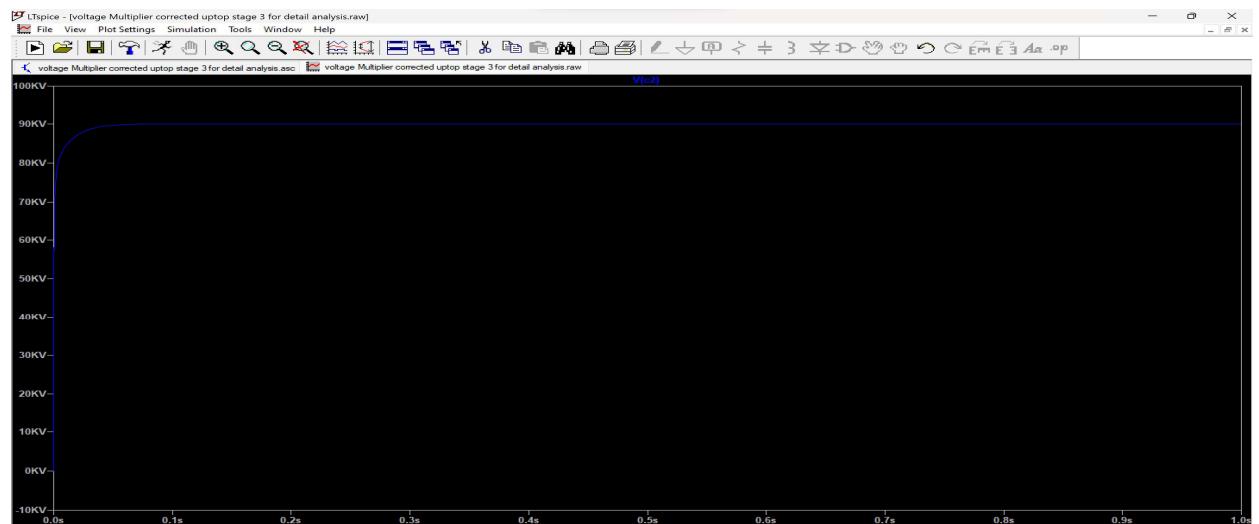


Figure-9: Voltage across Stage-1 Capacitor of DC Line

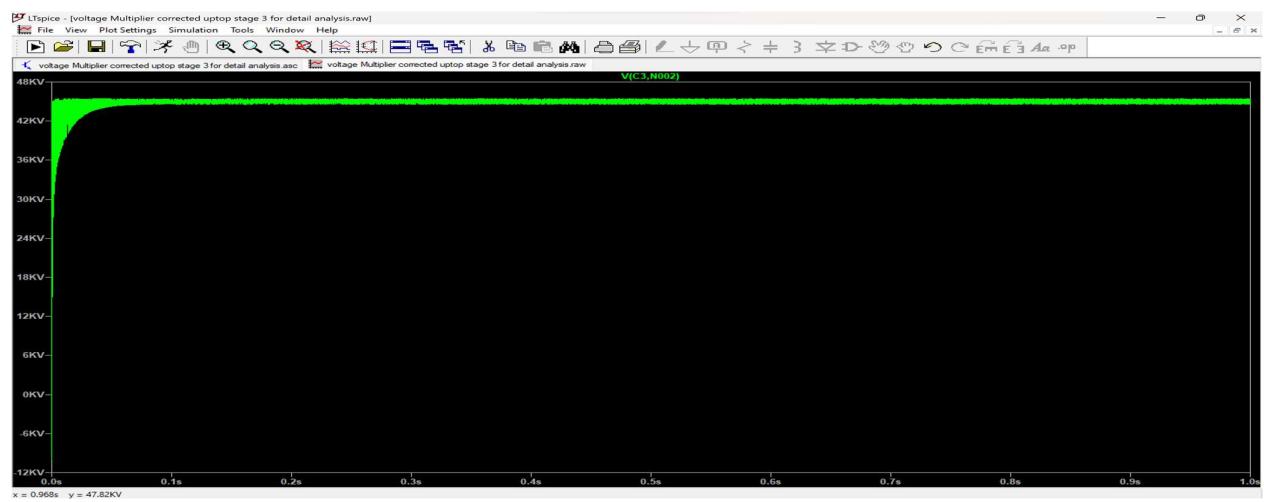


Figure-10: Voltage across Stage-1 Capacitor of ACLine-2



Figure-11: Voltage across Stage-2 Capacitor of ACLine-1

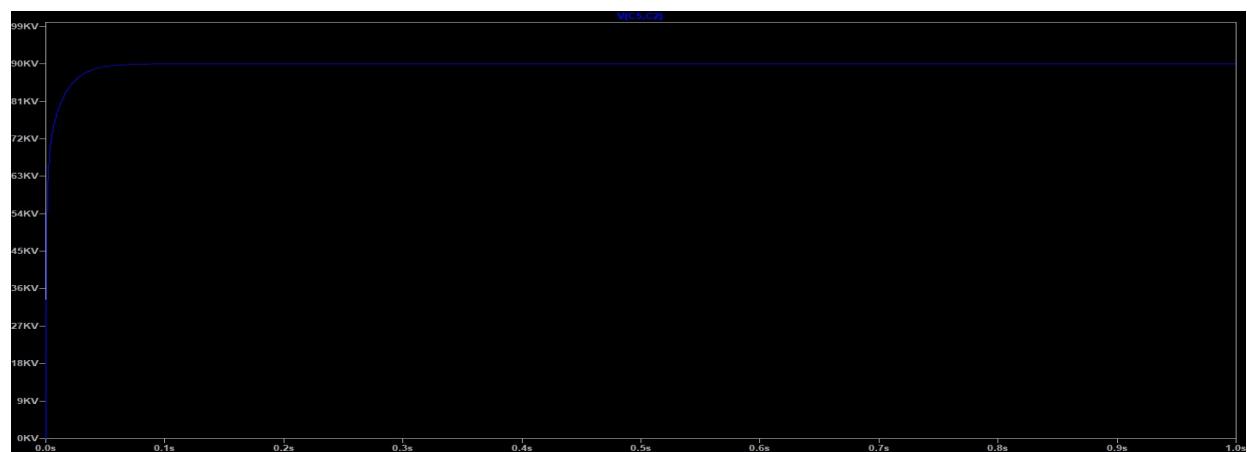


Figure-12: Voltage across Stage-2 Capacitor of DC Line

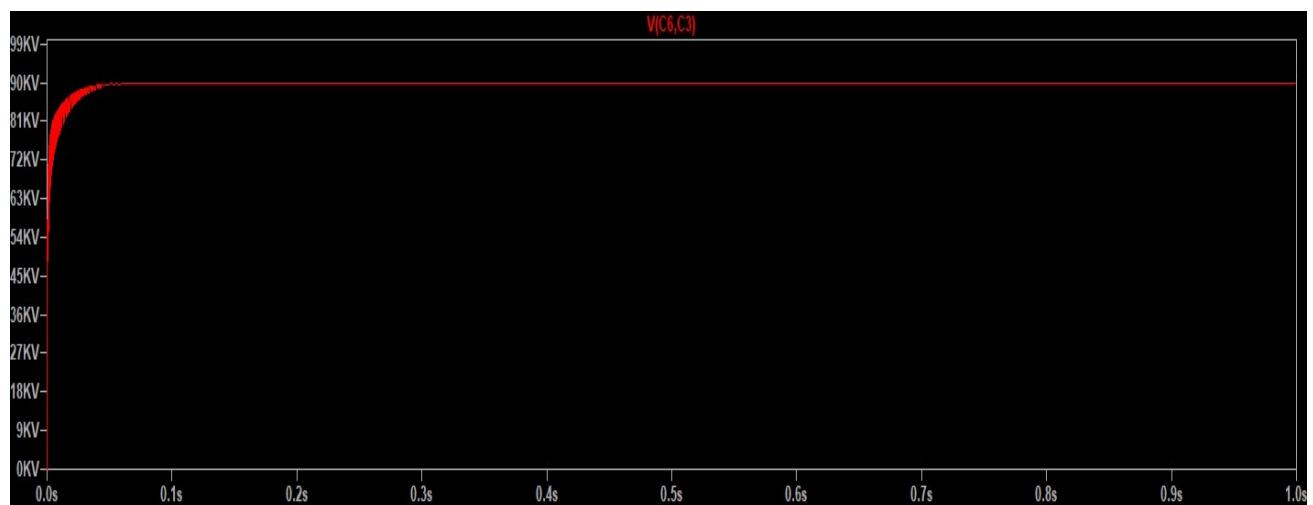


Figure-13: Voltage across Stage-2 Capacitor of ACLine-2

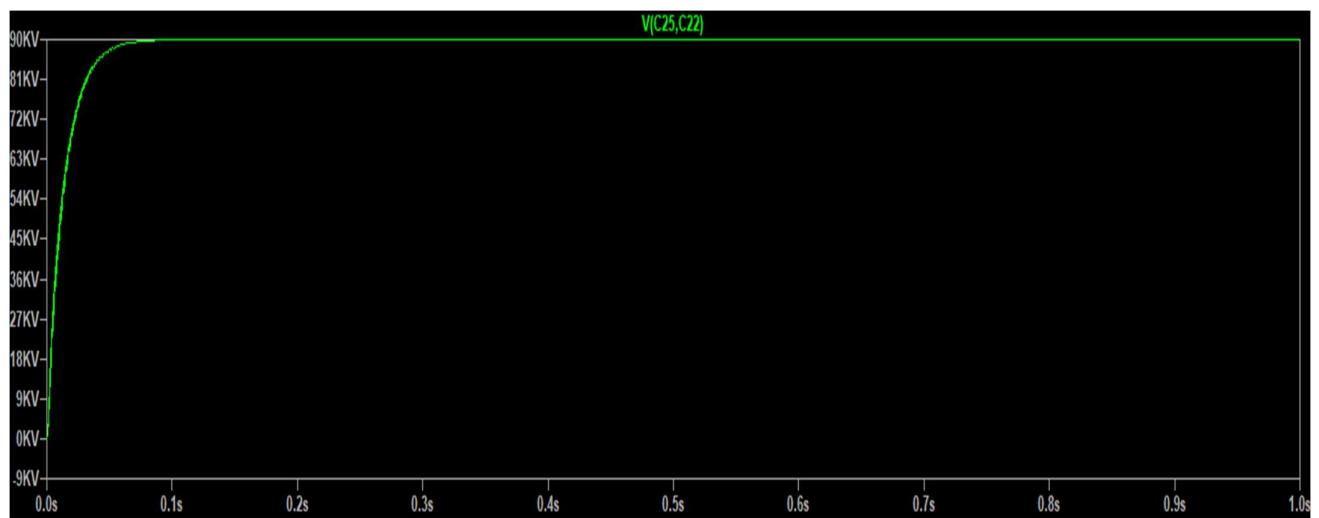


Figure-14: Voltage across stage -9 Capacitor of AC Line-1

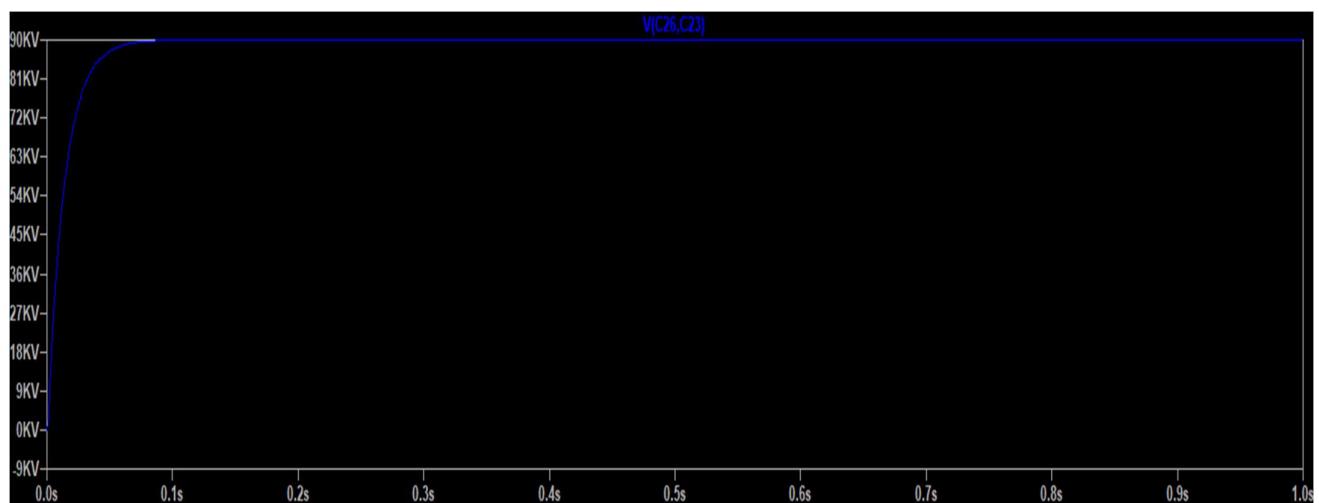


Figure-15: Voltage across Stage-9 of DC Line

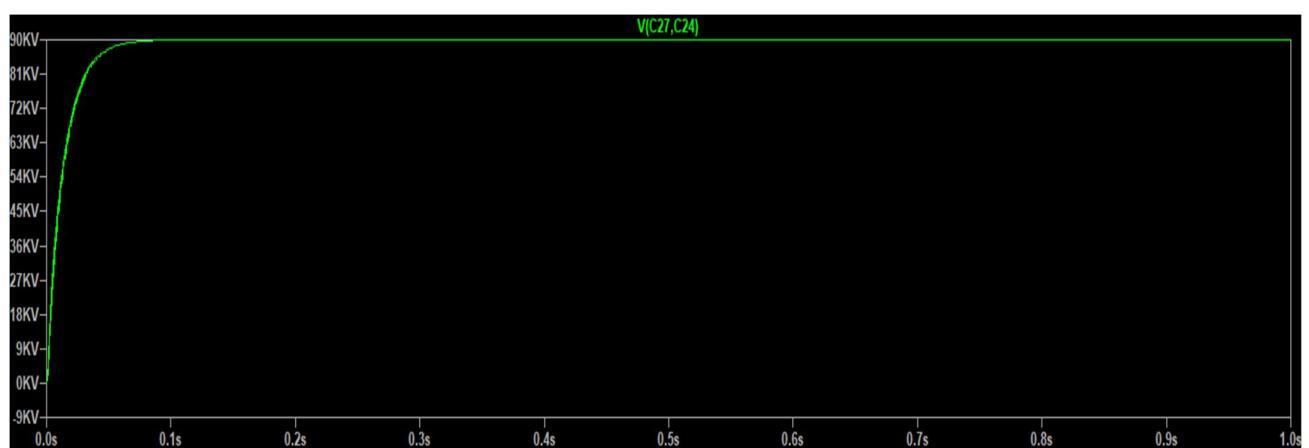


Figure-16: Voltage across Stage-9 Capacitor of AC Line-2

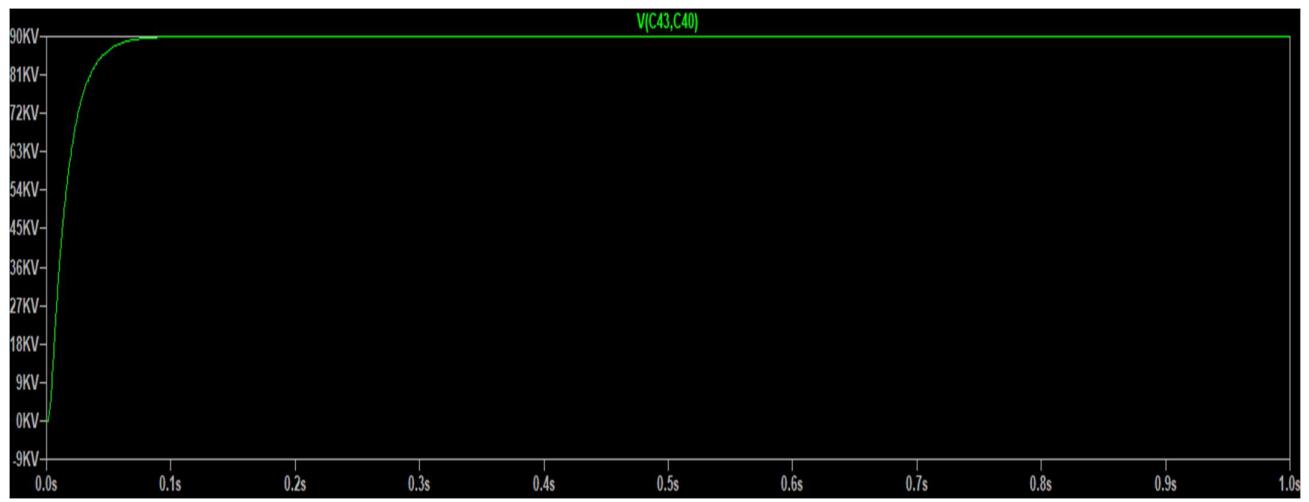


Figure-17: Voltage across Stage-15 Capacitor of ACLine-1

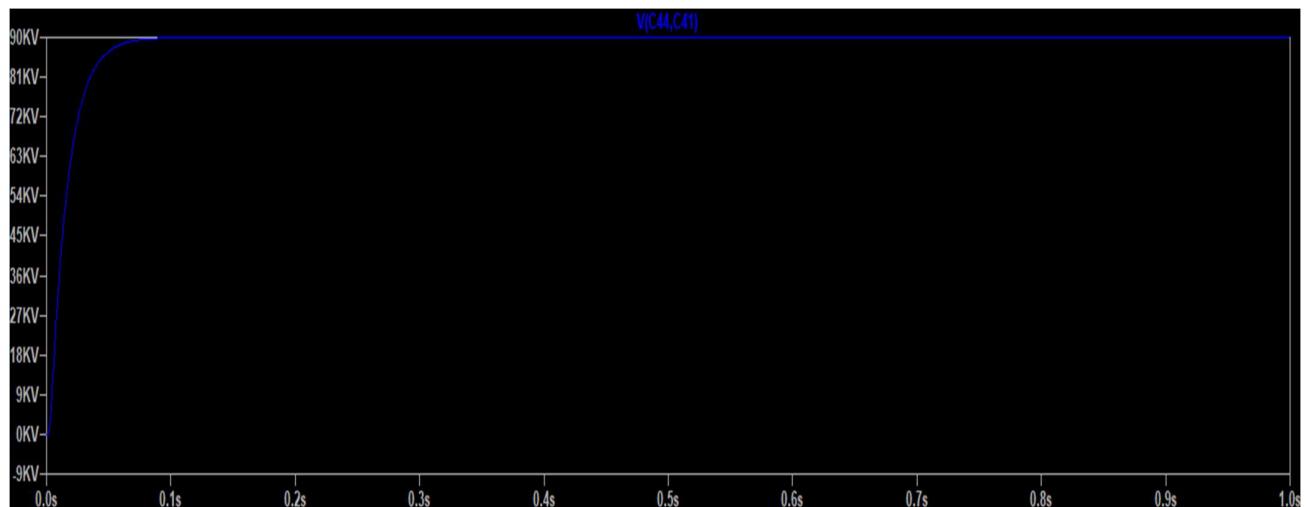


Figure-18: Voltage across Stage-15 Capacitor of DC Line

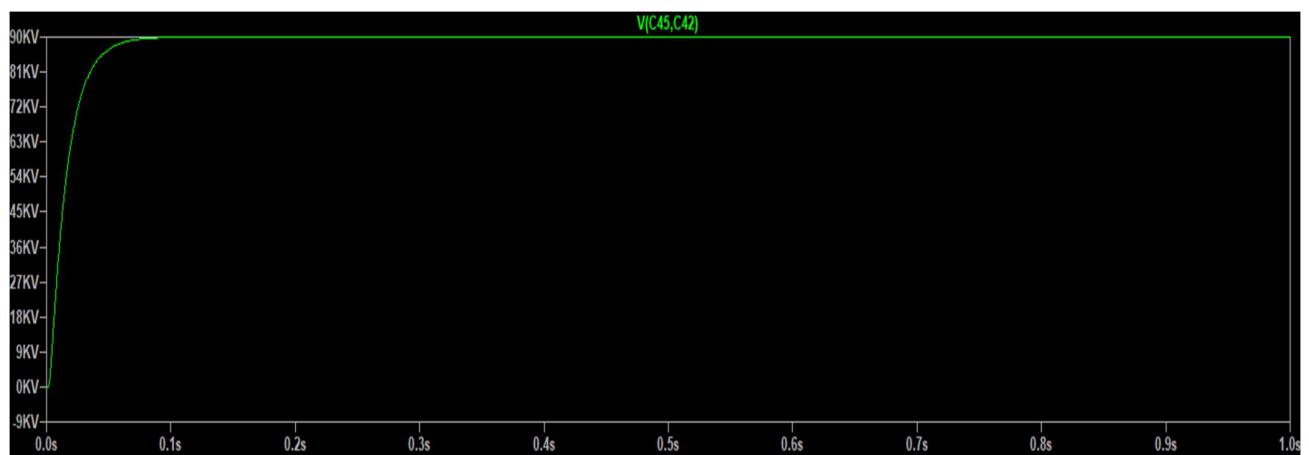


Figure-19: Voltage across Stage-15 Capacitor of ACLine-2

Stage Capacitor Current at No Load:

STAGE	AC-LINE-1		DC-LINE		AC-Line-2	
	MAX(A)	RMS(A)	MAX(A)	RMS(A)	MAX(A)	RMS(A)
1	0.0239258	0.000122939	0.0296224	8.24E-06	0.0228068	0.000122784
2	0.0232747	0.000118087	0.0297852	8.53E-06	0.0228678	0.000117933
3	0.0238851	0.000111926	0.0292358	8.37E-06	0.0227458	0.000111772
4	0.0257568	0.000104936	0.0302734	8.64E-06	0.0224609	0.00010478
5	0.0249430	9.73E-05	0.0301107	8.56E-06	0.0233154	9.72E-05
6	0.0225016	8.91E-05	0.0313721	8.49E-06	0.0223796	8.91E-05
7	0.0233968	8.07E-05	0.0280151	9.64E-06	0.0222982	8.06E-05
8	0.0190430	7.19E-05	0.0280762	1.04E-05	0.0220947	7.19E-05
9	0.0209147	6.29E-05	0.024821	9.16E-06	0.0224202	6.29E-05
10	0.0187174	5.38E-05	0.0256348	8.86E-06	0.0202637	5.38E-05
11	0.0165202	4.48E-05	0.0258789	8.96E-06	0.0187174	4.44E-05
12	0.0156250	3.57E-05	0.0256755	1.06E-05	0.0166423	3.52E-05
13	0.0142415	2.62E-05	0.0209351	8.08E-06	0.0159912	2.63E-05
14	0.0141602	1.65E-05	0.0142415	6.14E-06	0.00960286	1.70E-05
15	0.0068766	7.29E-06	0.00683594	4.84E-06	0.00793457	7.59E-06

Input Current

INPUT CURRENT AT NO LOAD

I _{in(1)}	I _{in(2)}
13.1866mA	12.8952mA
76.107µA	76.389µA

Diode Voltage and Current :

Stage	Diode no.	Current		Voltage (Max) (V) (N-P)
		Max (A)	RMS (A)	
1	1	0.000262217	4.11E-06	89999.4
	2	0.000264632	4.11E-06	89999.4
	3	0.000203351	3.17E-06	89999.4
	4	0.00020182	3.17E-06	89999.4
2	5	0.000305113	4.77E-06	89999.4
	6	0.000306252	4.76E-06	89999.4
	7	0.000278911	4.35E-06	89999.4
	8	0.000277921	4.35E-06	89999.4
3	9	0.000336334	5.26E-06	89999.4
	10	0.000334327	5.25E-06	89999.4
	11	0.000313646	4.93E-06	89999.4
	12	0.00031514	4.94E-06	89999.4
4	13	0.000360458	5.64E-06	89999.3
	14	0.000358526	5.63E-06	89999.3
	15	0.000341915	5.38E-06	89999.4
	16	0.000344183	5.39E-06	89999.4
5	17	0.000378202	5.94E-06	89999.4
	18	0.000379254	5.92E-06	89999.4
	19	0.000366746	5.74E-06	89999.4
	20	0.000365049	5.75E-06	89999.4
6	21	0.000395995	6.15E-06	89999.3
	22	0.000392912	6.14E-06	89999.3
	23	0.000383975	6.00E-06	89999.3
	24	0.000386109	6.01E-06	89999.3
7	25	0.000408518	6.32E-06	89999.4
	26	0.000401494	6.31E-06	89999.4
	27	0.000378202	5.94E-06	89999.4
	28	0.000401791	6.22E-06	89999.4
8	29	0.000415525	6.43E-06	89999.4
	30	0.000412308	6.42E-06	89999.4
	31	0.000406981	6.35E-06	89999.4
	32	0.000411796	6.37E-06	89999.4
9	33	0.000419593	6.51E-06	89999.4
	34	0.000422102	6.50E-06	89999.4
	35	0.000418047	6.46E-06	89999.4
	36	0.000418309	6.47E-06	89999.4
10	37	0.000423404	6.56E-06	89999.4
	38	0.000428111	6.55E-06	89999.4
	39	0.000425846	6.53E-06	89999.4
	40	0.00042154	6.54E-06	89999.4
11	41	0.000428212	6.59E-06	89999.4
	42	0.000431802	6.58E-06	89999.4
	43	0.000430876	6.57E-06	89999.3
	44	0.000426303	6.58E-06	89999.4
12	45	0.000430724	6.60E-06	89999.4
	46	0.0004334	6.59826E-06	89999.4
	47	0.000433345	6.58E-06	89999.3
	48	0.000429536	6.60E-06	89999.3
13	49	0.000432179	6.60E-06	89999.3
	50	0.000434144	6.59E-06	89999.4
	51	0.000434885	6.59E-06	89999.4
	52	0.000431652	6.61E-06	89999.4
14	53	0.000433621	6.61E-06	89999.4
	54	0.000435196	6.60E-06	89999.4
	55	0.000434876	6.58E-06	89999.4
	56	0.000431896	6.60E-06	89999.4
15	57	0.000219	6.61E-06	89999.4
	58	0.000219056	6.61E-06	89998.4
	59	0.0004255	6.44E-06	89999.4
	60	0.000422838	6.45E-06	89999.4

Waveform of Diode Voltages and Current at each stage

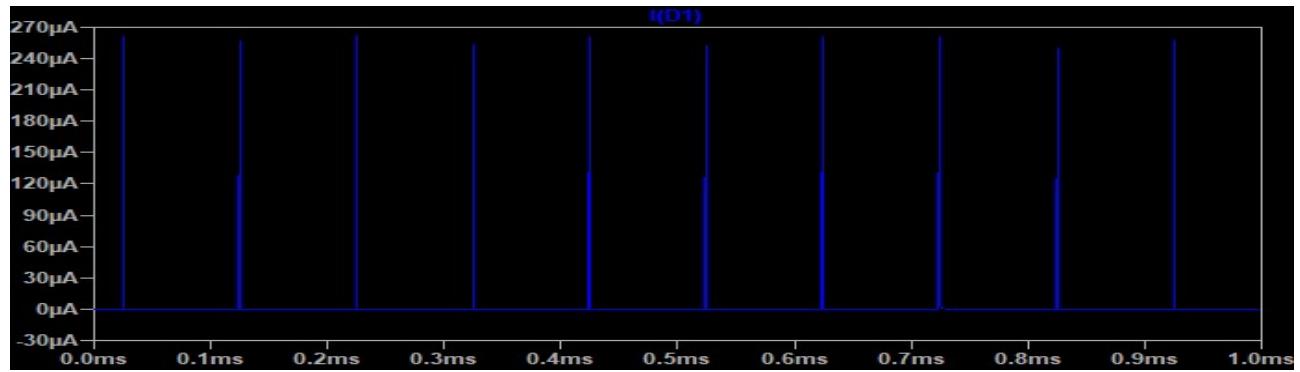


Figure-20: Current through D_1 (Stage-1)

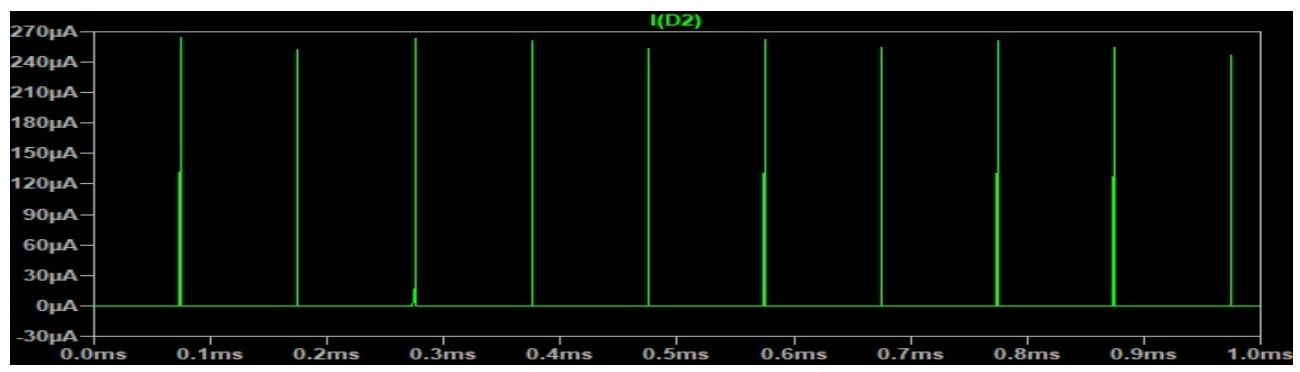


Figure-21: Current through D_2 (Stage-1)

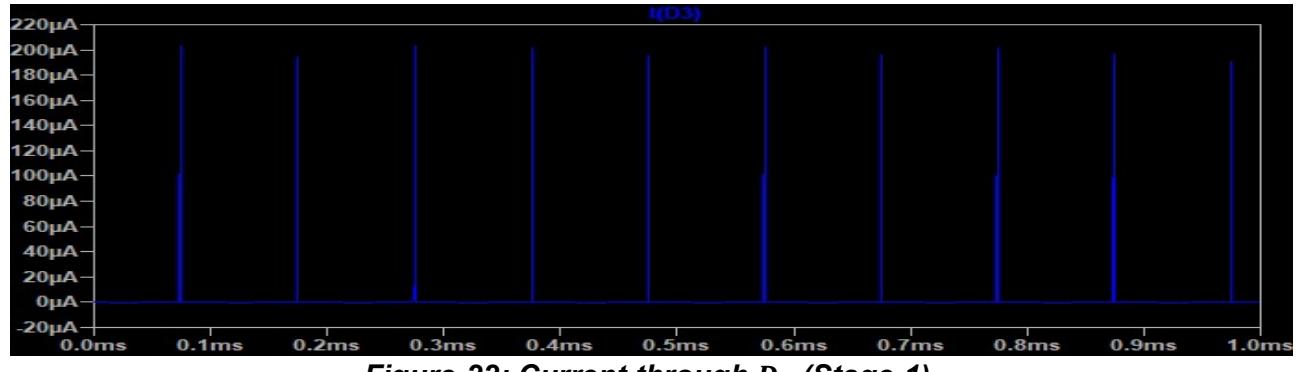


Figure-22: Current through D_3 (Stage-1)

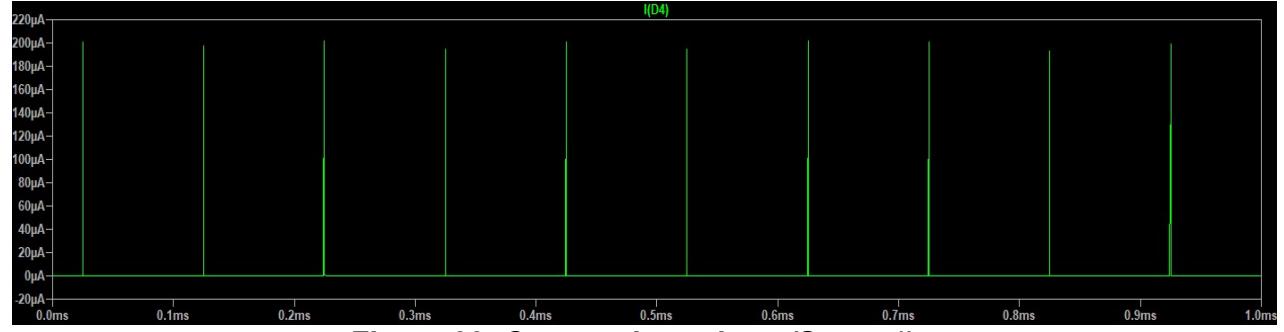


Figure-23: Current through D_4 (Stage-1)

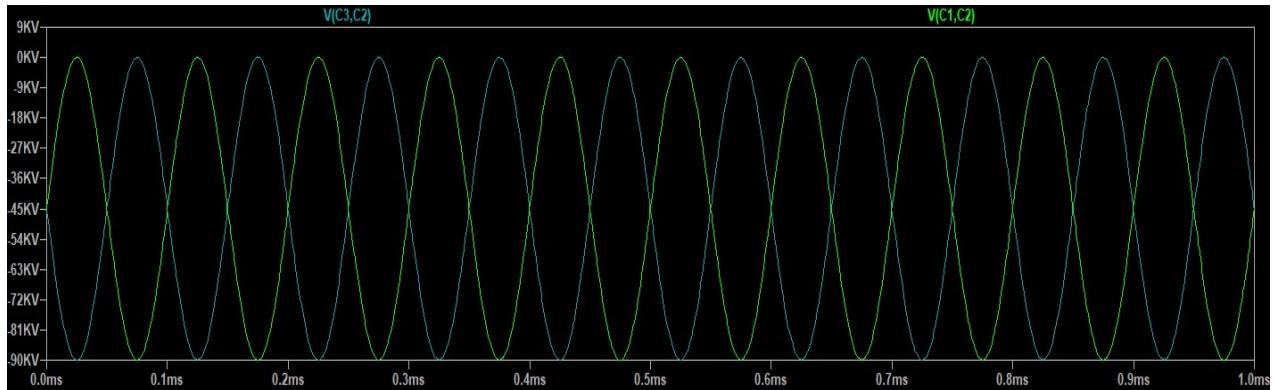


Figure-24: Voltage across D_1 and D_2 (Stage-1)

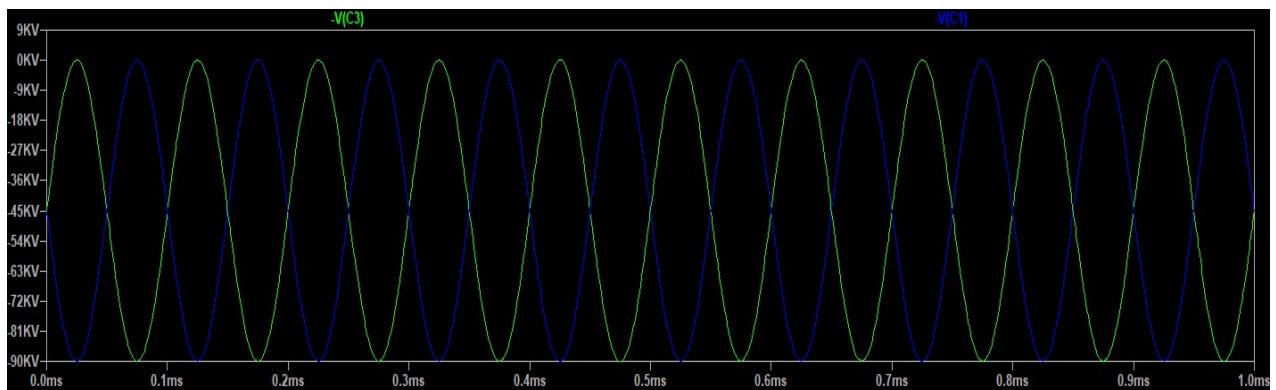


Figure-25: Voltage across D_3 and D_4 (Stage-1)

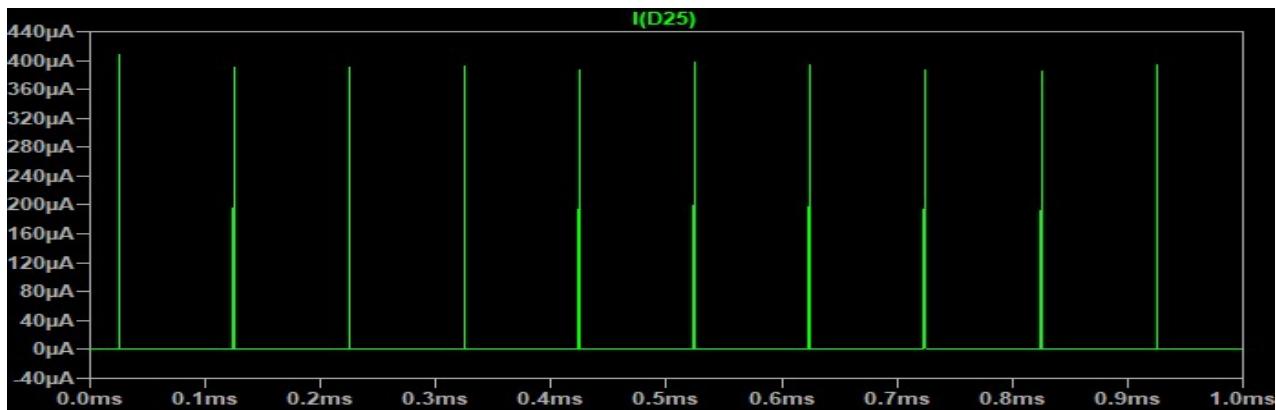


Figure-26: Current through D_{25} (Stage-7)

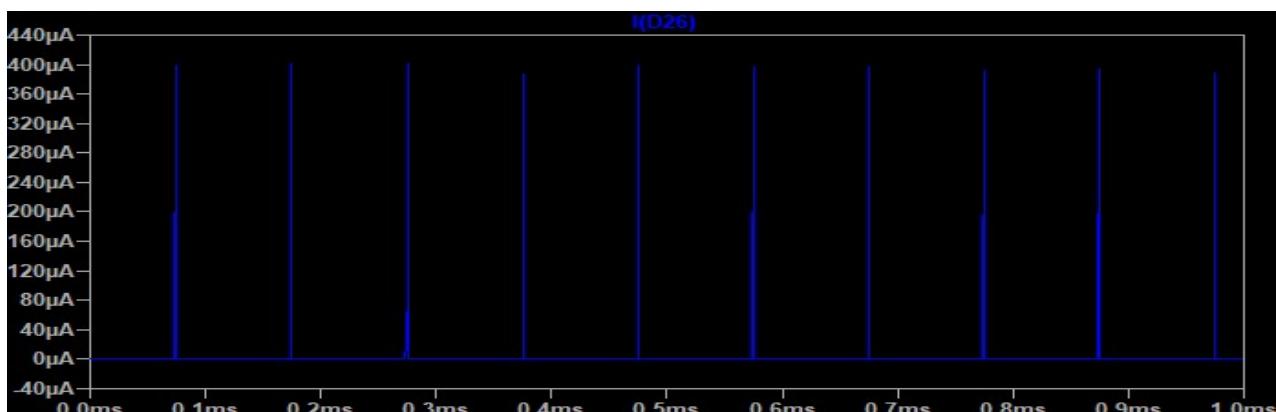


Figure-27: Current through D_{26} (Stage-7)

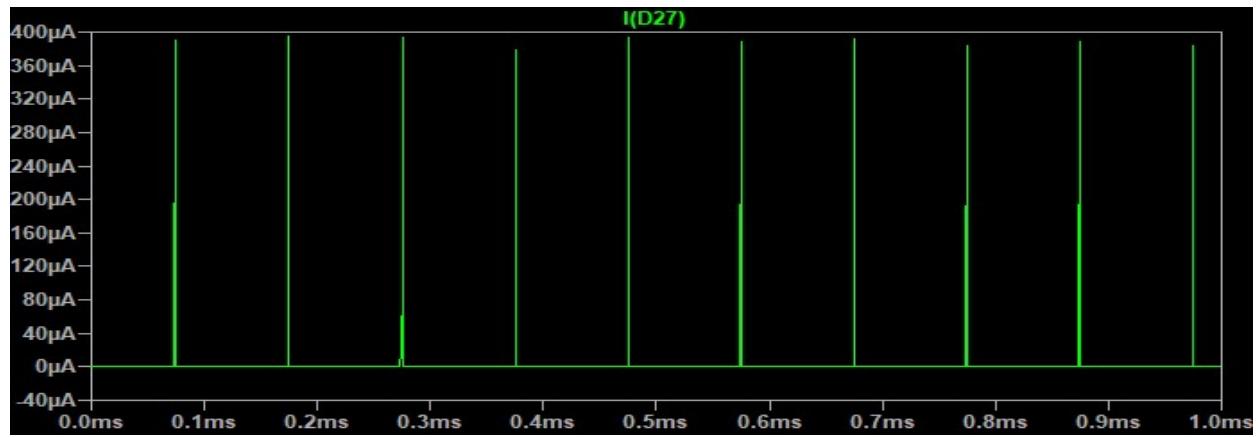


Figure-28: Current through D_{27} (Stage-7)

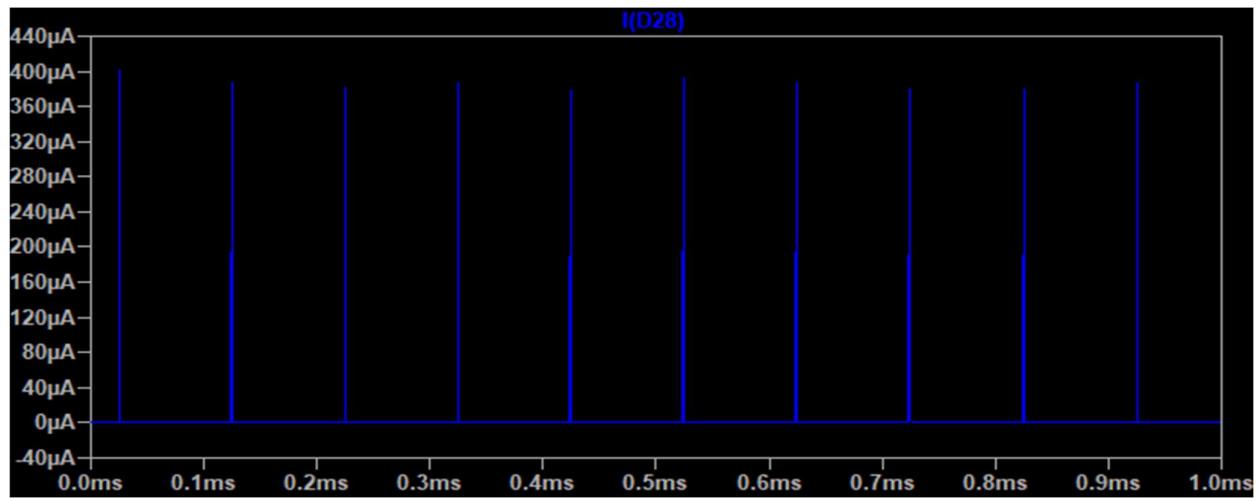


Figure-29: Current through D_{28} (Stage-7)

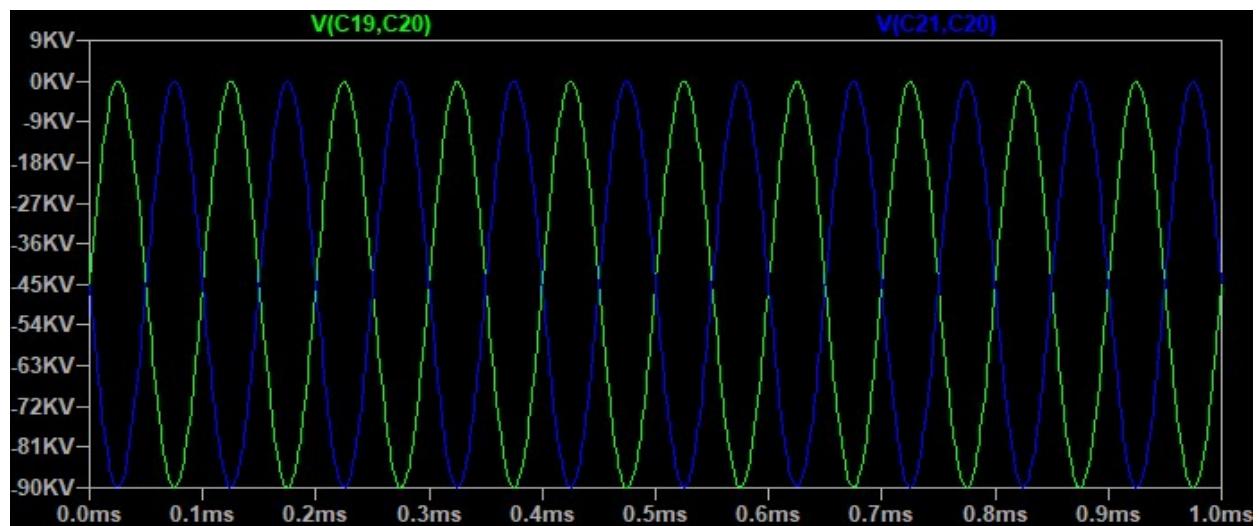


Figure-30: Voltage across D_{25} and D_{26} (Stage-7)

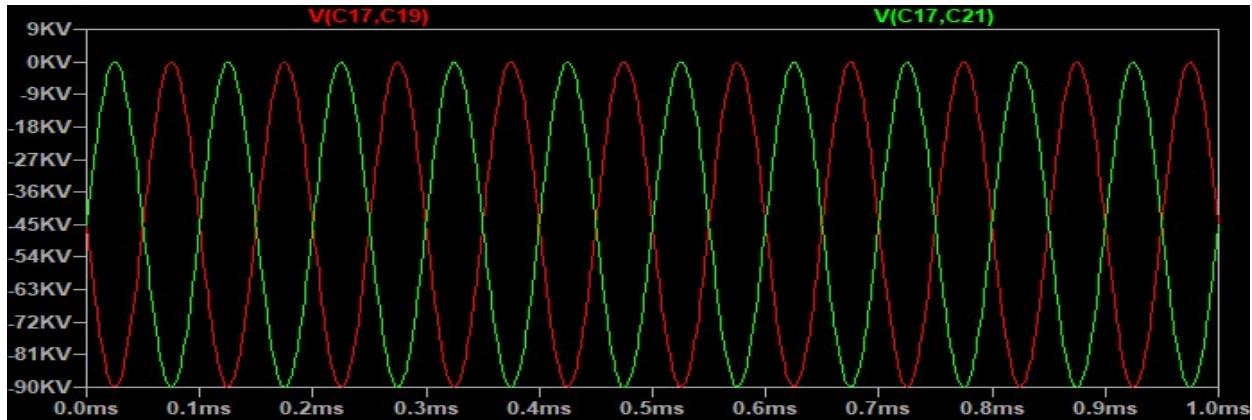


Figure-31: Voltage across D_{27} and D_{28} (Stage-7)

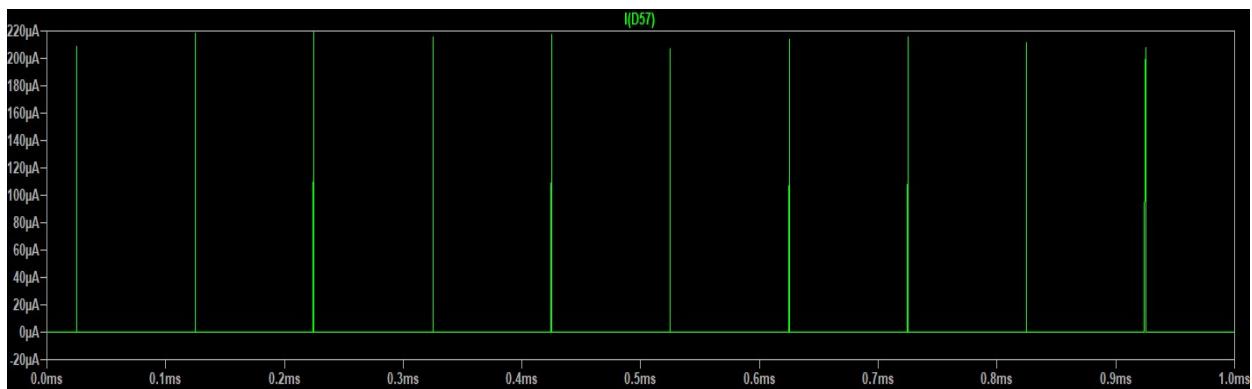


Figure-32: Current through D_{57} (Stage-15)

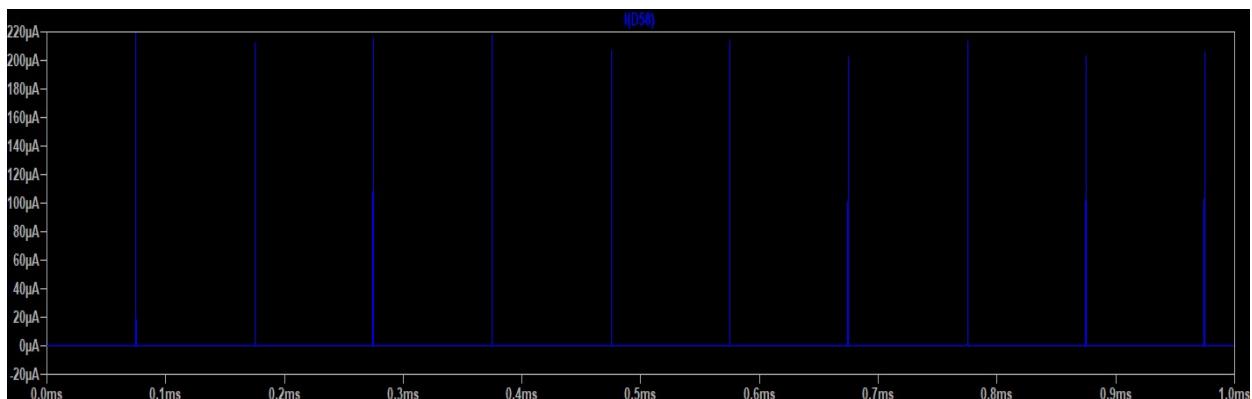


Figure-33: Current through D_{58} (Stage-15)

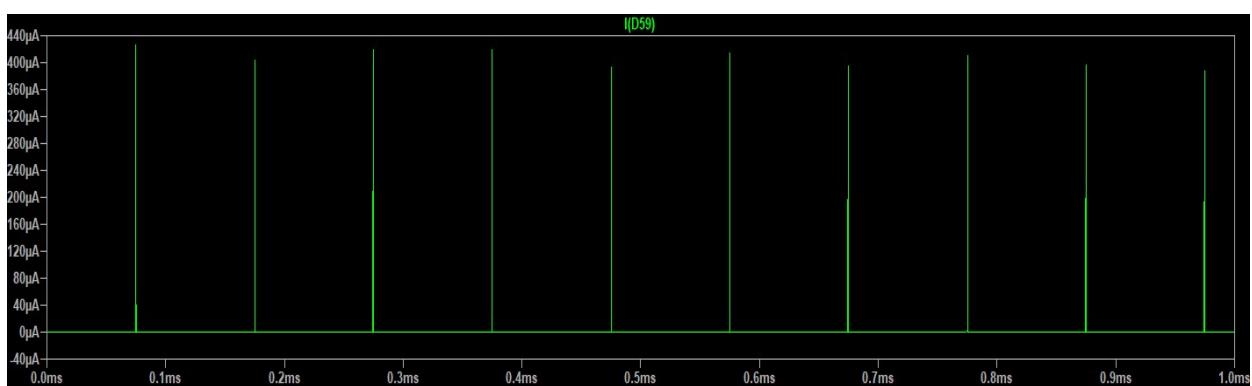


Figure-34: Current through D_{59} (Stage-15)

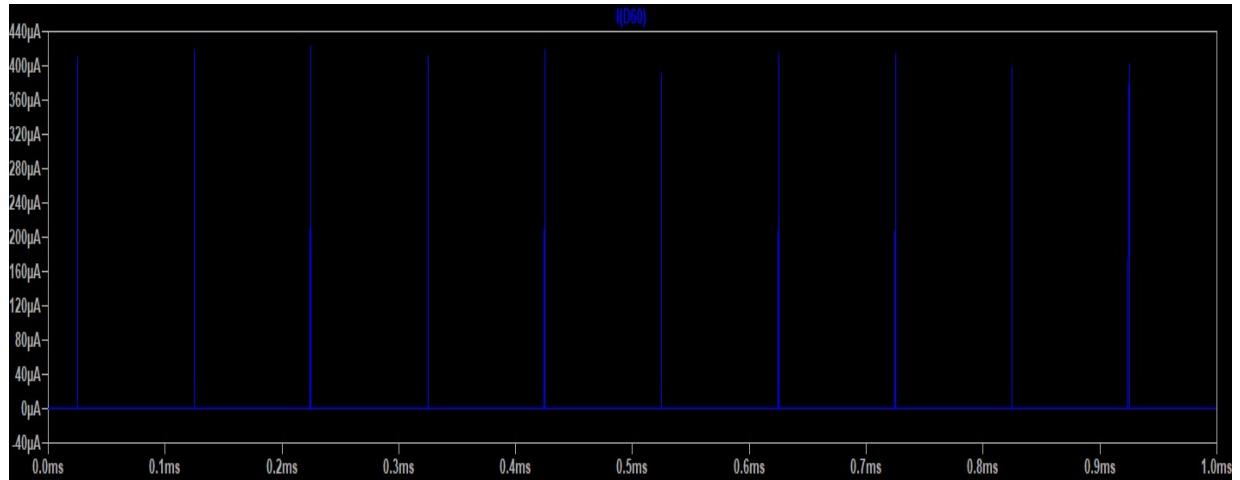


Figure-35: Current through D_{60} (Stage-15)

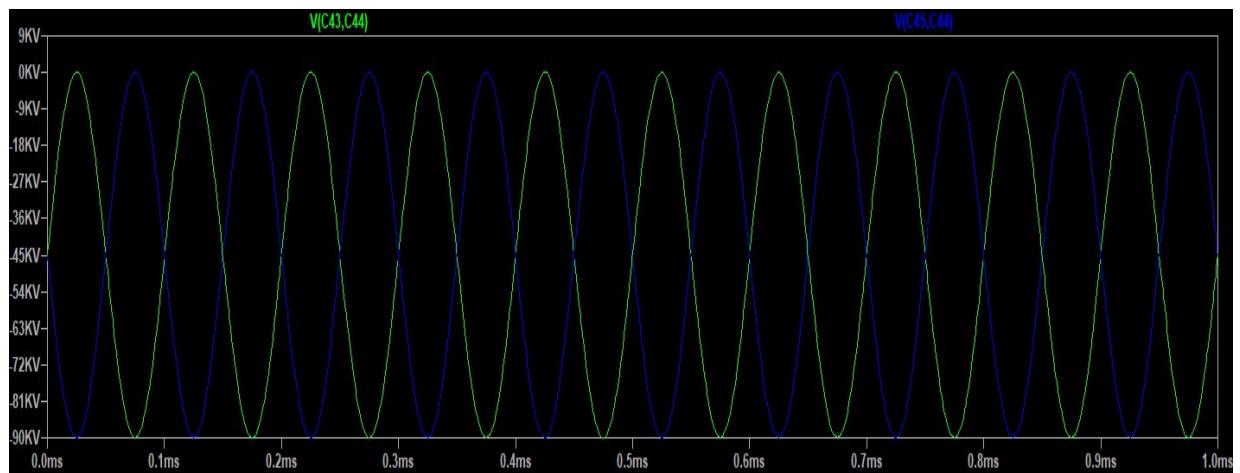


Figure-36: Voltage across D_{57} and D_{58} (Stage-15)

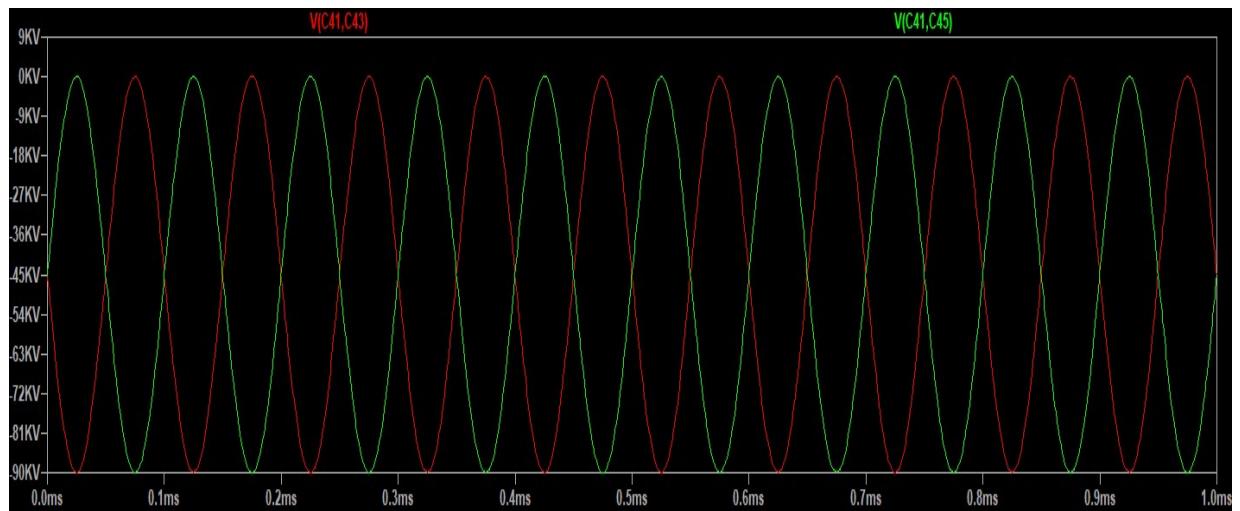


Figure-37: Voltage across D_{59} and D_{60} (Stage-15)

At 100kW beam load (10MΩ Load):

Given that we require a **current of 100 mA** and the output DC voltage at the 15th stage is approximately **1 MV**, the **load resistance would be 10 MΩ**.

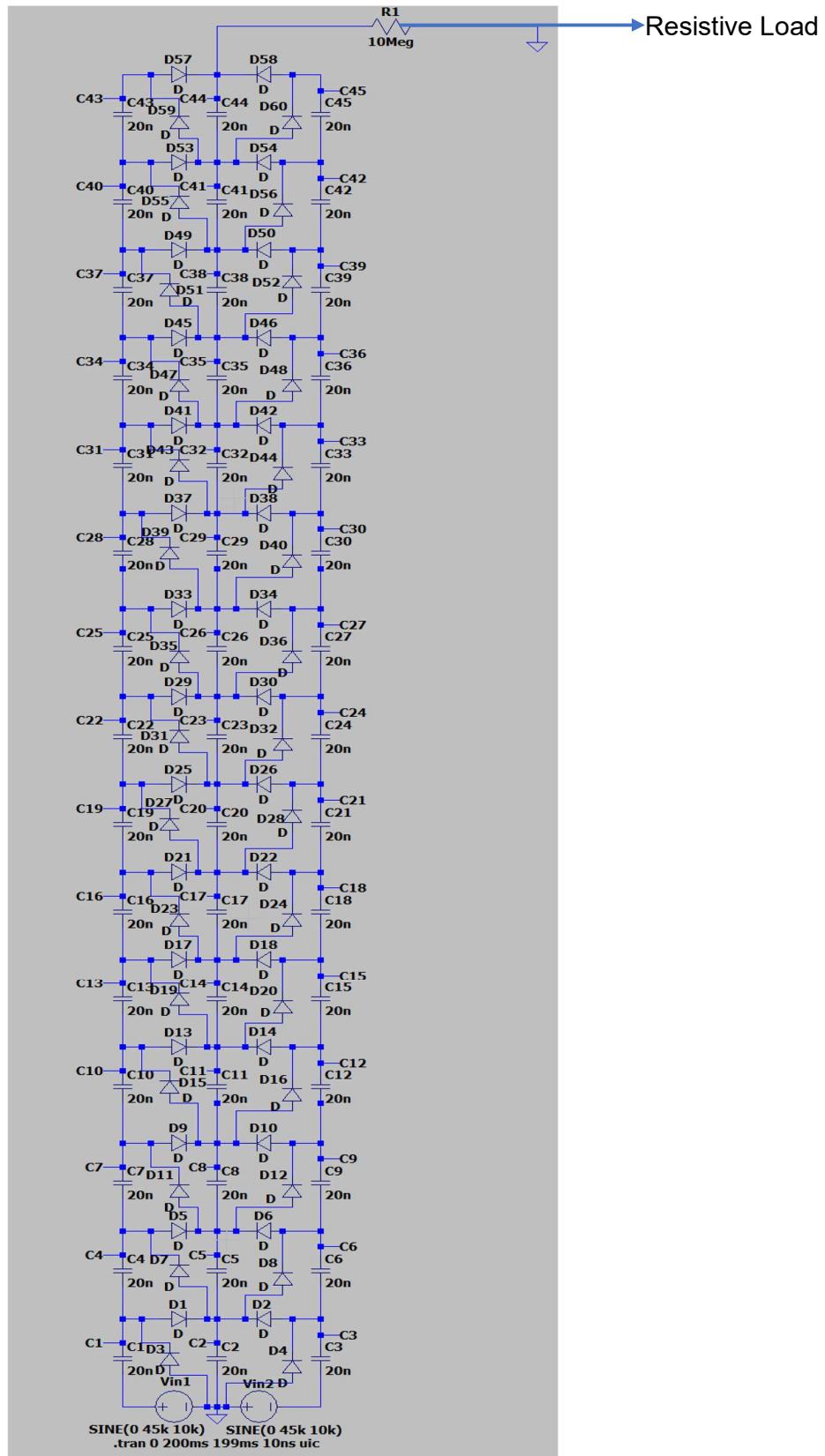
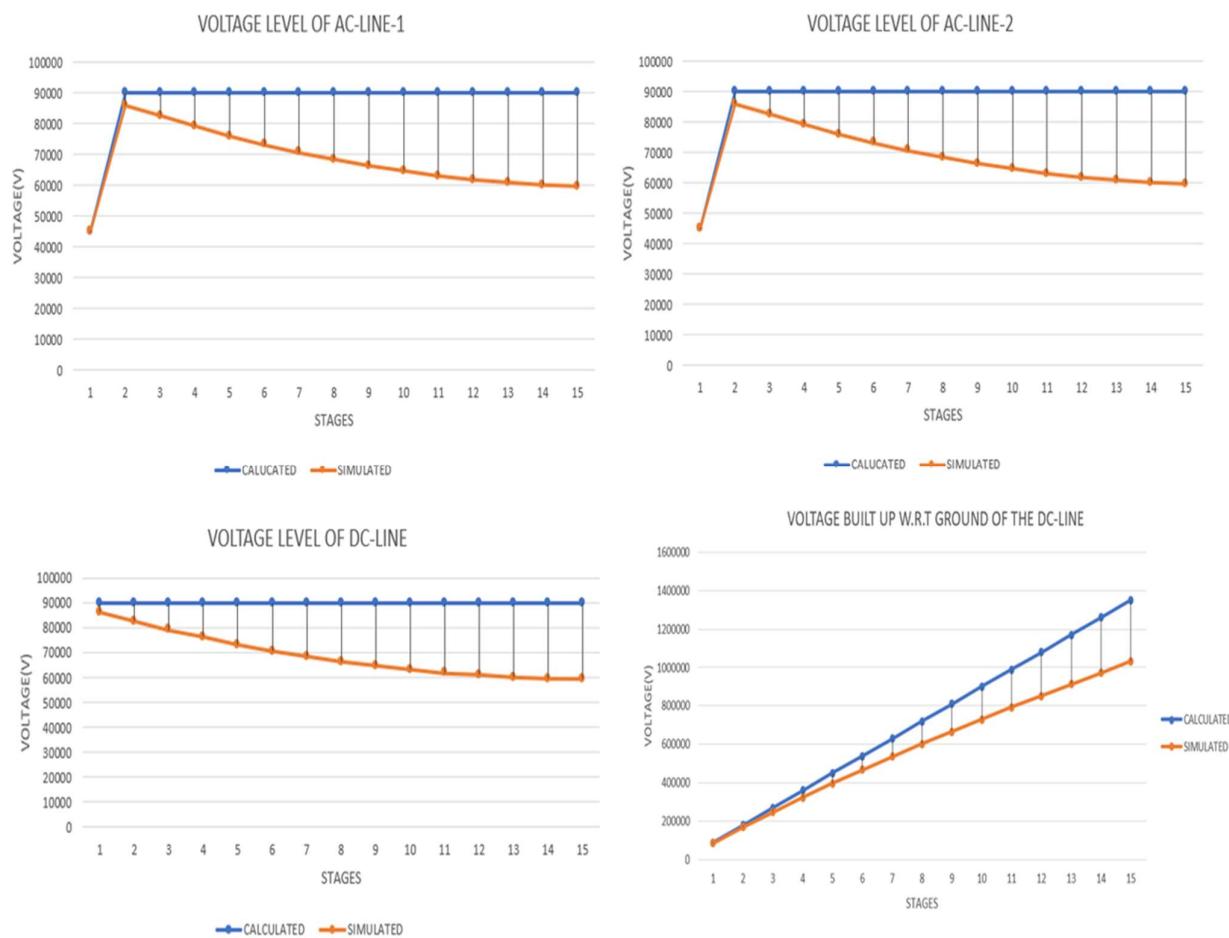


Figure-38: Simulation at Loaded Condition

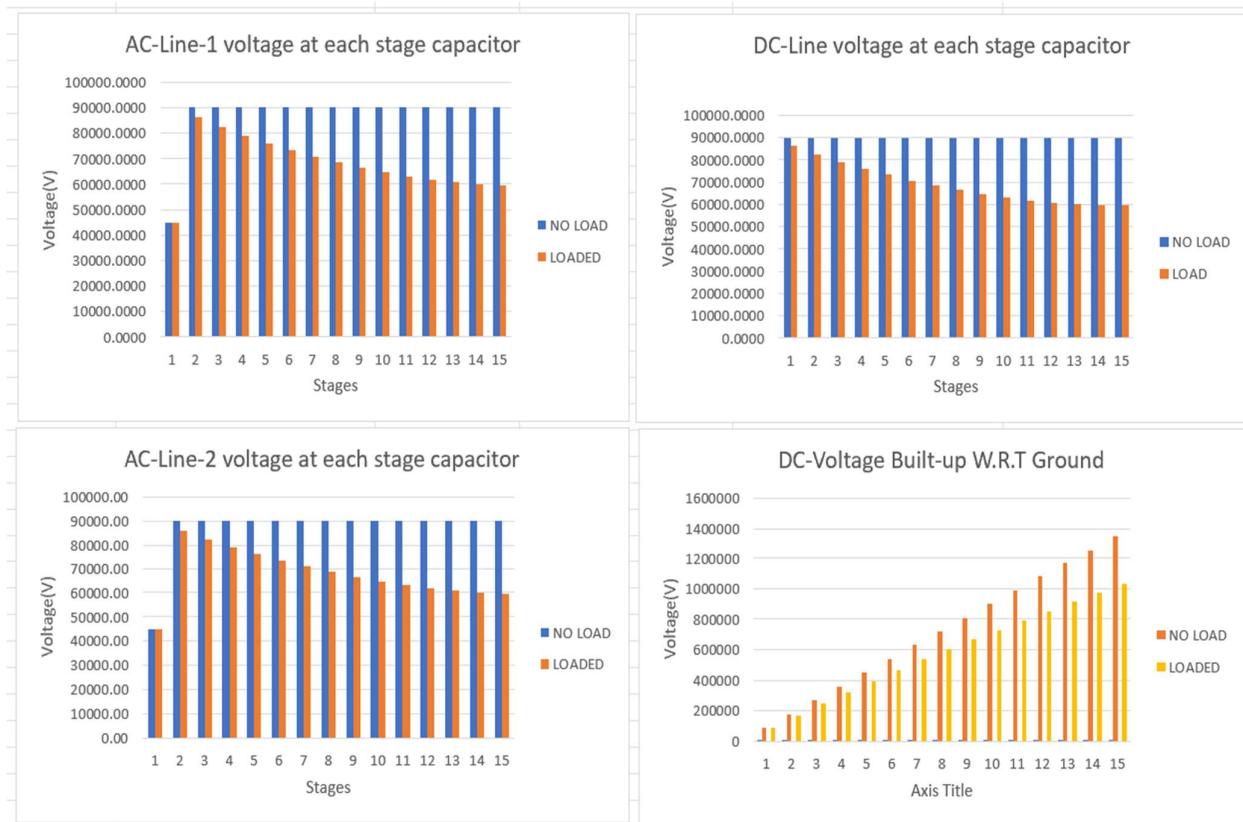
Voltage Level (At Loaded Condition):

Stage	AC-Line(1)	DC-Line	AC-Line(2)	Voltage Built up w.r.t Ground (V)
1	44999.3	86132.1	44999.3	86132.1
2	86132.1	82529.3	86132.1	168656
3	82529.5	79187.5	82529.4	247835
4	79187.6	76106.5	79187.6	323930
5	76106.6	73286.8	76106.6	397202
6	73286.9	70727.8	73286.9	467912
7	70728	68429.7	70727.9	536320
8	68429.7	66392.8	68429.9	602689
9	66392.9	64617.1	66392.9	667278
10	64617.1	63102.5	64617.4	730350
11	63102.7	61849	63102.7	792165
12	61849.3	60856.5	61848.9	852984
13	60856.8	60125.5	60856.6	913069
14	60125.8	59655.6	60125.5	972680
15	59655.6	59447.6	59655.8	1.03E+06

Graphical Representation of voltage level at each Stage



Graphical Comparison of voltages at each stage capacitor at No load and Loaded condition



Input Voltage Level:

Vin (V) -1	Vin (V) -2
45000.00	45000.00

Waveform of voltage and current across the load of $10M\Omega$



Figure39: Voltage across the load of $10M\Omega$ (1.0313MV)

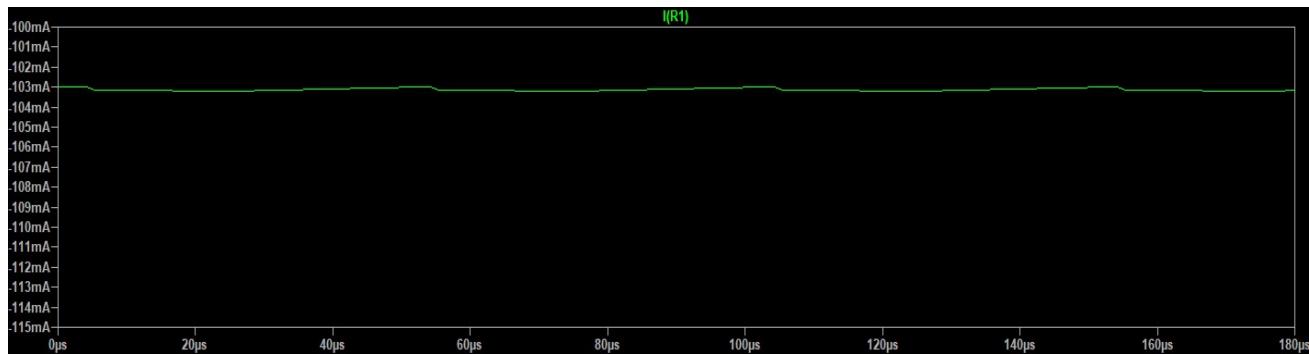


Figure-40: Current through the load of $10M\Omega$ (-103.13mA)

Waveform of Voltage across Capacitors at Different Stages

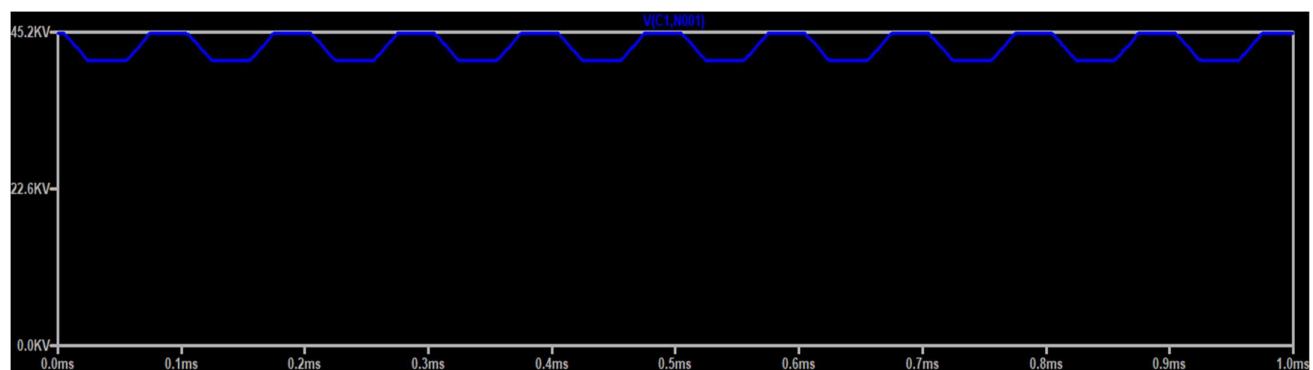


Figure- 41: Voltage across Stage-1 Capacitor of AC-Line-1

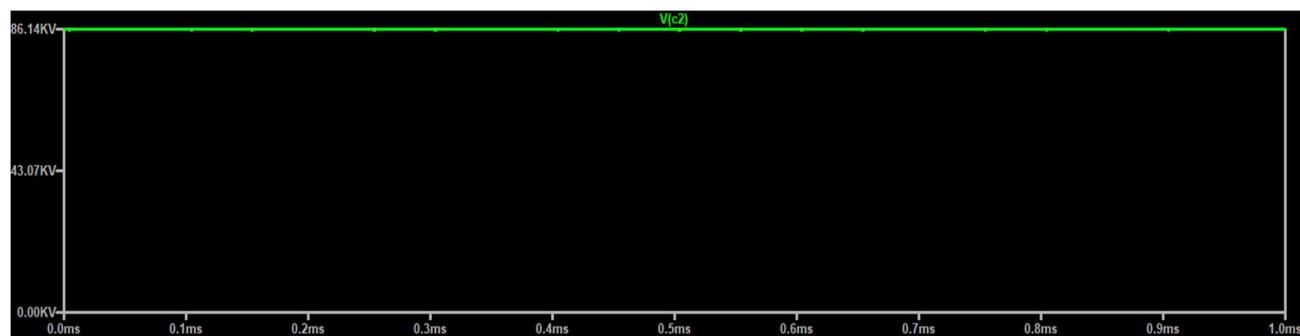


Figure-42: Voltage across Stage-1 Capacitor of DC-Line

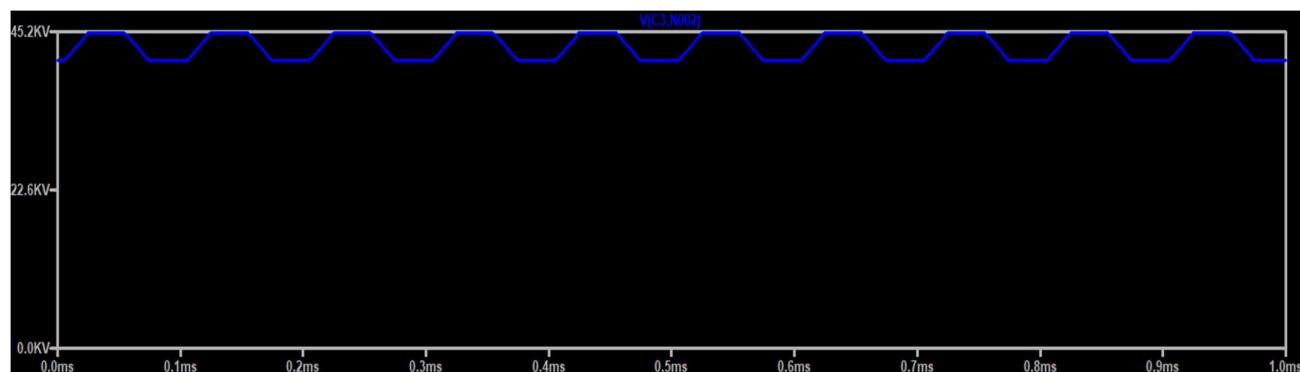


Figure-43: Voltage across Stage-1 Capacitor of AC-LINE-2

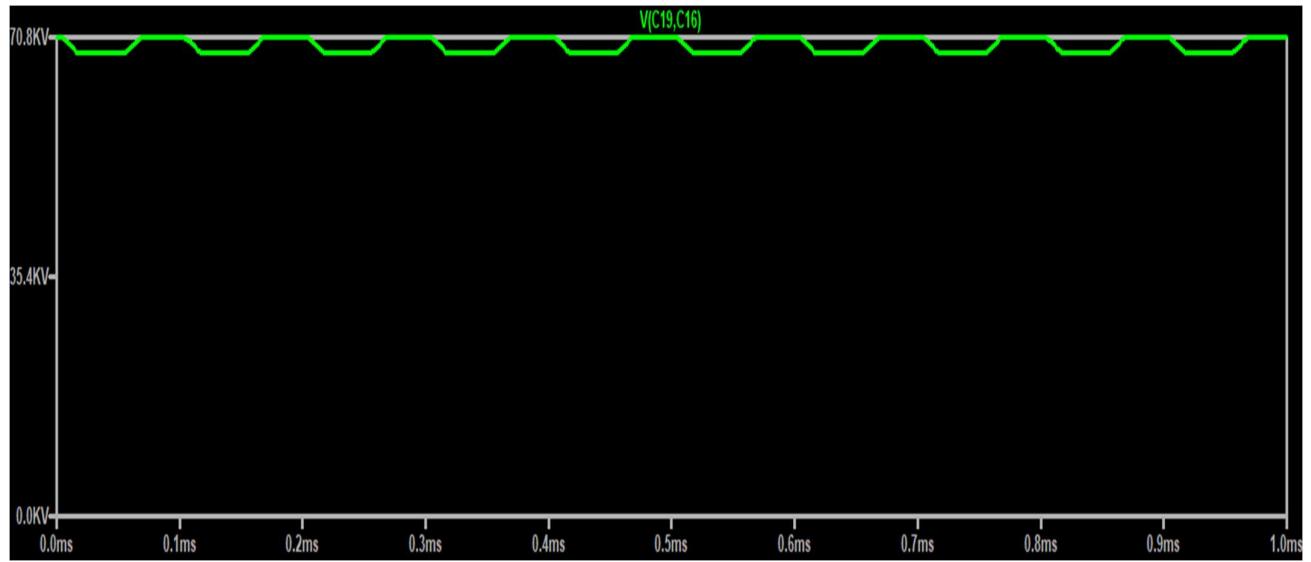


Figure-44: Voltage across Stage-7 Capacitor of AC-LINE-1

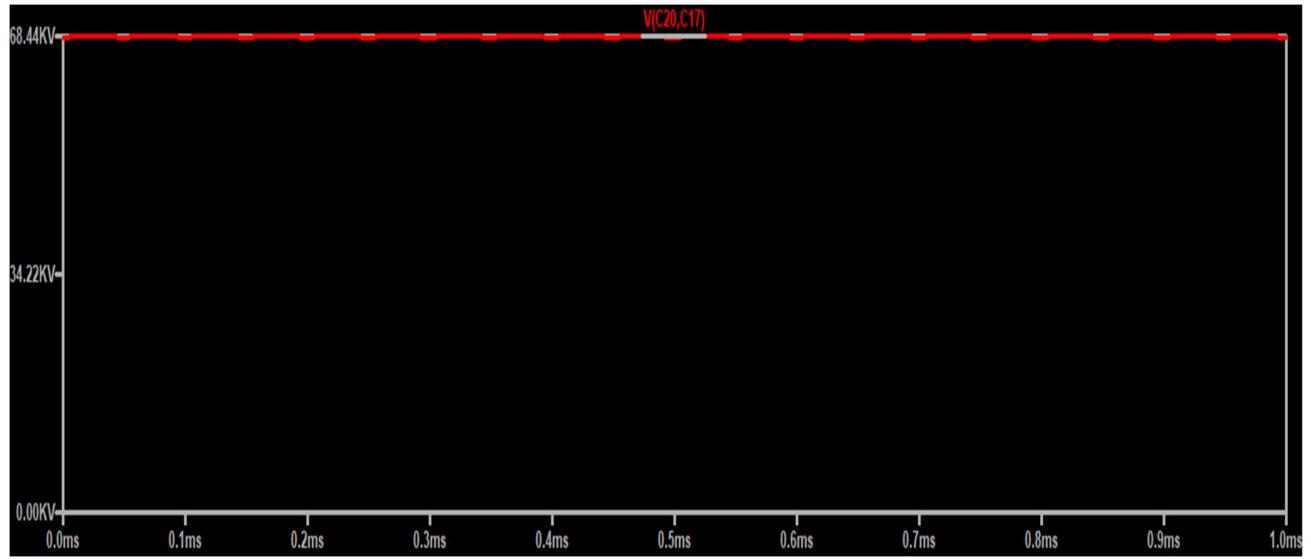


Figure-45: Voltage across Stage-7 Capacitor of DC-Line

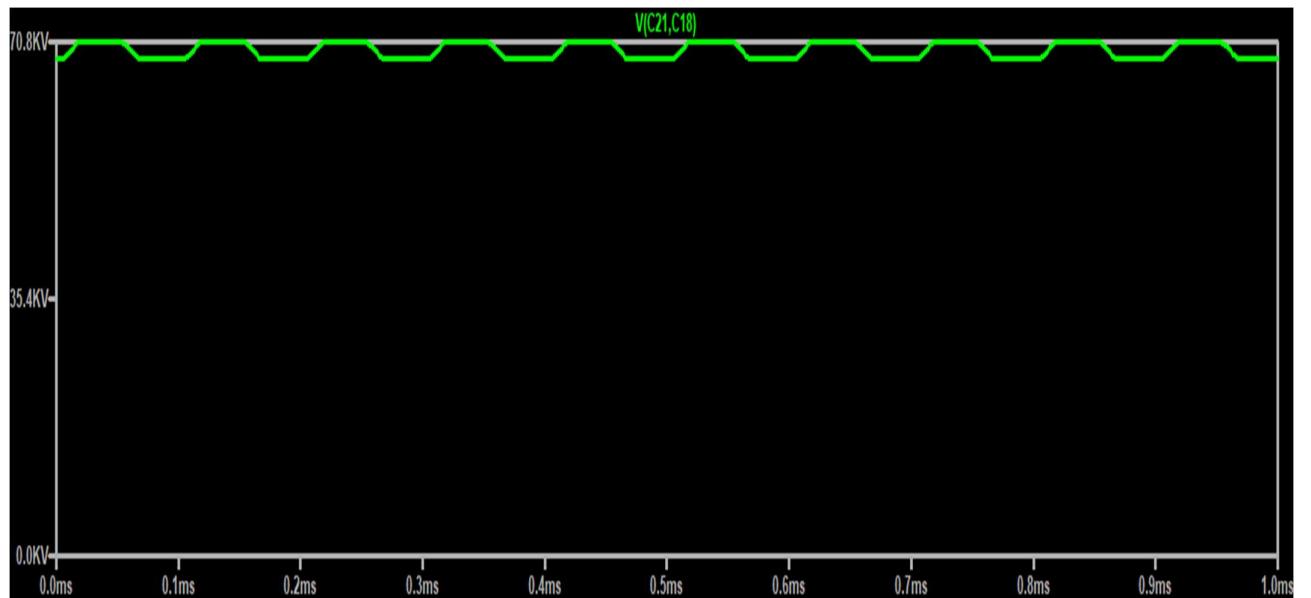


Figure-46: Voltage across Stage-7 Capacitor of AC-LINE-2

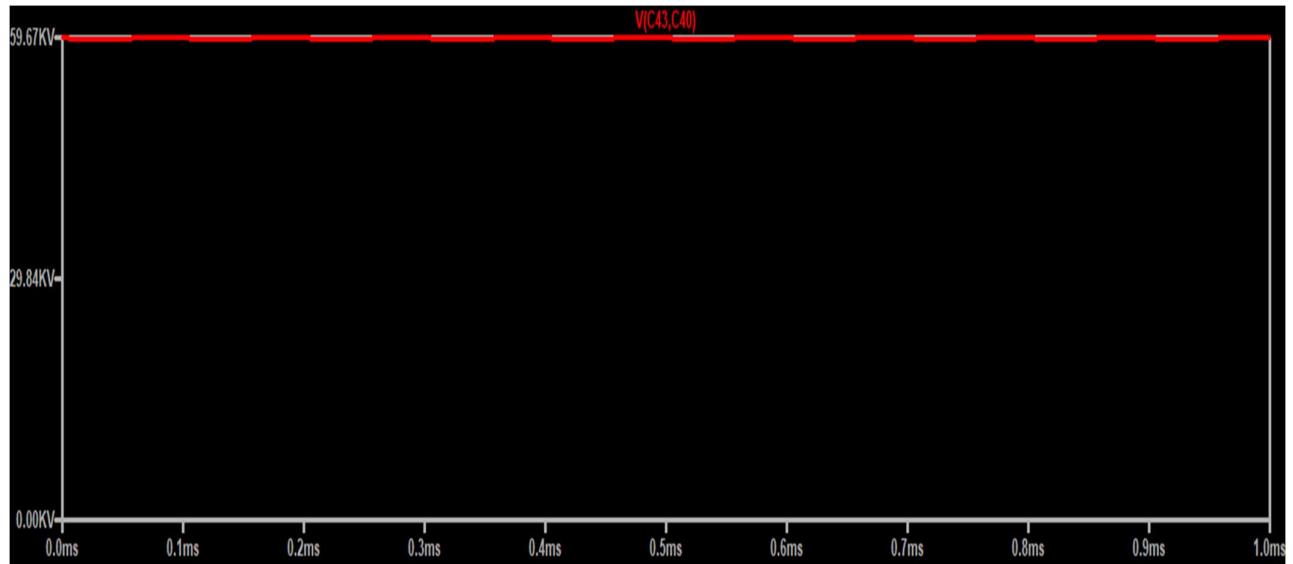


Figure-47: Voltage across Stage-15 Capacitor of AC-LINE-1

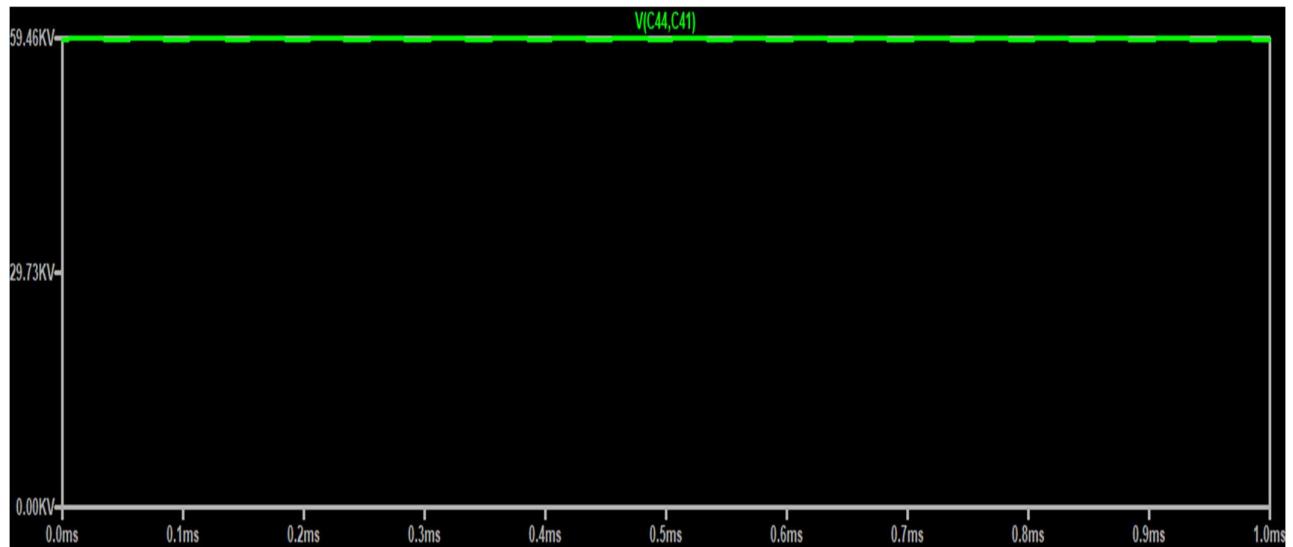


Figure-48: Voltage across Stage-15 Capacitor of DC-Line

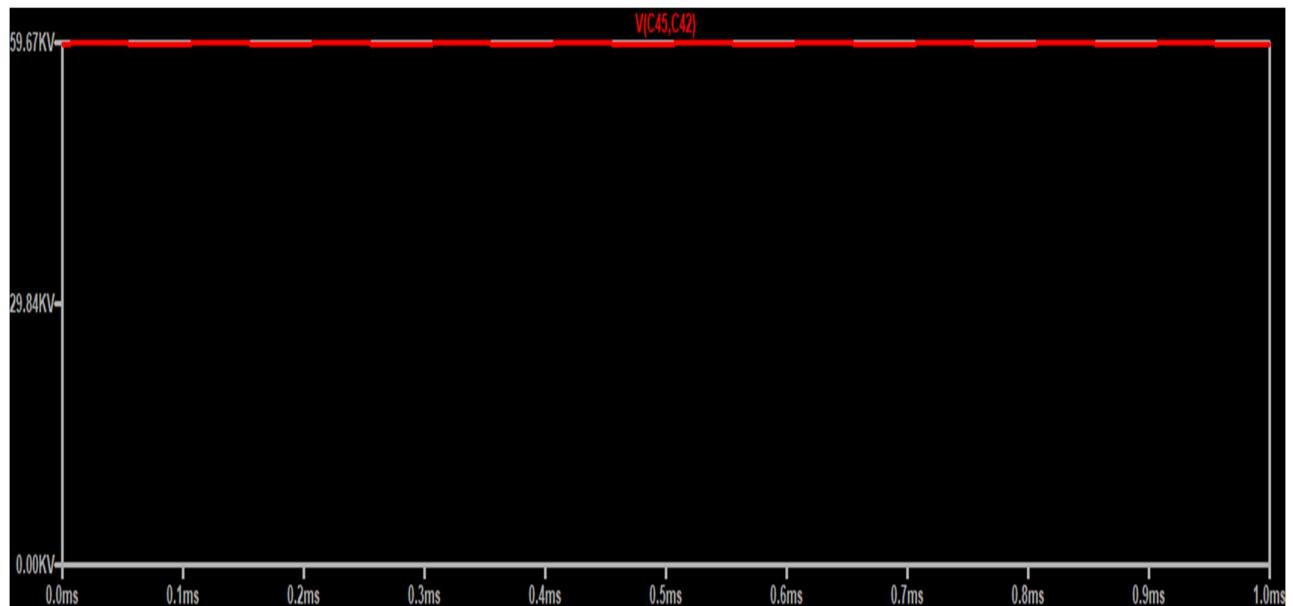
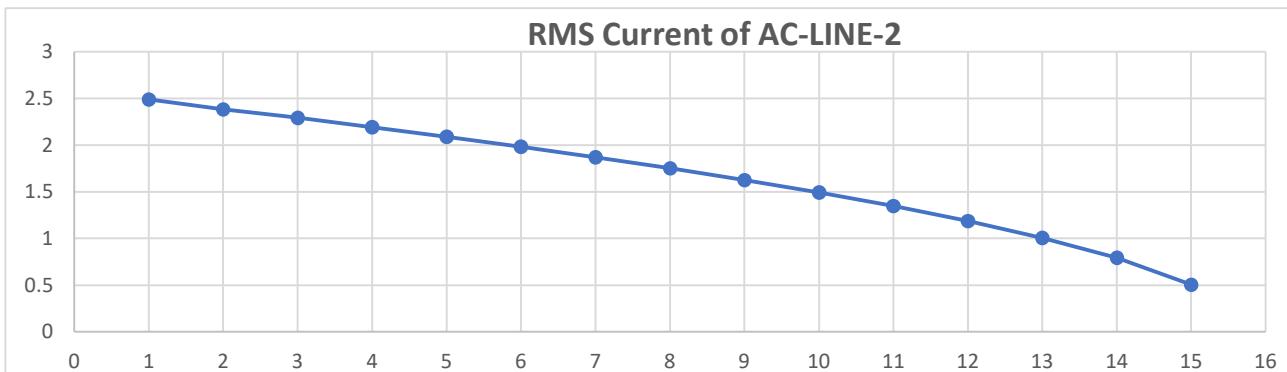
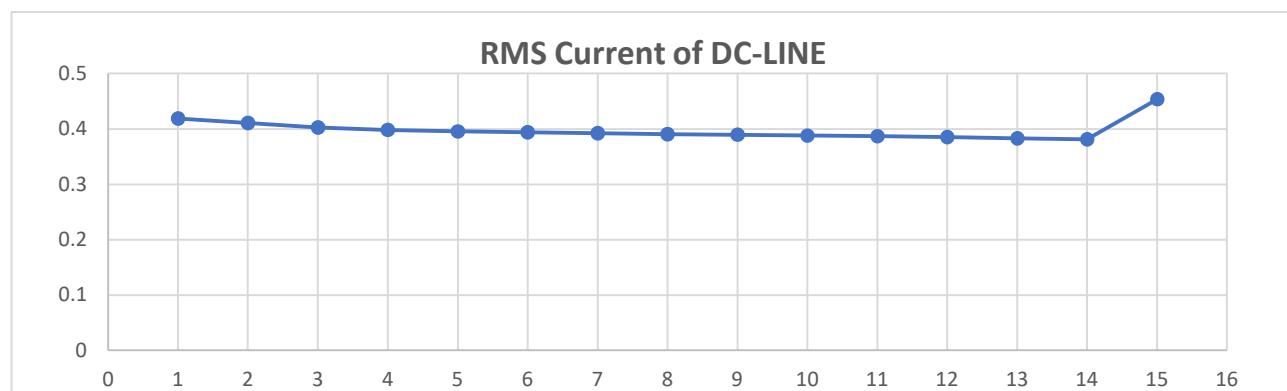
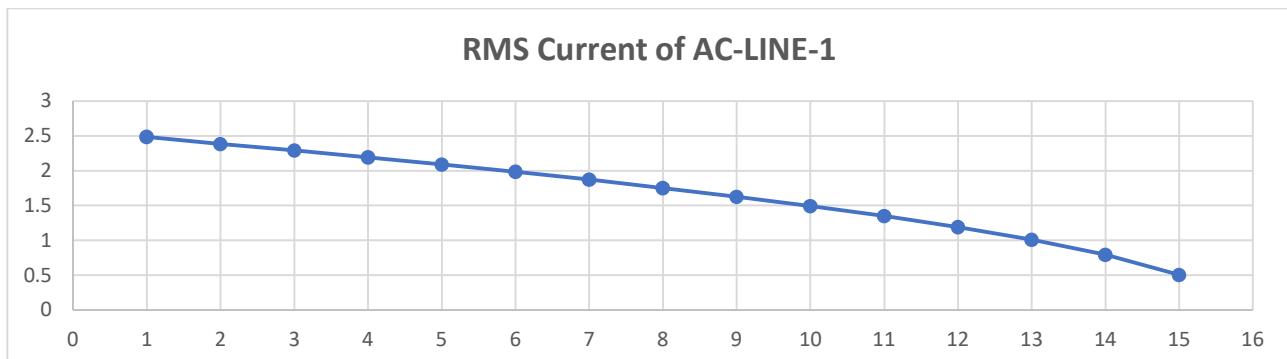


Figure-49: Voltage across Stage-15 Capacitor of AC-LINE-2

Current at Loaded Condition:

STAGE	AC-LINE-1		DC-LINE		AC-Line-2	
	MAX(A)	RMS(A)	MAX(A)	RMS(A)	MAX(A)	RMS(A)
1	8.01483	2.48879	2.68187	0.418967	8.13692	2.48882
2	5.60418	2.38394	2.96291	0.410671	5.65007	2.38398
3	5.05425	2.29201	2.90442	0.402595	5.06416	2.292
4	4.92799	2.19366	2.94189	0.398353	4.78046	2.19367
5	4.92799	2.09104	2.92624	0.395684	4.6485	2.091
6	4.92799	1.98375	2.85928	0.393912	4.56003	1.98377
7	4.92799	1.8713	2.71713	0.392156	4.39388	1.87125
8	4.92799	1.7528	2.61609	0.390744	4.27173	1.75286
9	4.92799	1.62742	2.78619	0.389389	4.21823	1.62731
10	4.92799	1.49336	2.63209	0.38806	4.07482	1.49327
11	4.92799	1.34833	2.65079	0.386591	4.02237	1.34844
12	4.92799	1.18903	2.61609	0.38491	3.87235	1.18904
13	4.92799	1.00875	2.61609	0.383137	3.80198	1.00888
14	4.92799	0.794229	2.61609	0.381217	3.6944	0.794221
15	4.92799	0.504244	3.99759	0.4536	3.6944	0.504278

Graphical Representation of Current level at each Stage



Input Voltage Level:

Iin(1) (RMS)	Iin(2) (RMS)
2.4888A	2.4888A

Waveform of Current through Capacitors at Different Stages

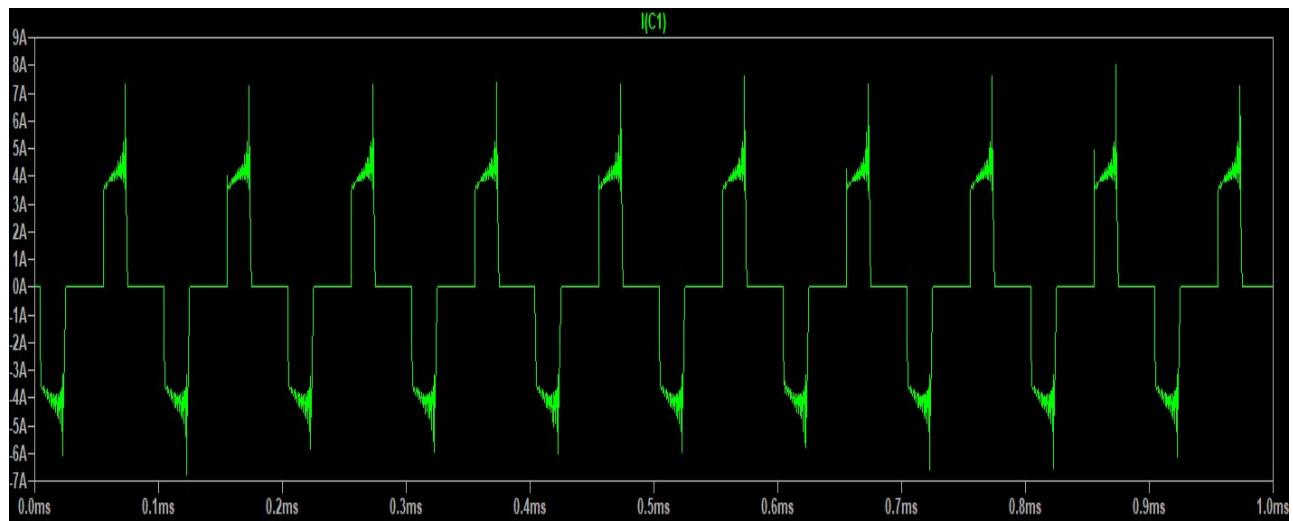


Figure-50: Current through Stage-1 Capacitor of AC-LINE-1

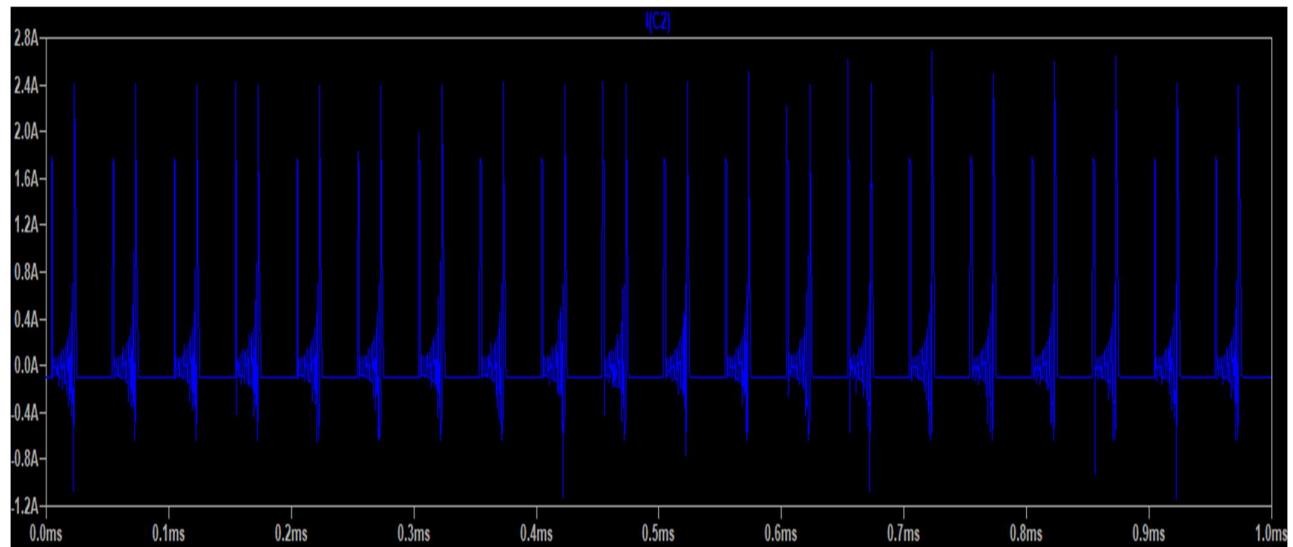


Figure-51: Current through Stage-1 Capacitor of DC-LINE

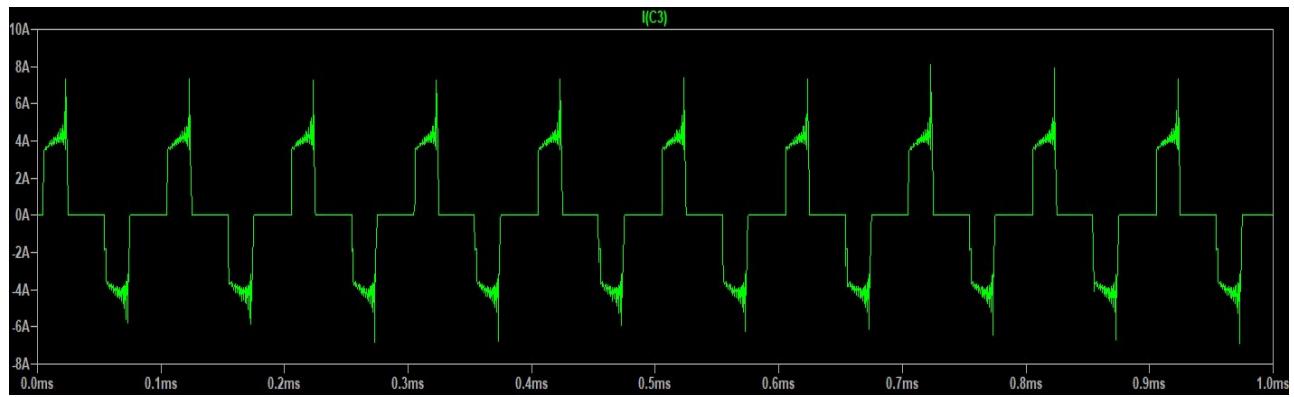


Figure-52: Current through Stage-1 Capacitor of AC-LINE-2

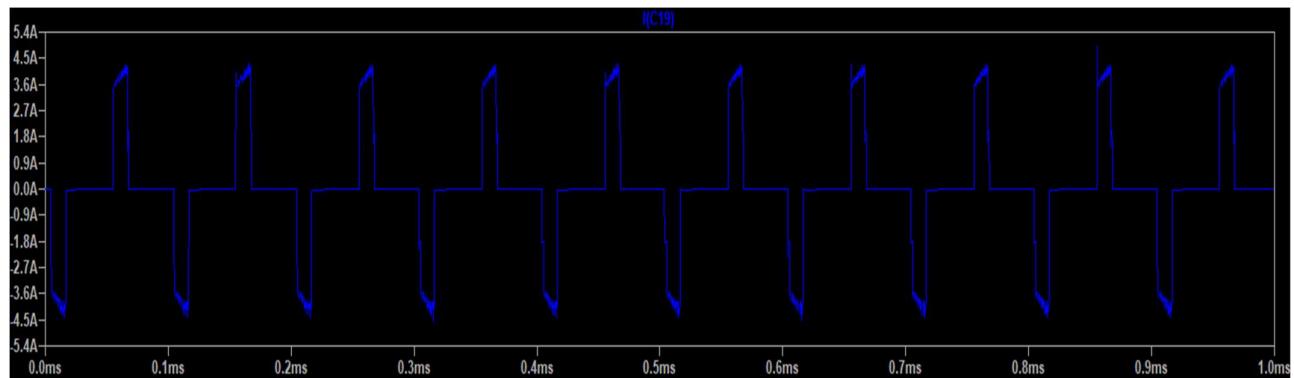


Figure-53: Current through Stage-7 Capacitor of AC-LINE-1

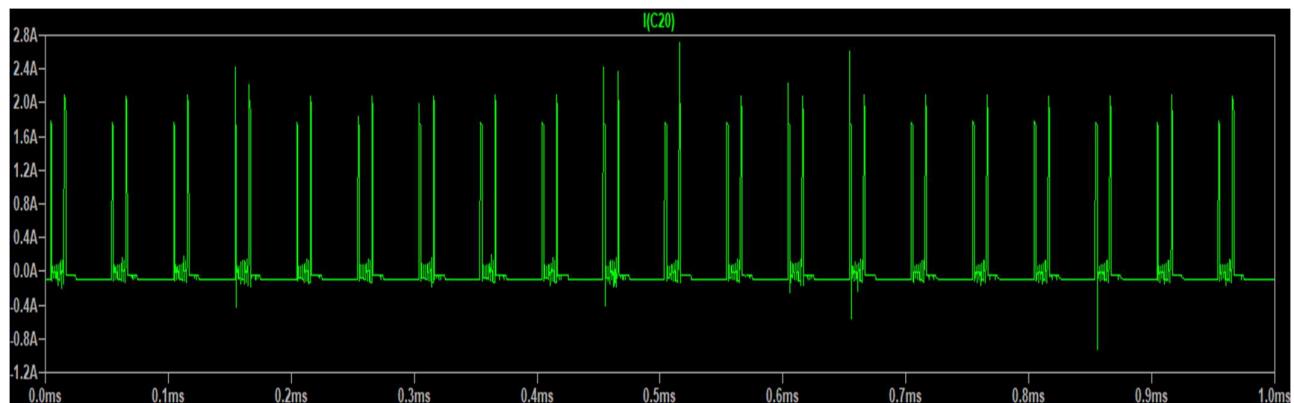


Figure-54: Current through Stage-7 Capacitor of DC-LINE

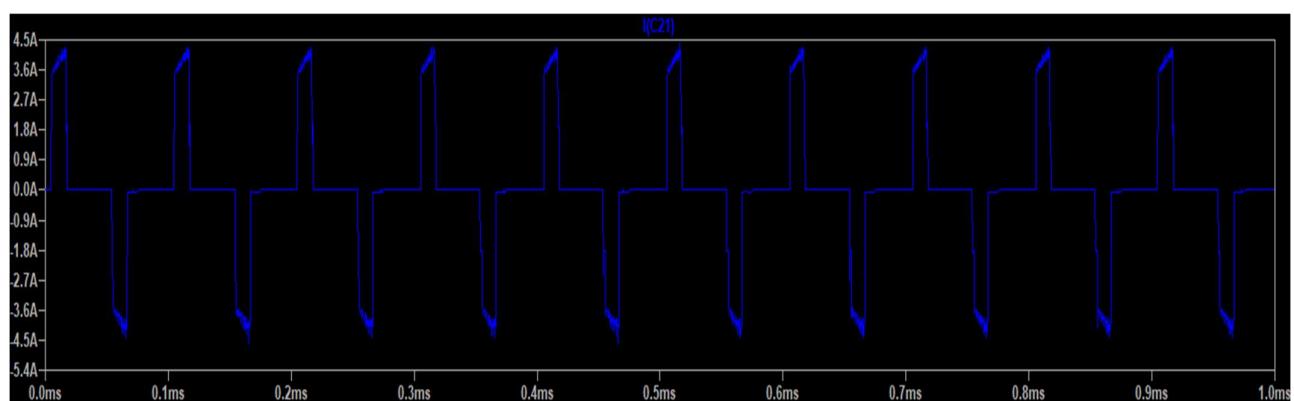


Figure-55: Current through Stage-7 Capacitor of AC-LINE-2

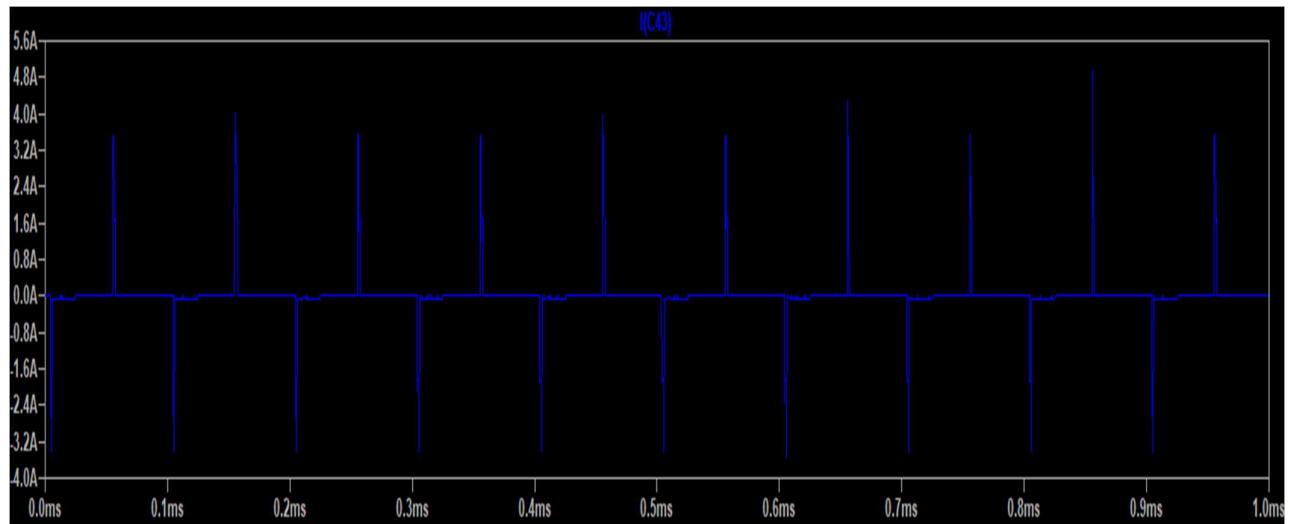


Figure-56: Current through Stage-15 Capacitor of AC-LINE-1

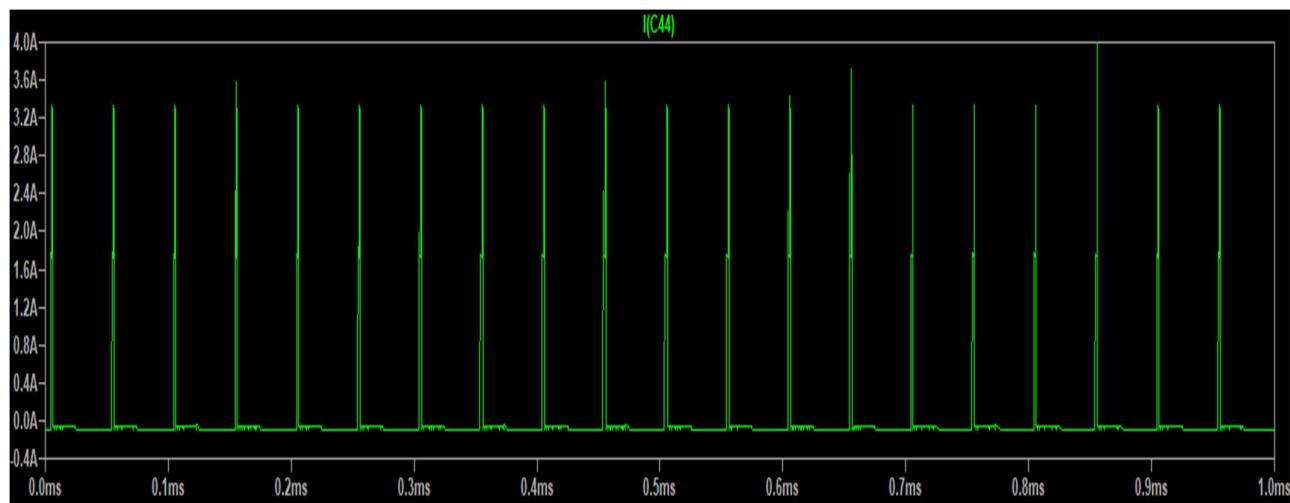


Figure-57: Current through Stage-15 Capacitor of DC-LINE

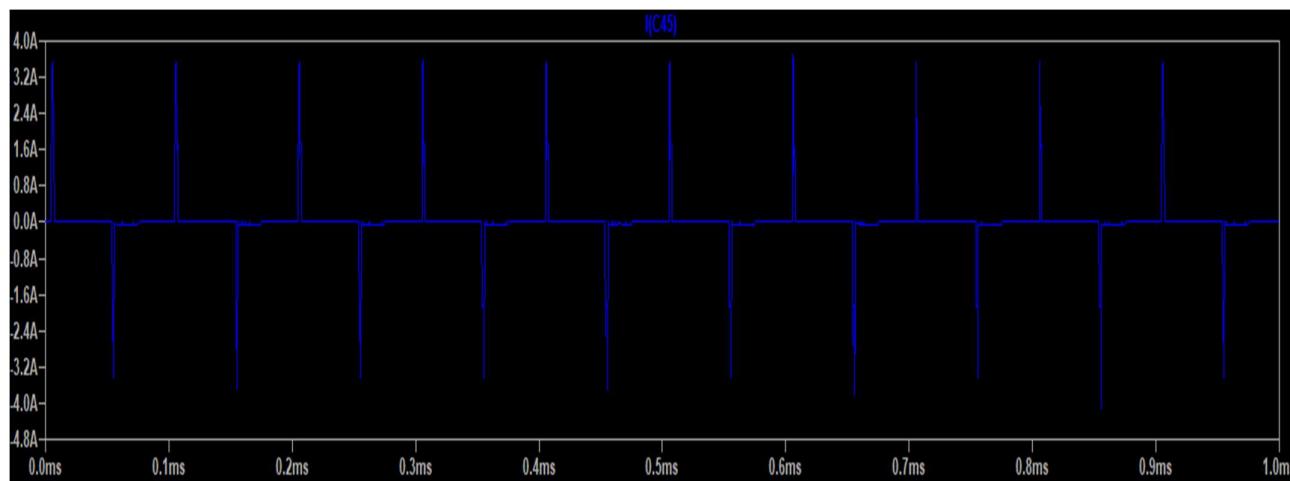


Figure-58: Current through Stage-15 Capacitor of AC-LINE-2

Diode Voltage and Current :

Stage	Diode no.	Current		Voltage(Max)(V)(N-P)
		Max(A)	RMS(A)	
1	1	6.60633	0.412409	86132.8
	2	6.71585	0.412334	86132.9
	3	6.11594	0.411358	86132.8
	4	6.32217	0.411283	86132.8
2	5	5.54549	0.461769	82530.2
	6	5.50354	0.46182	82530.1
	7	4.58003	0.328082	82529.9
	8	4.54312	0.328321	82529.9
3	9	5.1542	0.464303	79188.3
	10	5.18829	0.464334	79188.3
	11	4.42213	0.358727	79188.1
	12	4.45655	0.358583	79188.1
4	13	4.97443	0.463673	76107.3
	14	4.85893	0.463806	76107.3
	15	4.39195	0.364323	76107.1
	16	4.3776	0.364432	76107.2
5	17	4.80374	0.462671	73287.5
	18	4.63712	0.462489	73287.7
	19	4.29568	0.36605	73287.3
	20	4.32871	0.365792	73287.2
6	21	4.52862	0.460584	70728.6
	22	4.54799	0.460748	70728.6
	23	4.23955	0.36626	70728.3
	24	4.25908	0.366345	70728.3
7	25	4.51689	0.458584	68430.4
	26	4.54897	0.458421	68430.5
	27	4.80374	0.462671	68430.4
	28	4.1878	0.365006	68430.3
8	29	4.34879	0.455275	66393.6
	30	4.3589	0.455657	66393.6
	31	4.13114	0.363599	66393.4
	32	4.13119	0.363879	66393.4
9	33	4.32479	0.452618	64617.8
	34	4.33292	0.452533	64618
	35	4.06817	0.361425	79188.1
	36	4.07043	0.361093	79188.1
10	37	4.06558	0.448781	63103.4
	38	4.18242	0.448567	63103.3
	39	4.00174	0.35893	63102.8
	40	4.00279	0.358492	63102.9
11	41	4.06287	0.444477	61849.9
	42	4.10722	0.444587	61849.6
	43	3.92802	0.355079	61849.6
	44	3.92441	0.355526	61849.6
12	45	3.86844	0.439846	60857.4
	46	3.99212	0.439741	60857.3
	47	3.84605	0.351601	60857.2
	48	3.8448	0.351586	60857.1
13	49	3.873693	0.434502	60126.4
	50	82872	0.434668	60126.2
	51	3.75637	0.347078	60126.1
	52	3.75341	0.347409	60126.1
14	53	3.79342	0.428748	59656.4
	54	3.74103	0.4287	59656.4
	55	3.65604	0.342542	59655.6
	56	3.657	0.342597	59656.3
15	57	3.54351	0.328793	59448.4
	58	4.10073	0.32906	59448.3
	59	4.92799	0.382305	59447.8
	60	3.6944	0.38212	59447.8

Waveform of Diode Voltages and Current at each stage

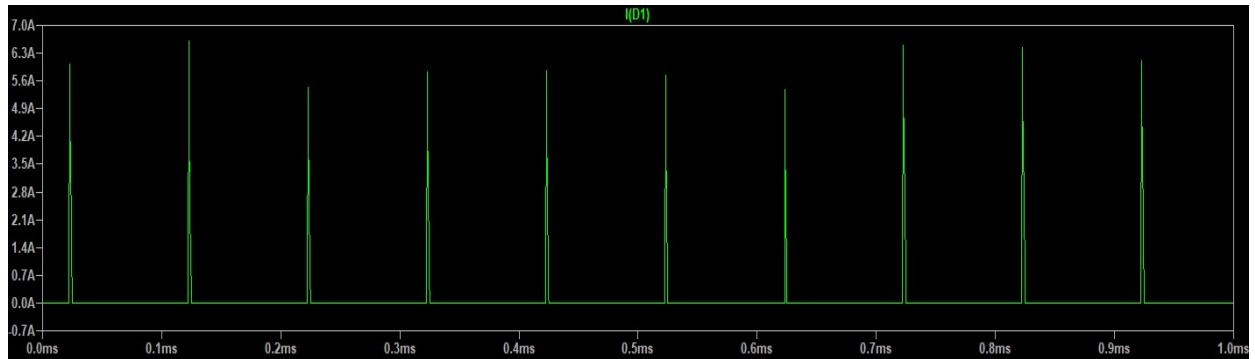


Figure-59: Current through D_1 (Stage-1)

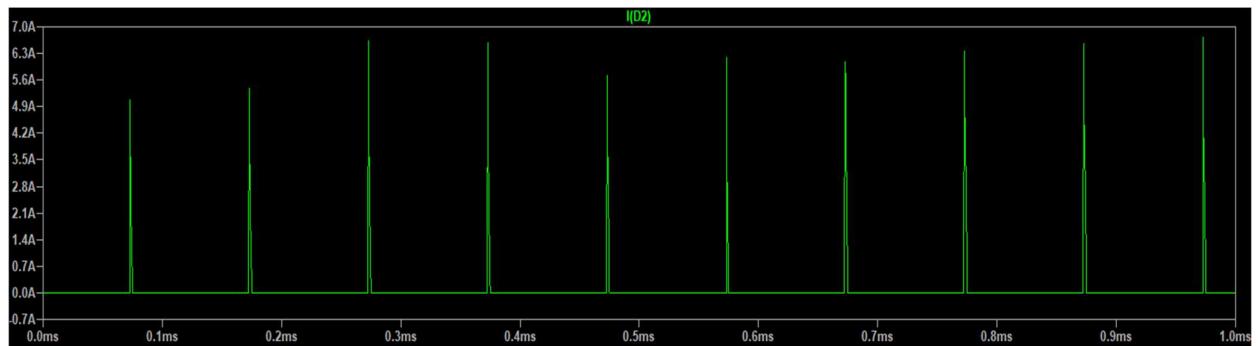


Figure-60: Current through D_2 (Stage-1)

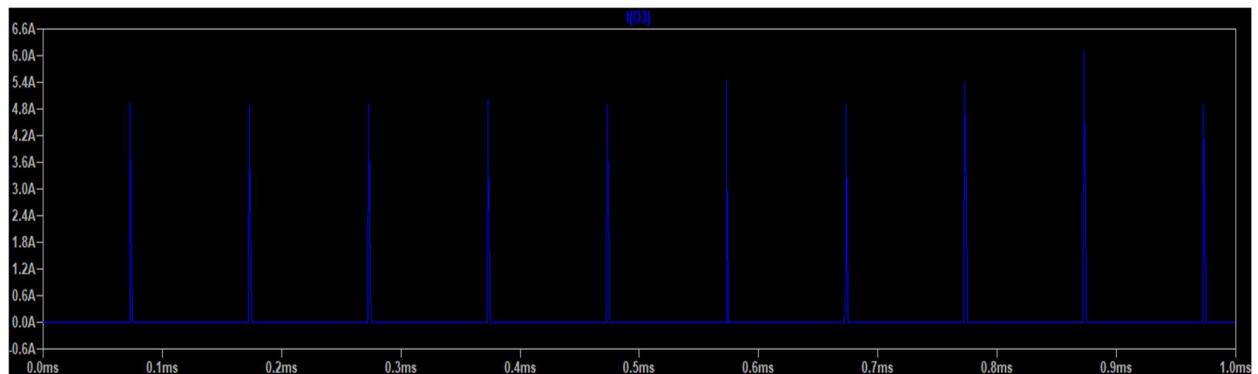


Figure-61: Current through D_3 (Stage-1)

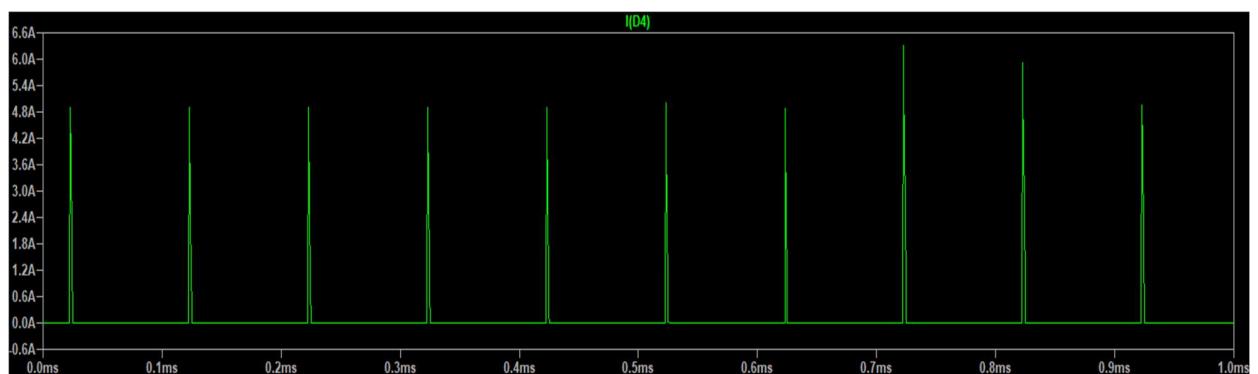


Figure-62: Current through D_4 (Stage-1)

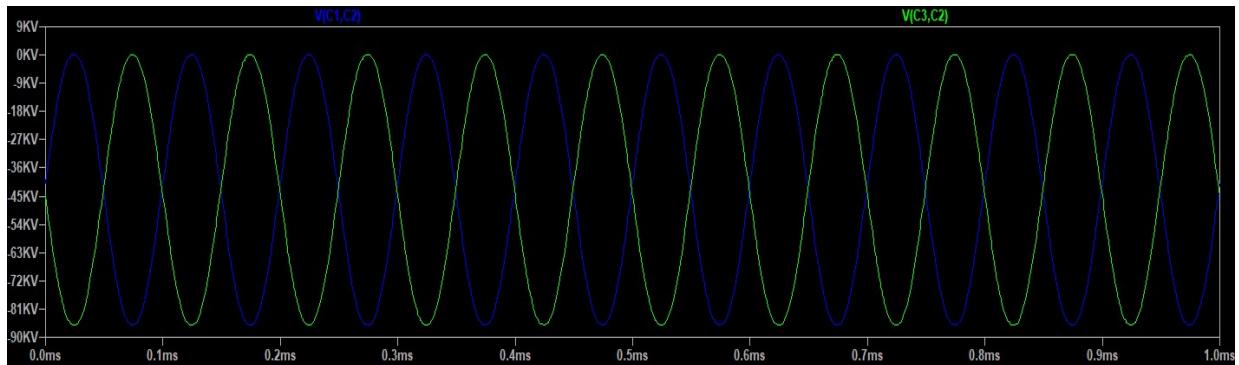


Figure-63: Voltage across D_1 and D_2 (Stage-1)

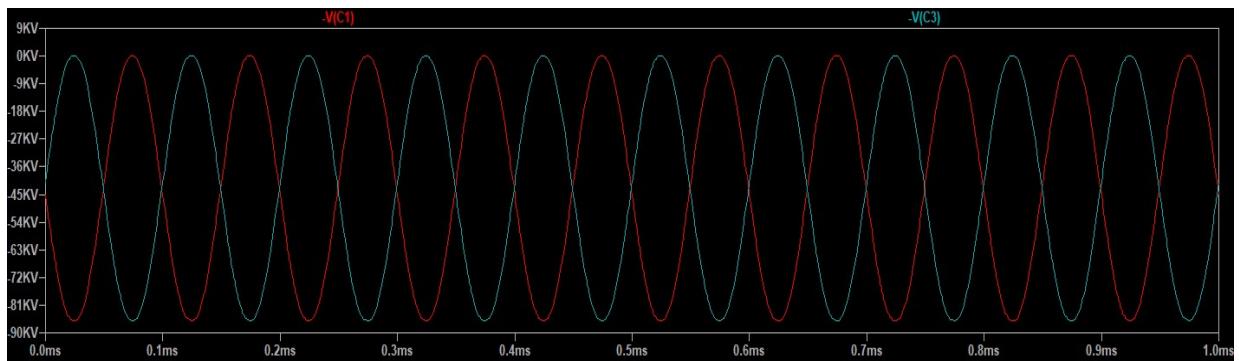


Figure-64: Voltage across D_3 and D_4 (Stage-1)

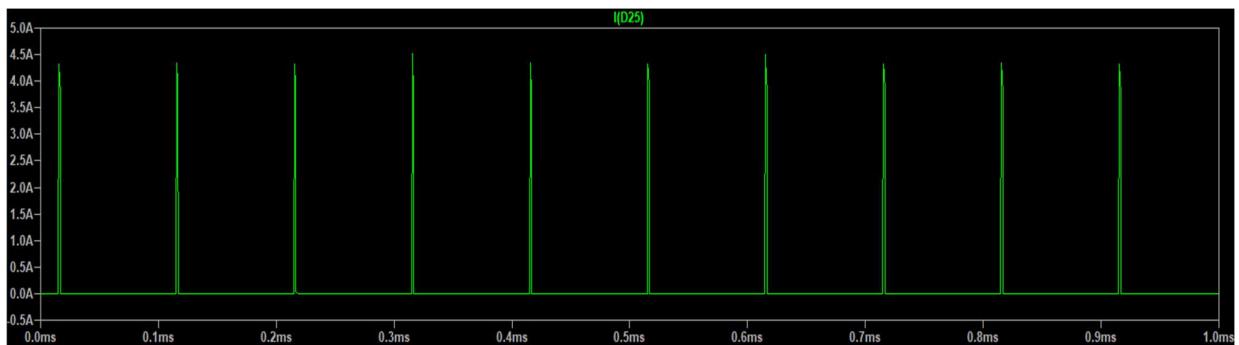


Figure-65: Current through D_{25} (Stage-7)

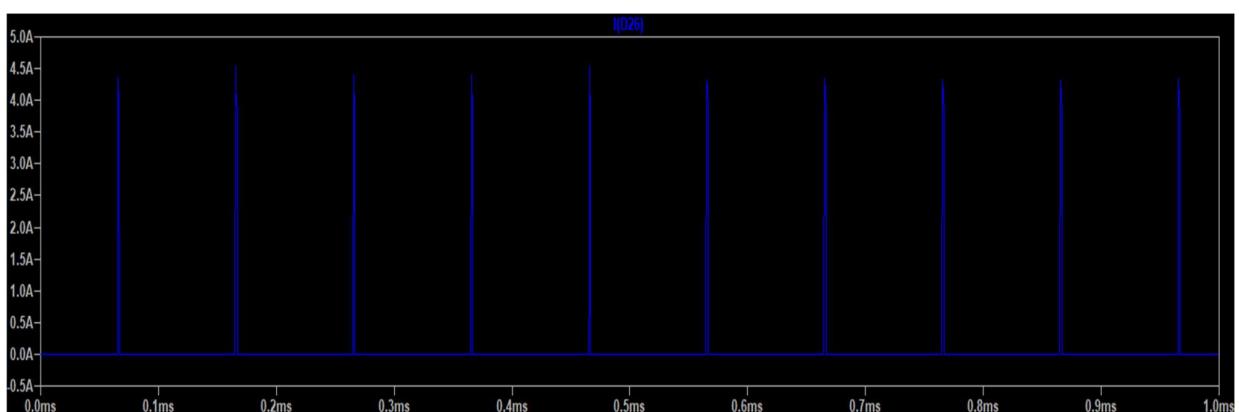


Figure-66: Current through D_{26} (Stage-7)

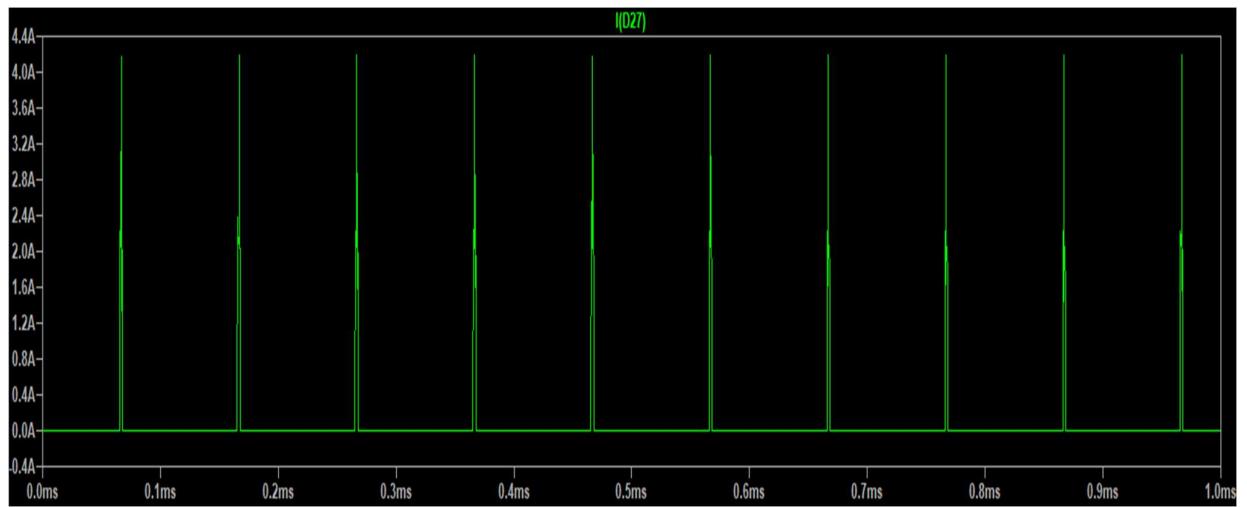


Figure-67: Current through D_{27} (Stage-7)

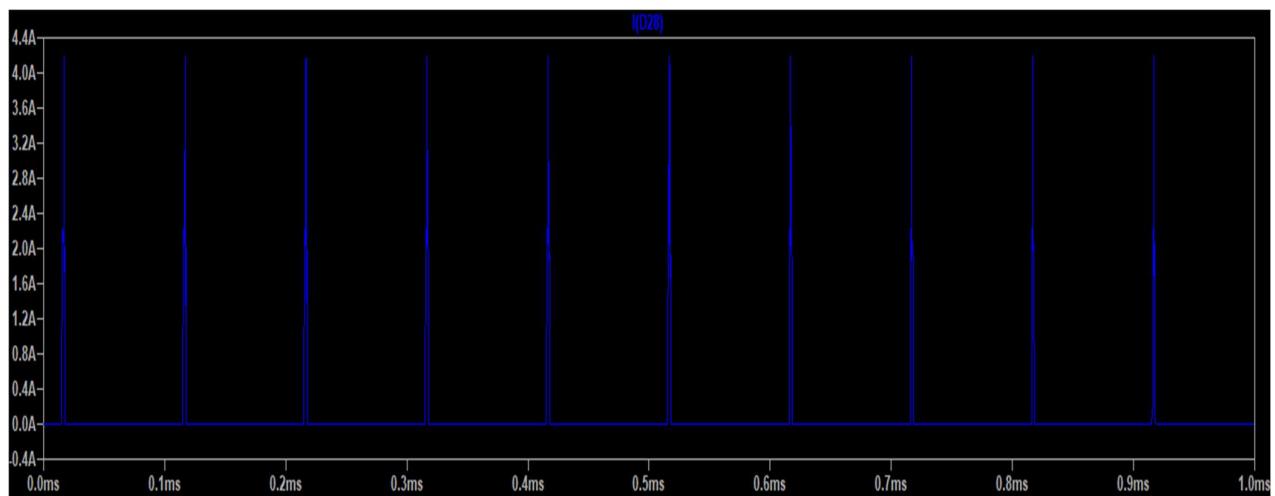


Figure-68: Current through D_{28} (Stage-7)

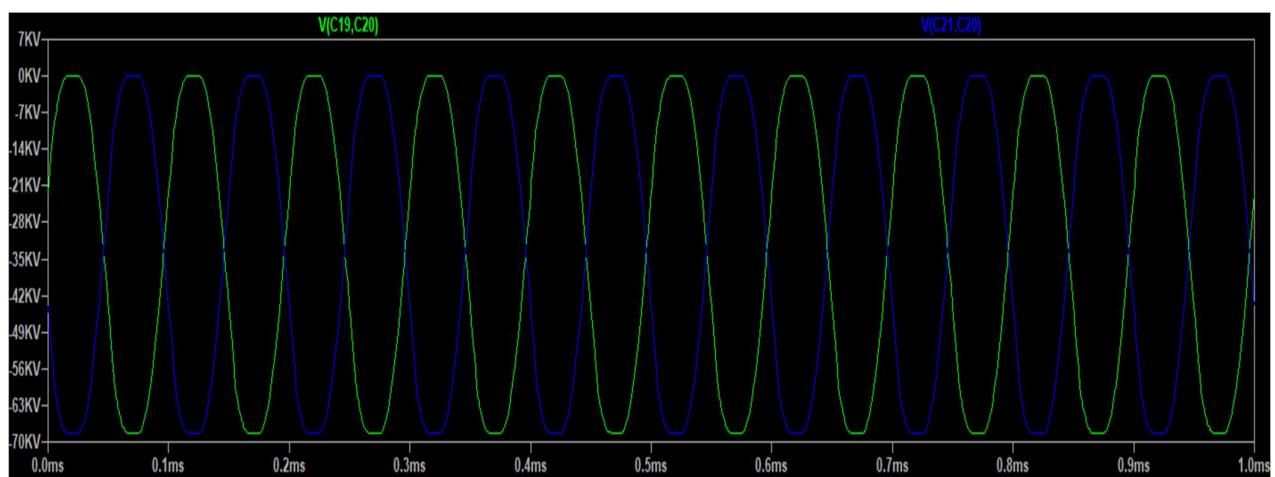


Figure-69: Voltage across D_{25} and D_{26} (Stage-7)

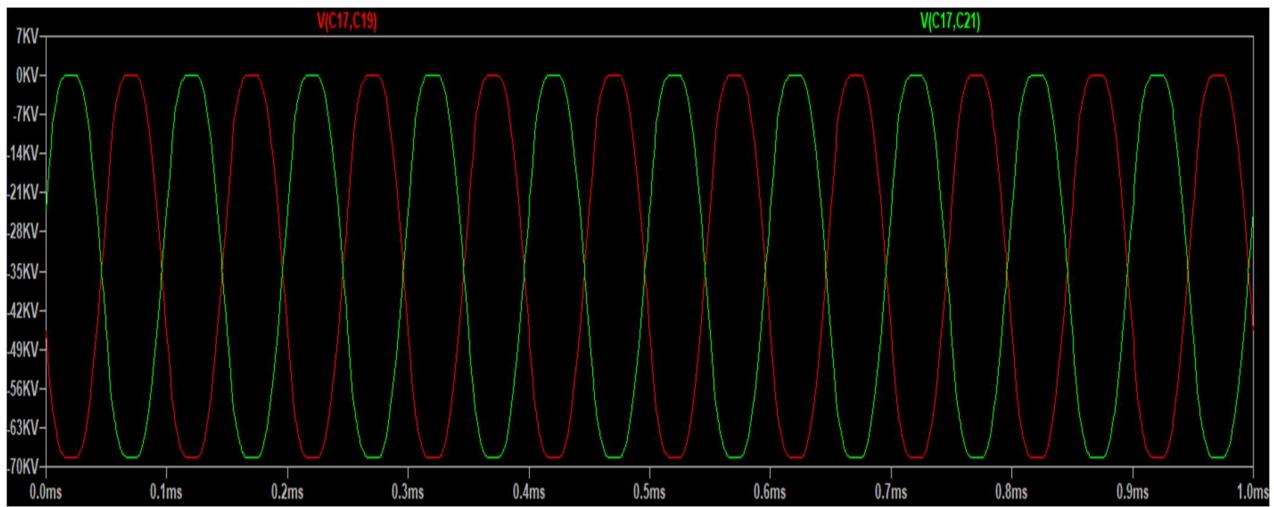


Figure-70: Voltage across D_{27} and D_{28} (Stage-7)

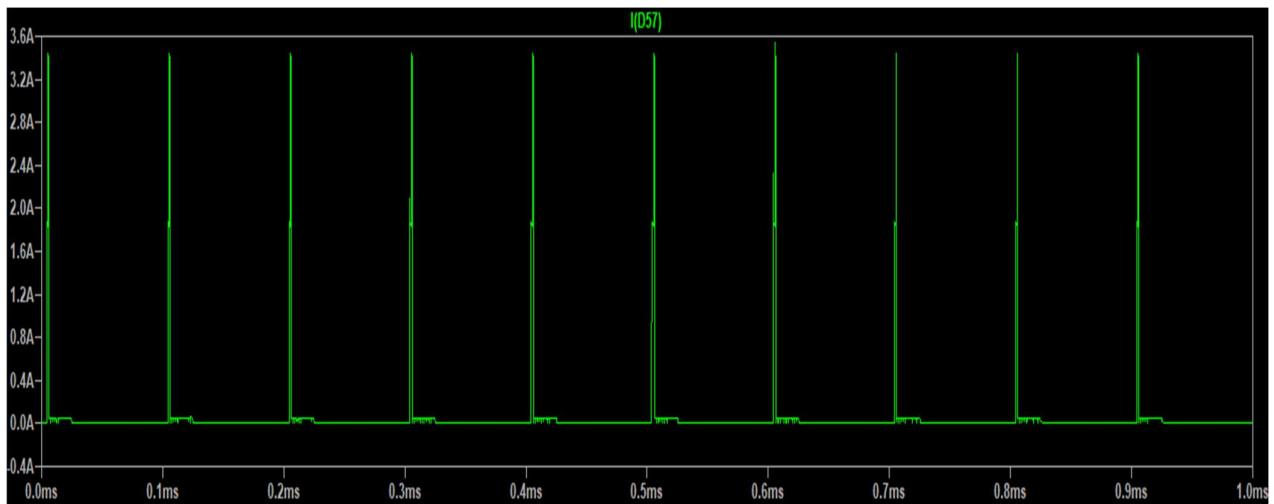


Figure-71: Current through D_{57} (Stage-15)

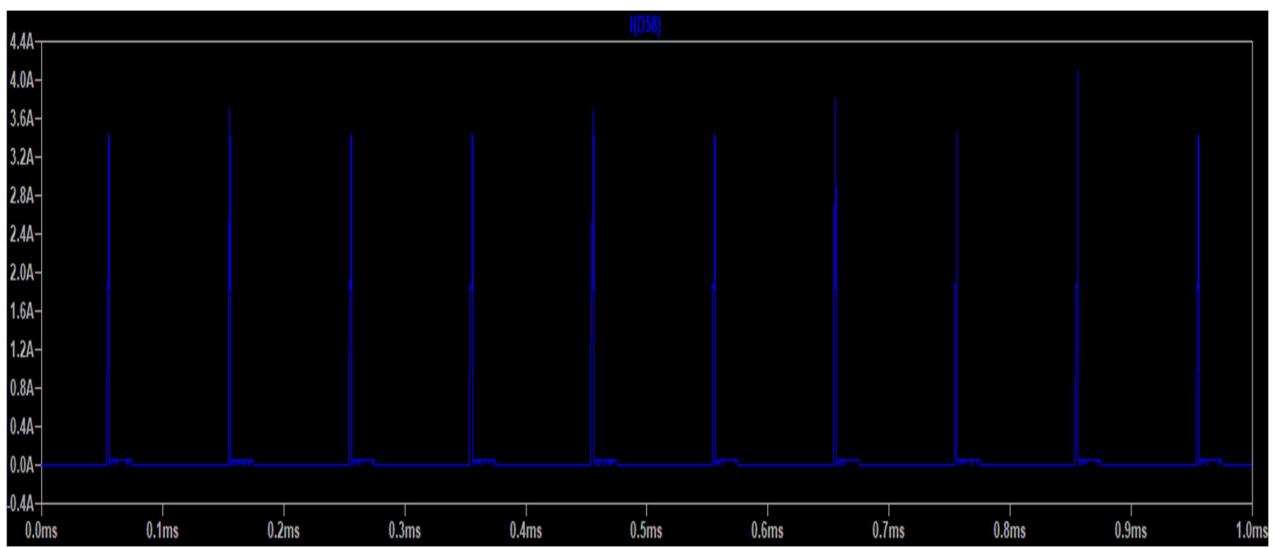


Figure-72: Current through D_{58} (Stage-15)

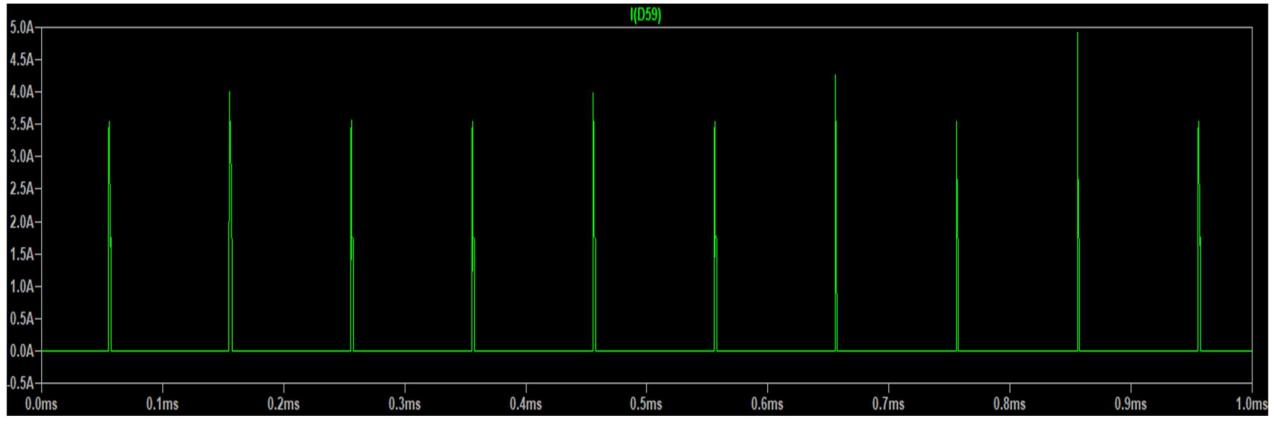


Figure-71: Current through D_{59} (Stage-15)

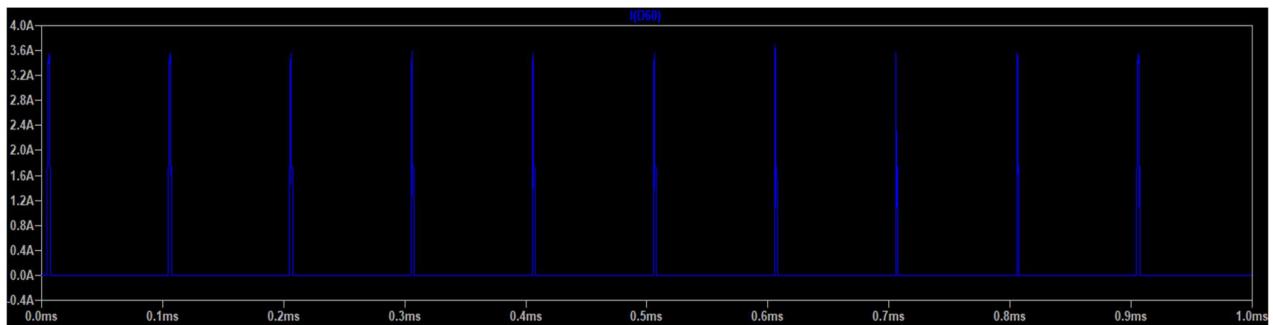


Figure-72: Current through D_{60} (Stage-15)

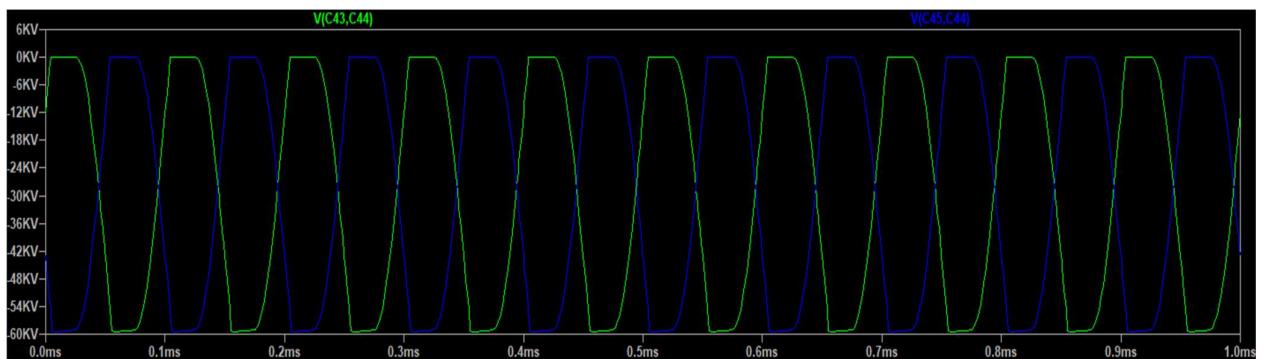


Figure-73: Voltage across D_{57} and D_{58} (Stage-15)

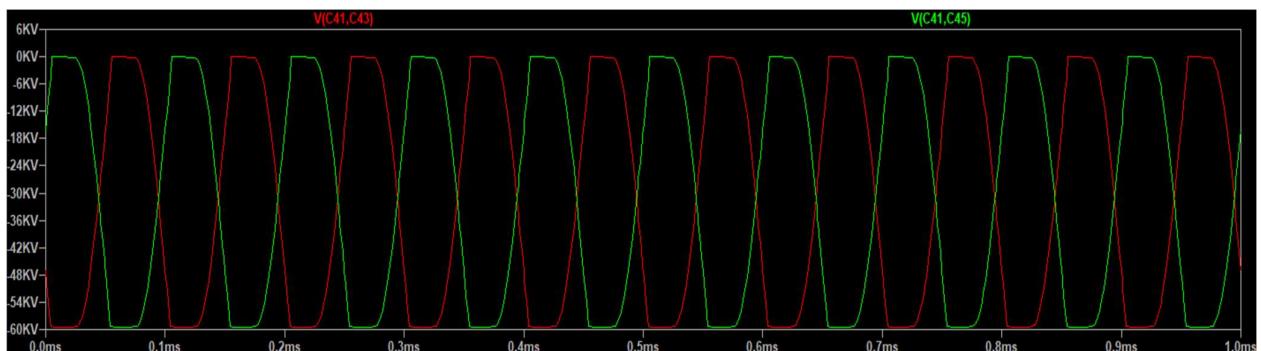


Figure-74: Voltage across D_{59} and D_{60} (Stage-15)

Power Dissipation calculation in stage capacitance:

$$P = I_{rms}^2 \times R_c$$

Consider, Dissipattion factor($\tan\delta$) = 0.02

$$\tan\delta = \frac{R_c}{X_c}$$

$$f = 10KHz$$

$$C = 20nF$$

$$R_c = 0.02 \times X_c$$

$$R_c = \frac{0.02}{2\pi f c} = \frac{0.02}{2 * \pi * 10^4 * 20 * 10^{-9}} = 15.915\Omega$$

Total Power Dissipation = 1528.733692 watts

Rc	Stage	AC-line-1		DC-line		AC-line-2	
		Irms	Power Dissipation	Irms	Power Dissipation	Irms	Power Dissipation
15.915	1	2.48879	98.57871419	0.418967	2.793613219	2.48882	98.58109075
15.915	2	2.38394	90.44764933	0.410671	2.684075417	2.38398	90.45068459
15.915	3	2.29201	83.60642611	0.402595	2.579546712	2.292	83.60569656
15.915	4	2.19366	76.58527487	0.398353	2.525473567	2.19367	76.58597312
15.915	5	2.09104	69.5875144	0.395684	2.49174515	2.091	69.58485212
15.915	6	1.98375	62.62972755	0.393912	2.469477453	1.98377	62.63099042
15.915	7	1.8713	55.73056913	0.392156	2.447509415	1.87125	55.72759099
15.915	8	1.7528	48.89577927	0.390744	2.429916102	1.75286	48.89912683
15.915	9	1.62742	42.15081155	0.389389	2.413092671	1.62731	42.14511366
15.915	10	1.49336	35.49242489	0.38806	2.39664882	1.49327	35.48814699
15.915	11	1.34833	28.93337115	0.386591	2.378538149	1.34844	28.93809225
15.915	12	1.18903	22.50050511	0.38491	2.357898094	1.18904	22.50088358
15.915	13	1.00875	16.19473099	0.383137	2.336225886	1.00888	16.19890537
15.915	14	0.794229	10.0391773	0.381217	2.312869673	0.794221	10.03897505
15.915	15	0.504244	4.046579914	0.4536	3.274558358	0.504278	4.047125635
		745.4192558			37.89118869		745.4232479

Simulation Conclusion:

Here, I have simulated a 15-stage symmetrical Cockcroft-Walton circuit under no-load and loaded conditions. In this simulation, I considered ideal capacitors and diodes. The simulation ran for 200 ms , with data recording starting at 199ms and a time step of 10 ns.

Here are the key observations from the simulation:

1. Voltage Levels (At No load Condition):

- AC-Line-1 , DC-Line , AC-Line-2 voltage in the 1st stage: 45 kV(Approx) for 45kV-0-45kV. 10kHz input.
- From 2nd to the 15th stage, all capacitors have a voltage around 90 kV.
- However, the voltage with respect to ground on the DC line keeps increasing and reaches approximately 1350 kV which matches with the calculation.

2. Current Behaviour(At No load Condition):

- Since there is no load connected, the current through the capacitors remains very low.
- The ideal diodes have nearly zero forward voltage, and also a gradual decrease in RMS current through the diodes with each stage.

3. Loaded Condition:

- For the loaded condition, we consider 10 MΩ resistances to achieve a current of 100 mA.
- In the simulation, I observed a DC-line voltage of 1.03 MV with respect to ground, which closely matches with the calculated value of 1.038 MV.
- The RMS Current through the capacitor decreases with each stage. But at the DC- Line there is a Sudden Peak of RMS current at the 15th stage
- The diode current is approximately constant.

4. Voltage Drop and Power Dissipation:

- The regular decrease in the DC-line voltage is due to the ($I_{rms}X_c$) drop of the capacitors.
- The power dissipation of the capacitors is calculated using the formula ($I_{rms}^2 * R_c$)considering a dissipation factor of 0.02. This yields an effective resistance R_c of 15.915Ω .
- Overall, power dissipation decreases on both the AC-Lines over stages and the DC- line power dissipation remains nearly constant. Maximum power loss at first stage capacitor. Total power loss in stage capacitance is 1.5kW.

Simulation of Heat Run Testing circuit of Single Capacitor Module (20nF,10Khz)

Here we are simulating the heat run test circuit, which we perform under resonance conditions. Initially, for simplicity we replace the step-down transformer with an independent source of 100V at 10 kHz in the simulation . We use a 12.66 mH inductor to ensure that the circuit operates at resonance. Next, we simulate the original circuit by using a transformer with a turn ratio of 22 and replaced the inverter with an independent source of 10 kV at 10 kHz.

However, we observe that the input voltage and current are not perfectly in phase. In resonance conditions, they should ideally be in phase. To achieve this, we need to adjust the value of the inductor. The optimal value for the inductor is approximately 12.489 mH.

Calculations:

We know at resonances,

$$\omega^2 = \frac{1}{LC}$$

$$L = \frac{1}{\omega^2 C}$$

$$L = \frac{1}{20 * 10^{-9} (2 * \pi * 10^4)^2} = 12.66mH$$

$$\mathbf{L = 12.66 \text{ mH}}$$

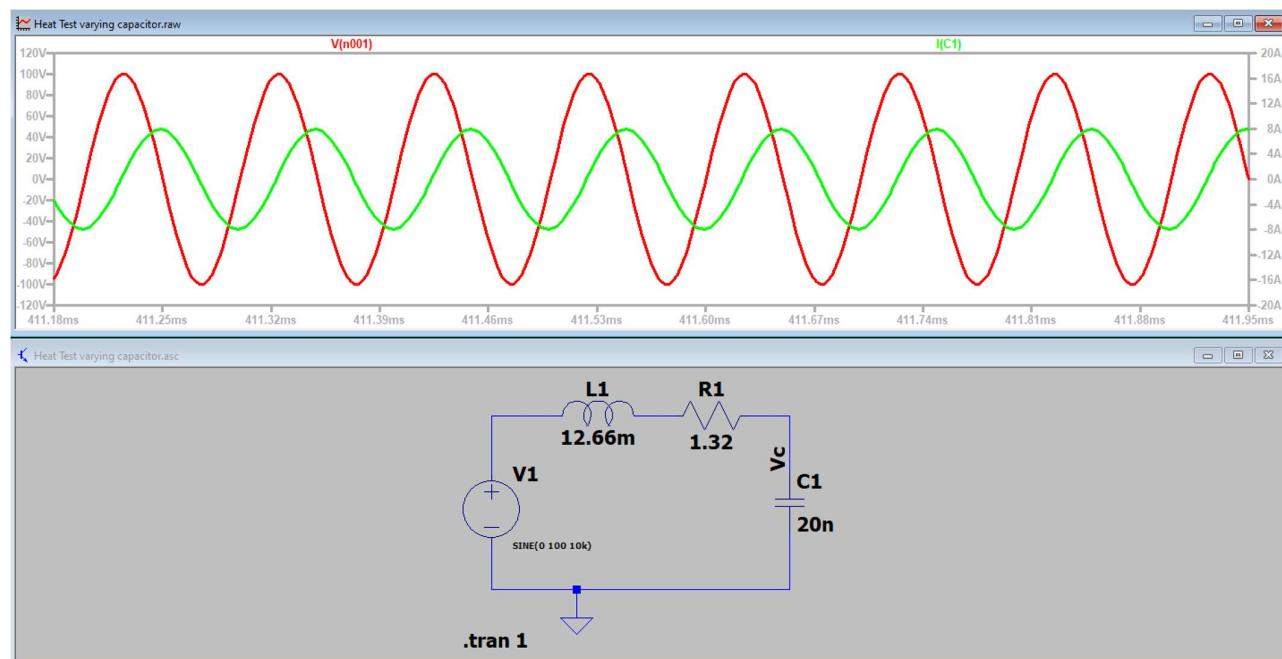


Figure-75: Heat run test circuit using calculated inductance(12.66mH)

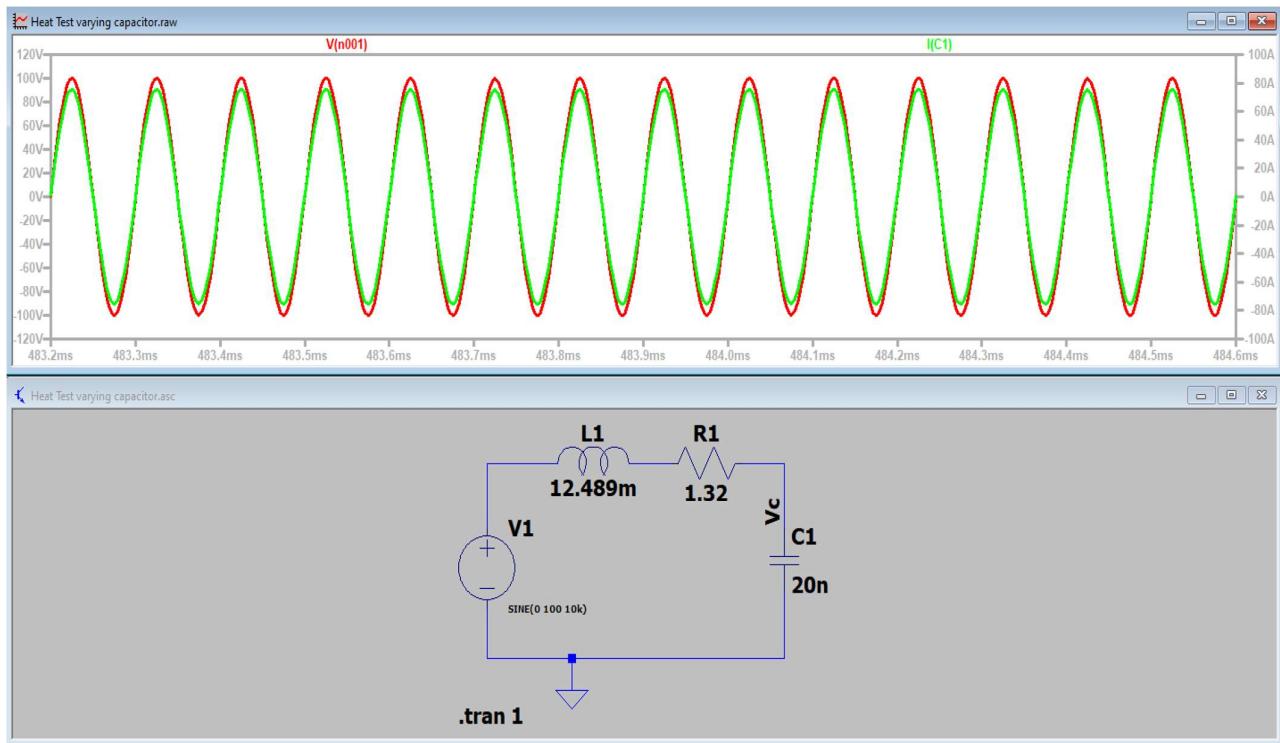


Figure-76: Heat run test using tuned inductance value(12.489mH)

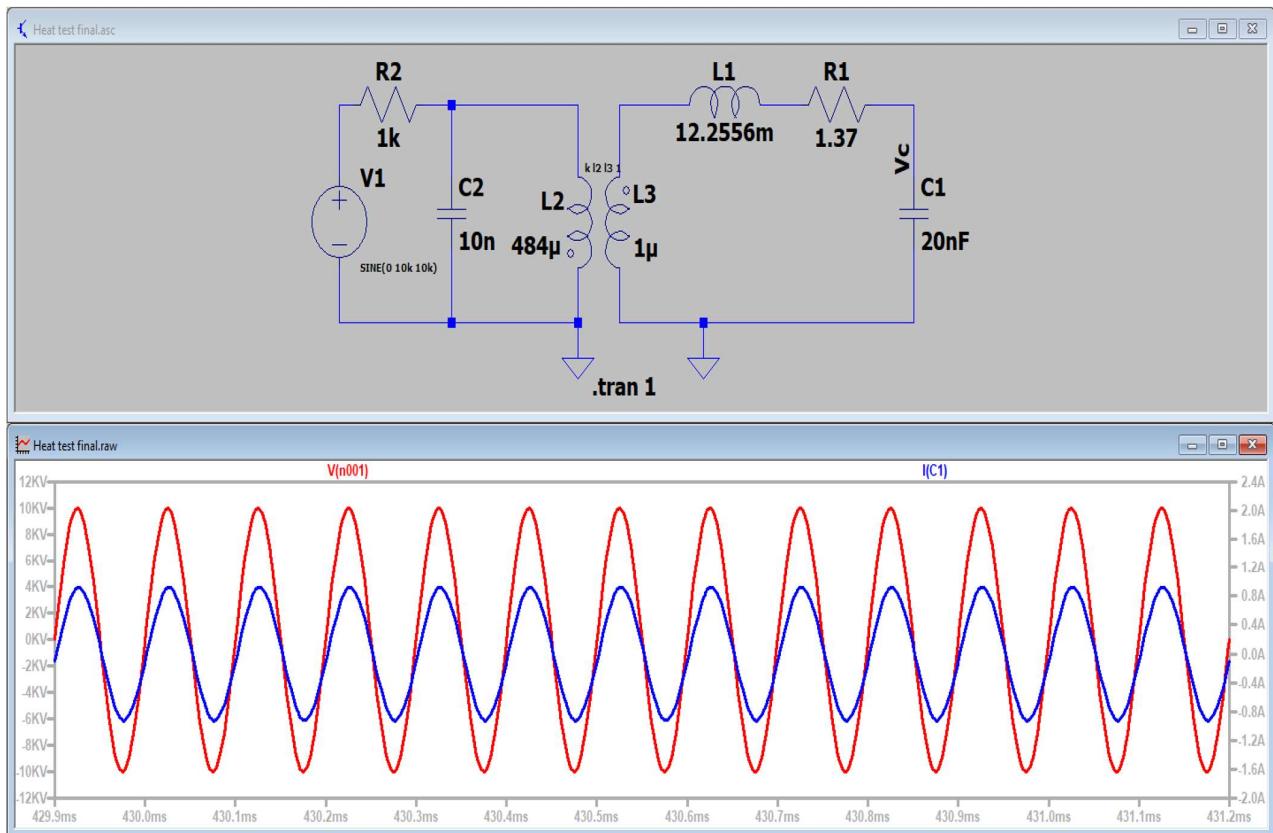


Figure-77: Original Heat run test circuit

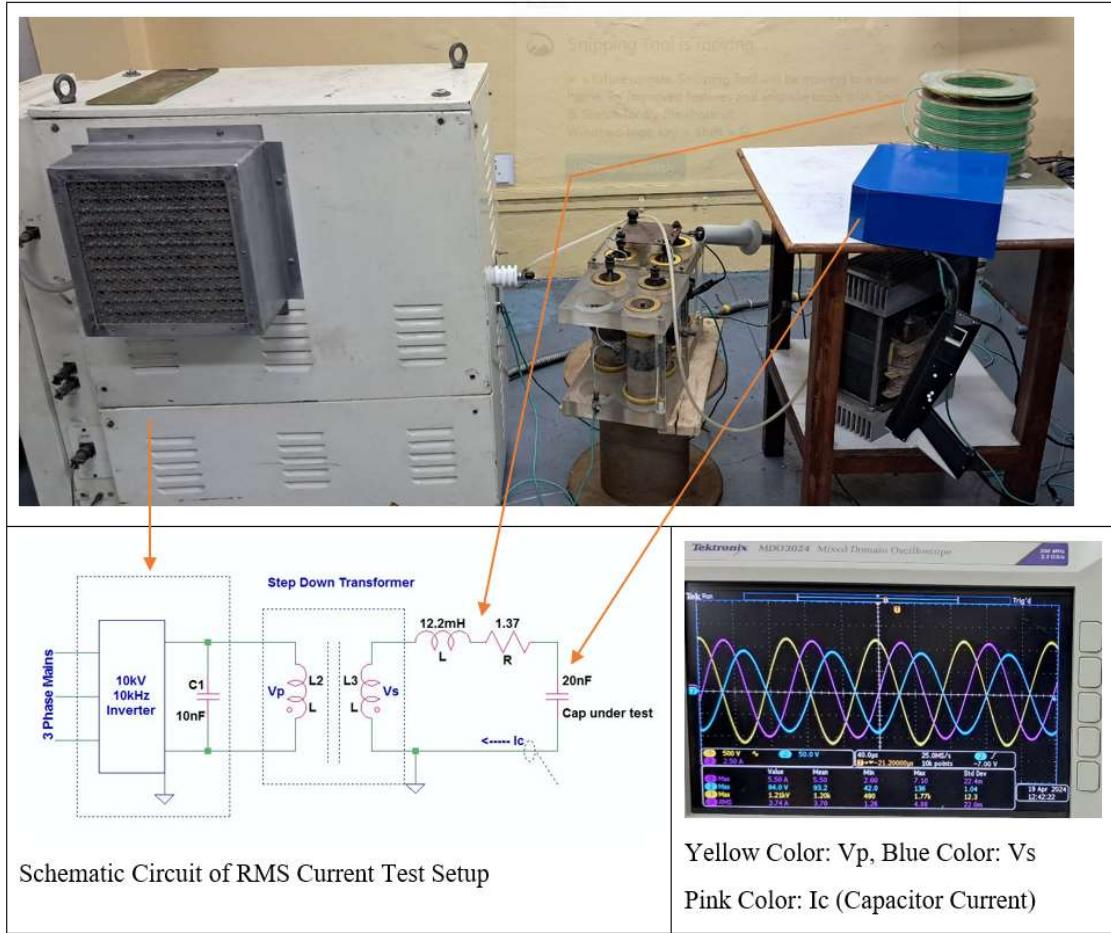
Inspection and testing of SCWM stage Capacitor

Technical Specification for High Voltage Capacitor		
S No.	Parameter	Value
1.	Capacitance	20nF
2.	Cap. Value measuring frequency	1 kHz
3.	Tolerance	±15%
4.	Rated voltage	120kV _{DC} (42 kVrms)
5.	Test Voltage	150kV DC 1 minute
6.	Current Rating	3Arms@10kHz
7.	Dielectric	Solid Dielectric(Ceramic-BaTiO ₃ or equivalent)
8.	Dissipation factor	≤ 0.001 at 1kHz
9.	Operating conditions	(i) Continous working in 5%SF ₆ +95%N ₂ at 6kg/cm ² external bar Pressure (ii) 30mbar vacuum for 4 hours
10.	Dimension	Overall Dimension: 342 ± 0.2mm (L), 262 ± 0.5mm (W) & 112mm ± 0.5mm(H)
11.	Termination	Threaded Inserts

A)LCR measurement: LCR values of capacitor has been measured to be C 19.45nF & D = 0.00088 @ 1kHz.

LCR measurements				
Before RMS current test			After RMS current test	
V=1V				
f, kHz	C _p , nF	D	C _p	D
1	19.45	0.00088	19.4	0.0006
10	19.35	0.00011	19.39	0.0004
20	19.43	0.00071	19.4	0.0009
50	19.26	0.00099	19.39	0.0015
100	19.44	0.0012	19.4	0.0025
200	1.51	0.0022	19.46	0.0046
300	19.6	0.0028	19.56	0.0068
500	20	0.0041	19.87	0.011
1000	22	0.0064	21.5	0.023
V=5V				
f, kHz	C _p	D	C _p	D
1	19.44	0.0008	19.42	0.00064
10	19.43	0.0004	19.4	0.00056
20	19.45	0.00064	19.41	0.00063

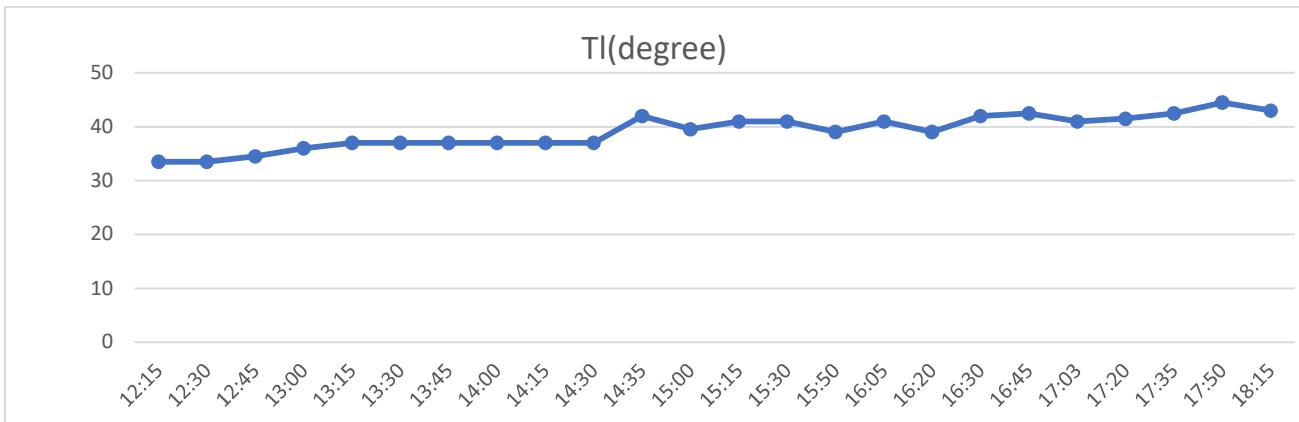
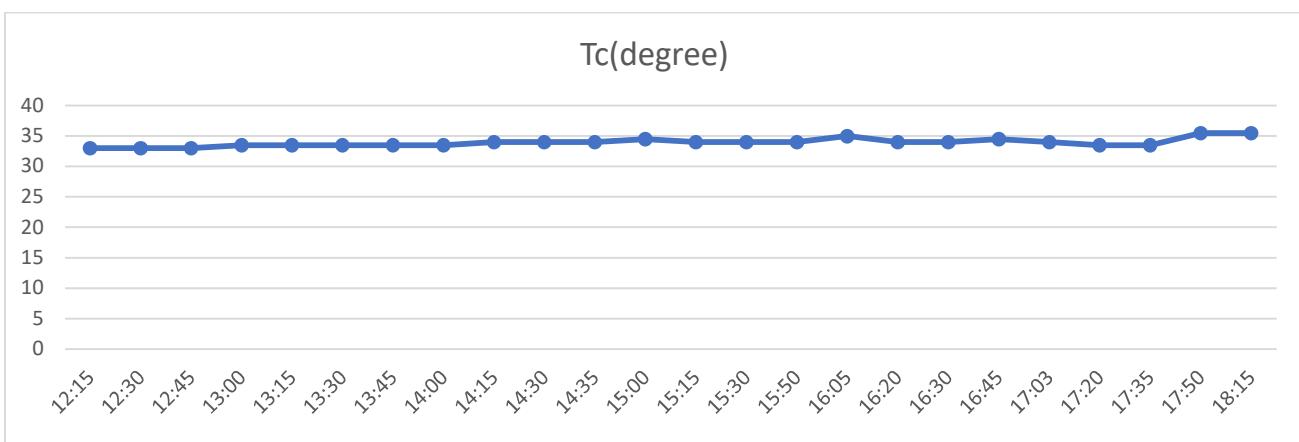
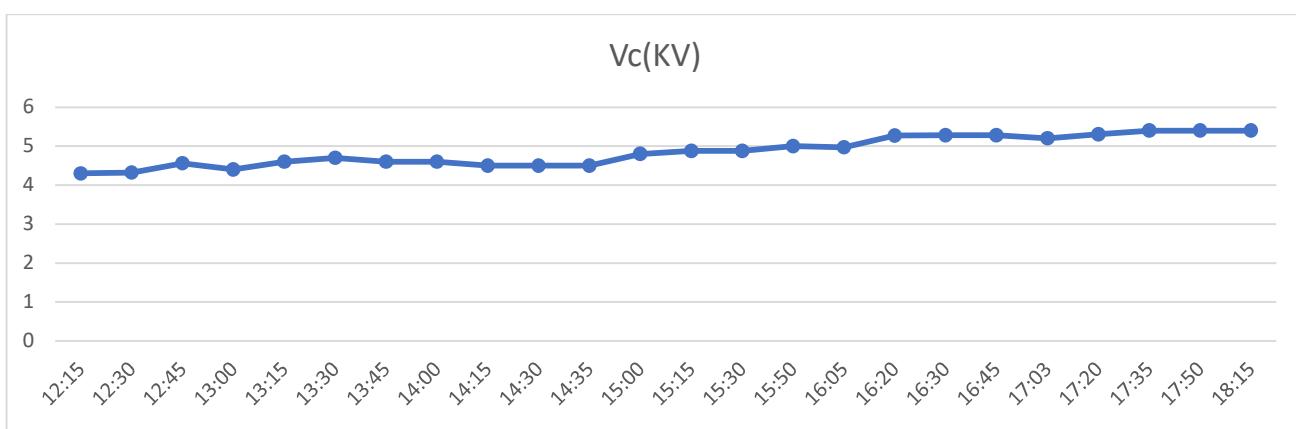
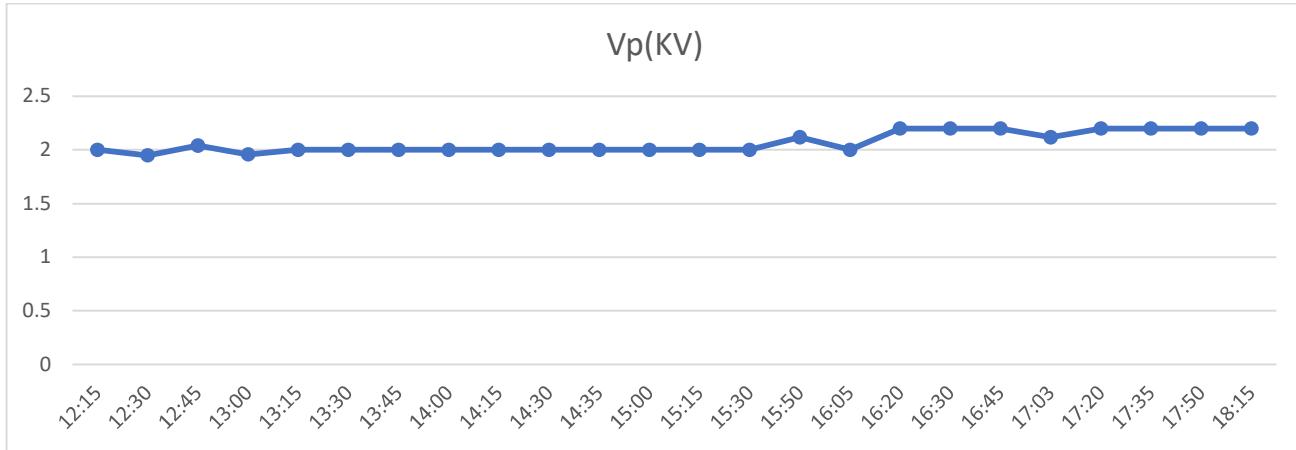
B) RMS current testing: Capacitor has been successfully tested at continuous 3.5Arms, 10kHz current using test inverter under series resonance method. The temperature rise on capacitor with 6 hours continuous testing was 0.5°C. Circuit diagram and test set-up and waveform are shown below:

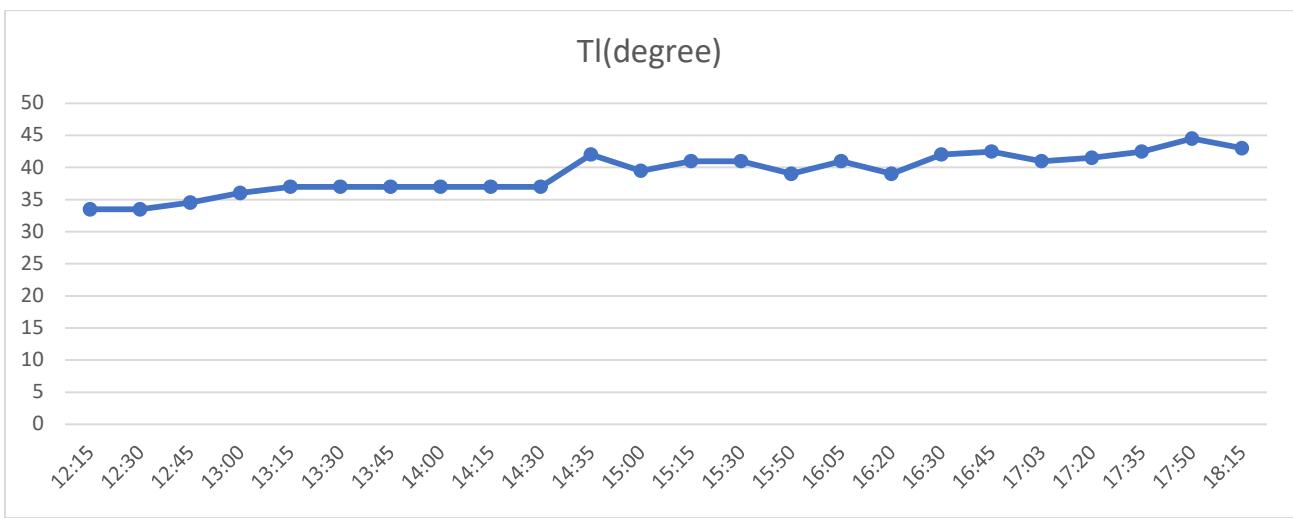
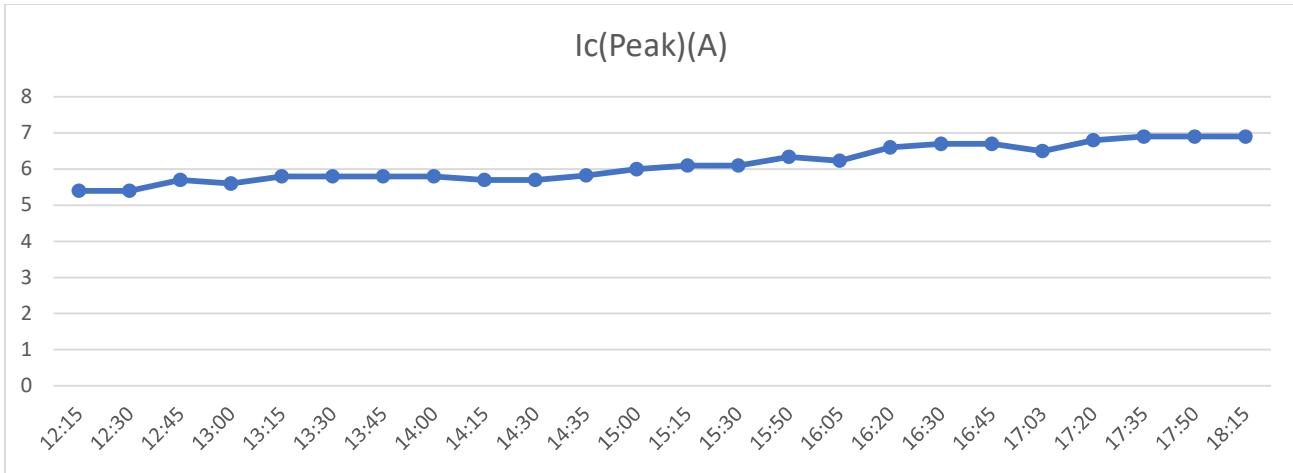


Original Data of Heat run test of Single Capacitor Module

Sl.No.	Time	Vp(kV)	Vc(kV)	Ic(Peak)(A)	Ic(RMS)(A)	Tc(degree)	TI(degree)
1	12:15	2	4.3	5.4	3.72	33	33.5
2	12:30	1.95	4.32	5.4	3.77	33	33.5
3	12:45	2.04	4.56	5.7	3.97	33	34.5
4	13:00	1.96	4.4	5.6	3.82	33.5	36
5	13:15	2	4.6	5.8	4.02	33.5	37
6	13:30	2	4.7	5.8	4.02	33.5	37
7	13:45	2	4.6	5.8	4.02	33.5	37
8	14:00	2	4.6	5.8	4.6	33.5	37
9	14:15	2	4.5	5.7	3.93	34	37
10	14:30	2	4.5	5.7	3.95	34	37
11	14:35	2	4.5	5.82	4.01	34	42
12	15:00	2	4.8	6	4	34.5	39.5
13	15:15	2	4.88	6.1	4.14	34	41
14	15:30	2	4.88	6.1	4.12	34	41
15	15:50	2.12	5	6.34	4.37	34	39
16	16:05	2	4.97	6.23	4.3	35	41
17	16:20	2.2	5.27	6.6	4.5	34	39
18	16:30	2.2	5.28	6.7	4.61	34	42
19	16:45	2.2	5.28	6.7	4.64	34.5	42.5
20	17:03	2.12	5.2	6.5	4.53	34	41
21	17:20	2.2	5.3	6.8	4.6	33.5	41.5
22	17:35	2.2	5.4	6.9	4.7	33.5	42.5
23	17:50	2.2	5.4	6.9	4.7	35.5	44.5
24	18:15	2.2	5.4	6.9	4.7	35.5	43

Graphical Representation of the change of parameter W.R.T time





HV testing and LCR Testing of 3.3nF ,40kV, tan δ=0.002 at 1KHz

A) HV TESTING

High-voltage (HV) testing assesses the performance and safety of electrical components, such as capacitors, under elevated voltage conditions. It helps verify their insulation integrity and suitability for specific applications.

SET-UP INSTRUCTIONS

- See Instruction Manual for Clearance from HV Circuit and HV module required for Safety and for use of barriers.
- Connect the GROUND terminal of the HV module to a known earth ground.
- Connect the HV output cable to the HV output connector located on the HV module. The exposed shield connection on the HV output cable is at guard potential and must not be grounded.
- The EXTERNAL INTERLOCK plug must be wired to an external interlock switch or shorted with a jumper.
- With MAIN BREAKER off, plug INPUT cord into control panel receptacle and into grounded outlet
- Identify the HV terminal and the ground terminal of the specimen to be tested. Connect the ground terminal to the GROUND post of the HV module. Attach the spring Clip of the HV cable to the HV terminal of the specimen.
- The specimen under test may retain a lethal electrical charge even when the test set is turned off. The Specimen must be discharged with a properly grounded grounding stick.

B) LCR TESTING

LCR meter is an essential electronic instrument that measures the inductance (L), capacitance (C), and resistance (R) of electronic components. These parameters are crucial for the design and testing of electronic circuits, as they determine the performance and behaviour of these circuits.

Working Principle of LCR meters

LCR meters work on the principle of impedance measurement. Impedance is the opposition to the flow of alternating current (AC) in a circuit, and it comprises of resistance, inductance, and capacitance. The LCR meter applies an AC voltage or current to the component under test and measures the resulting voltage or current. By analysing the phase difference and amplitude ratio between the input and output signals, the LCR meter can calculate the component's impedance and extract its L, C, and R values.

Precaution:

Before testing a specimen like capacitor, we should discharge the capacitor by shorting their terminals.

Dimensional Check and Torque Test :

SL.NO.	Diameter(Max)	Diameter(Terminal)	Height(with T)	Height(W/O T)	Torque(N/m)
1	55.87	15.2	33.13	26.8	1.5
	55.79	15.18	33.09	26.34	1.5
	55.75	15.1	33.1	26.48	1.5
2	55.74	15.16	32.98	26.86	1.5
	55.79	15.21	33.08	26.65	1.5
	55.72	15.18	33.02	26.62	1.5
3	55.77	15.1	32.96	26.32	1.5
	55.82	15.12	33.02	26.59	1.5
	55.85	15.14	33.04	27.16	1.5
4	55.73	15.13	32.97	26.42	1.5
	55.75	15.08	33.06	26.94	1.5
	55.79	15.11	32.96	27.01	1.5
5	55.72	15.11	32.95	26.5	1.5
	55.84	15.1	33.01	27.26	1.5
	55.93	15.05	32.98	26.98	1.5

HV Testing :

SI.No.	Voltage(kV)	Current(µA)	Time(minute)
1	10.2	0.0-0.0	1
	20.3	0.0-0.0	1
	30.3	0.0-0.0	1
	40	0.0-0.0	1
2	10.2	0.0-0.0	1
	20.2	0.0-0.0	1
	30.8	0.0-0.0	1
	40.2	0.0-0.0	1
3	10.2	0.0-0.0	1
	20.3	0.0-0.0	1
	30	0.0-0.0	1
	40	0.0-0.0	1
4	10.2	0.0-0.0	1
	20	0.0-0.0	1
	30.4	0.0-0.0	1
	40.4	0.0-0.0	1
5	10.4	0.0-0.0	1
	20	0.0-0.0	1
	30.1	0.0-0.0	1
	40.2	0.0-0.0	1

LCR Testing:

SI.NO	Frequency	Before HV testing					After HV Testing				
		AC-1v		Ac-5v			AC-1v		Ac-5v		
		Cp(nf)	D	Cp(nf)	D		Cp(nf)	D	Cp(nf)	D	
1	1kHz	3.29	0.000	3.33	0.000		3.33	0.0007	3.32	0.0009	
	10KHz	3.31	0.003	3.33	0.003		3.33	0.0037	3.32	0.0034	
	20KHz	3.30	0.003	3.33	0.005		3.32	0.0058	3.31	0.0056	
	50KHz	3.30	0.010	3.32	0.011		3.31	0.0113	3.31	0.0108	
	100KHz	3.29	0.018	3.30	0.018		3.30	0.0183	3.29	0.0181	
2	1kHz	3.31	0.000	3.33	0.000		3.32	0.00064	3.34	0.0009	
	10KHz	3.30	0.002	3.32	0.003		3.33	0.0034	3.34	0.0035	
	20KHz	3.30	0.004	3.32	0.005		3.33	0.0056	3.34	0.0012	
	50KHz	3.29	0.009	3.31	0.010		3.32	0.0107	3.33	0.0109	
	100KHz	3.31	0.02	3.30	0.017		3.31	0.0179	3.31	0.0180	
3	1kHz	3.34	0.000	3.34	0.000		3.34	0.00056	3.35	0.00077	
	10KHz	3.33	0.002	3.34	0.003		3.34	0.00300	3.35	0.0032	
	20KHz	3.33	0.004	3.33	0.004		3.34	0.005	3.35	0.0054	
	50KHz	3.32	0.009	3.33	0.009		3.33	0.0098	3.34	0.0104	
	100KHz	3.31	0.017	3.32	0.01		3.32	0.0163	3.33	0.0172	
4	1kHz	3.25	0.000	3.26	0.001		3.25	0.0013	3.25	0.0010	
	10KHz	3.24	0.004	3.25	0.004		3.25	0.0044	3.24	0.0043	
	20KHz	3.24	0.006	3.25	0.007		3.24	0.0072	3.241	0.0069	
	50KHz	3.23	0.012	3.23	0.013		3.23	0.0136	3.23	0.0127	
	100KHz	3.22	0.018	3.22	0.021		3.21	0.021	3.216	0.0205	
5	1kHz	3.32	0.000	3.34	0.000		3.33	0.0007	3.34	0.00077	
	10KHz	3.32	0.002	3.34	0.003		3.33	0.0031	3.34	0.0033	
	20KHz	3.32	0.004	3.33	0.005		3.33	0.0054	3.34	0.0054	
	50KHz	3.31	0.009	3.32	0.010		3.32	0.0104	3.33	0.0104	
	100KHz	3.3	0.016	3.31	0.016		3.31	0.0176	3.32	0.0172	

HV testing of Ceramic Capacitor in Dielectric fluid (Test voltage=1.5 * rated voltage, 1 minute duration, standard IEC60384-1;2008):

Sl.No.	Voltage(kV)	Current(µA)	Time(minute)
1	10	0.0-0.0	1
	20	0.0-0.0	1
	30.1	0.0-0.0	1
	40.1	0.0-0.0	1
	50.1	0.0-0.0	1
	60.3	0.0-0.0	1
2	10	0.0-0.0	1
	20	0.0-0.0	1
	30.2	0.0-0.0	1
	40.4	0.0-0.0	1
	45	0.0-0.0	1
	50.5	0.1-0.0	1
	55.4	0.0-0.0	1
	60.1	0.0-0.0	1



LCR Testing After HV testing of Ceramic Capacitor in the Dielectric fluid:

Sl.NO	Frequency	AC-1v		Ac-5v	
		Cp(nf)	D	Cp(nf)	D
1	1kHz	3.3065	0.0006	3.280	0.0007
	10KHz	3.3039	0.0032	3.290	0.00285
	20KHz	3.304	0.005	3.291	0.00478
	50KHz	3.297	0.0099	3.286	0.00925
	100KHz	3.286	0.016	3.277	0.01559
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2	1kHz	3.3079	0.0007	3.318	0.001
	10KHz	3.308	0.0027	3.316	0.003
	20KHz	3.305	0.0049	3.3141	0.0051
	50KHz	3.298	0.0094	3.3074	0.010
	100KHz	3.288	0.016	3.2974	0.0164

CONCLUSION

During my two-month summer training at the EBC, APPD, BARC, I acquired a comprehensive understanding of the fundamental principles and practical applications of HV multiplier circuit for DC Electron Beam Accelerator.

I gained proficiency in simulating circuits using LT Spice and developed a thorough knowledge of the symmetrical Cockcroft-Walton Voltage Multiplier Circuit, including its operating principles and various configurations. Additionally, I learned about the connection and rating of capacitors and diodes used in multiplier circuits. Through simulations, I analysed the performance of the circuit under both no-load and loaded conditions, and interpreted the results through graphical representations.

Furthermore, I successfully simulated the heat run test circuit of the single capacitor module (20nF, 10kHz) and performed HV and LCR tests on a new specimen (3.3nF, 40kV, D=0.002 at 1KHz). This training experience has equipped me with valuable knowledge and skills in the field of high voltage engineering.